



標題	採用 HiperPFS™-2 (PFS7326H) 和 HiperLCS™ (LCS702HG) 的 150 W 功率因數修正 LLC 電源供應器參考設計報告
規格	90 VAC – 265 VAC 輸入； 150 W (0 - 3.5 A 時 ~43 V) 輸出 (定電流)
應用	LED 街燈
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摘要與功能

- 整合式 PFC 和 LLC Stage 適合所需元件極少的設計
- 連續模式 PFC 採用低成本鐵氧體鐵芯
- 高頻率 (250 kHz) LLC，適用於尺寸非常小的變壓器。
- 於 115 VAC 時，PFC 滿載效率超過 95%
- LLC 滿載效率超過 95%
 - 於 115 VAC / 230 VAC 時，系統效率超過 91% / 93%
- 啓動電路可省略另外的偏壓電源供應器
- 內建電流調節和類比調光

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重要附註：

雖然此電路板的設計符合安全隔離要求，但工程原型尚未取得相關機構之認證。執行所有測試應使用隔離變壓器才能提供 **AC** 輸入給原型板。

由於本設計沒有另外的偏壓轉換器，在電源供應器斷電之後，大電容器 **C14** 上會立即出現 **~280 VDC**。為了安全起見，此電容器必須使用適當的電阻器 (**10 k/2 W** 即可) 加以放電，或是讓電源供應器停滯 **10** 分鐘左右再進行操作。



1 簡介

本工程報告說明適用於 90-265 VAC LED 街燈和其他高功率照明應用的 43 (標準值) V、150 W 電源供應器的參考設計。這款電源供應器設計有定電流輸出，可直接在 43 V 下驅動 150 W LED 面板。

本設計採用 PFS7326H 做為 PFC 前端，以及 LCS702HG 做為 LLC 輸出 Stage。

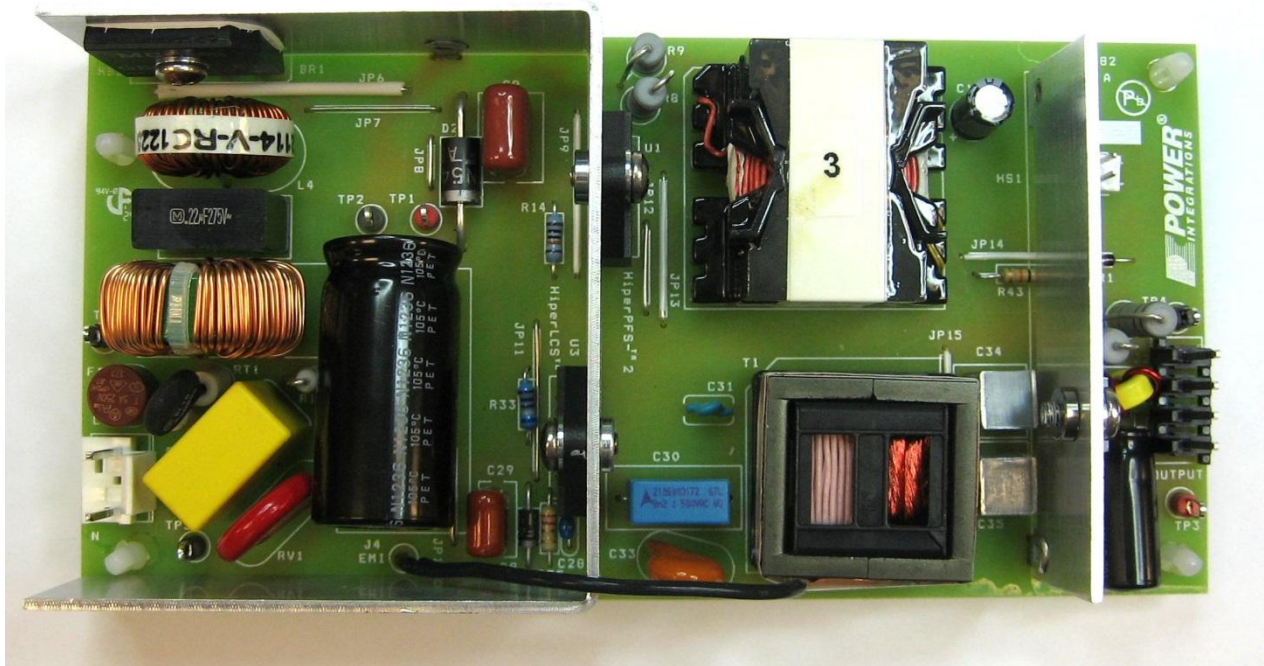


Figure 1 – RD-382 Photograph, Top View.



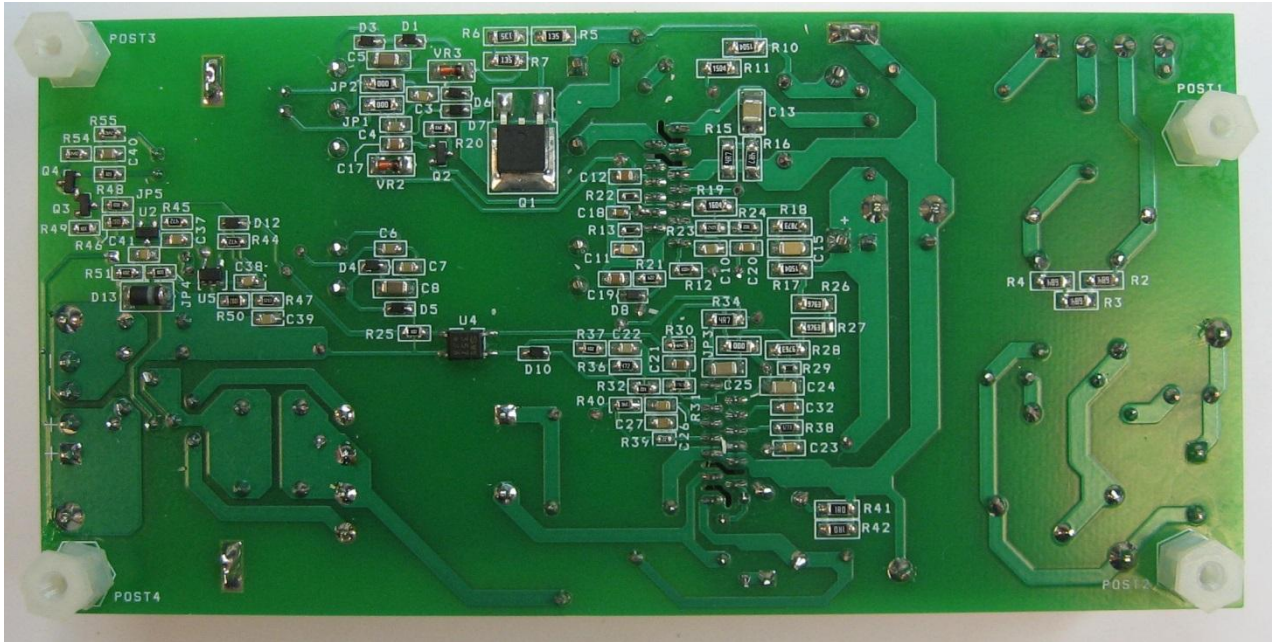


Figure 2 – RD-382 Photograph, Bottom View.



2 電源供應器規格

下表展示設計的最低可接受效能。實際效能列在結果部分。

說明	符號	最小值	典型值	最大值	單位	註解
輸入 電壓 頻率 功率因數 (PF)	V_{IN} f_{LINE} 功率因數 (PF)	90 47 0.97	50/60	265 64	VAC Hz	3 線輸入。 滿載，230 VAC
主電源轉換器輸出 輸出電壓 輸出漣波 輸出電流	V_{LG} $V_{RIPPLE(LG)}$ I_{LG}		43	300	V mV P-P A	43 VDC (標準值 - 由 LED 負載定義) 20 MHz 頻寬 定電流電源供應器，在無負載狀況下受保護
總輸出功率 連續輸出功率 峰值輸出功率	P_{OUT} $P_{OUT(PK)}$		150	N/A	W W	
效率 滿載時的整體系統功耗	$\eta_{主要}$		91 93		%	於 115 VAC、滿載條件下測量 於 230 VAC、滿載條件下測量
環境 傳導性 EMI 安全 突波 差模 共模						符合 CISPR22B / EN55022B 標準 設計符合 IEC950 / UL1950 第 II 級 1.2/50 μ s 突波，IEC 1000-4-5，差模：2 Ω 共模：12 Ω
環境溫度	T_{AMB}	0		60	$^{\circ}$ C	請參閱「散熱」一節以瞭解各種條件



3 電路圖

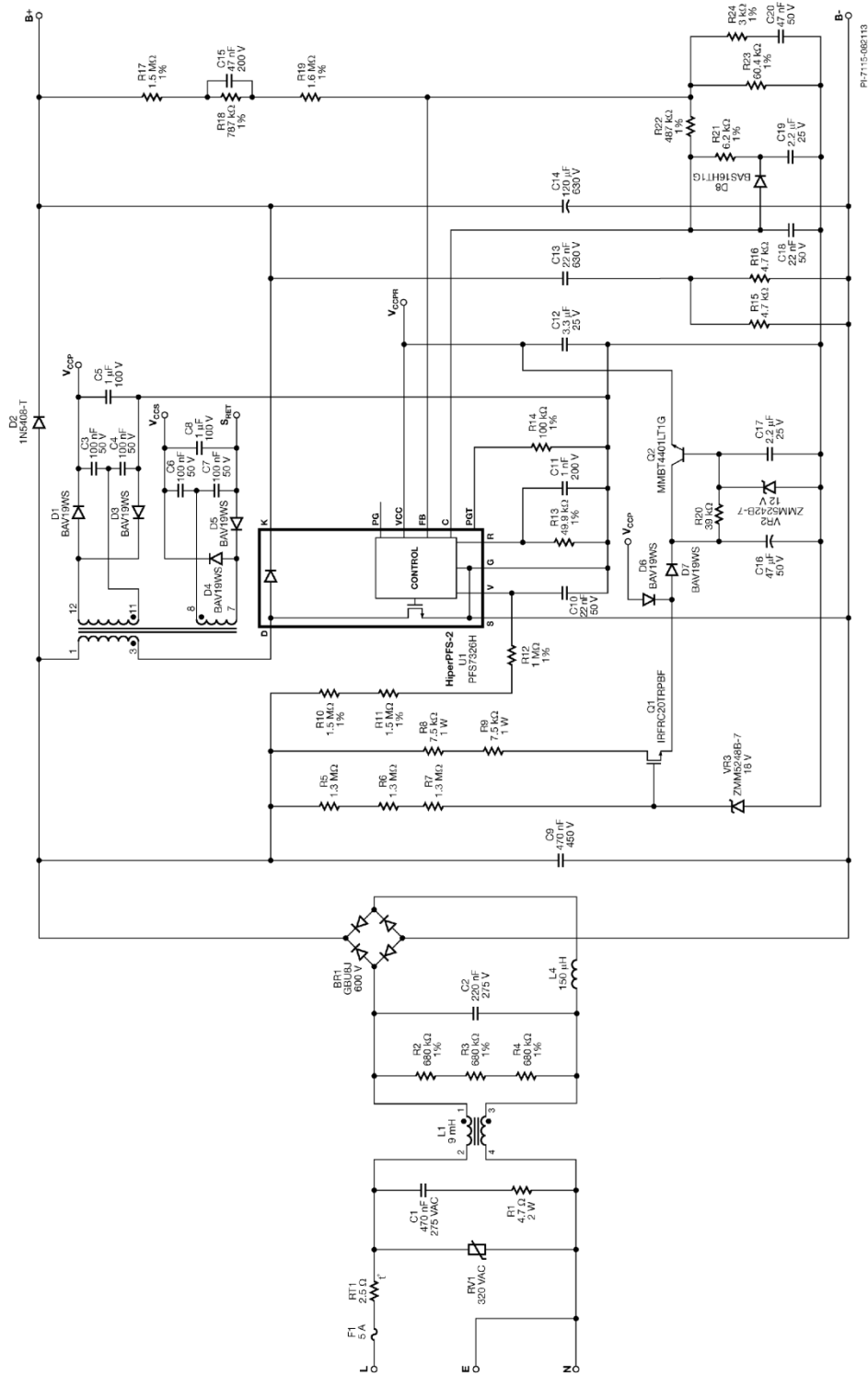


Figure 3 – Schematic RD-382 Street Light Power Supply Application Circuit - Input Filter, PFC Power Stage, and Bias Supplies.



4 電路說明

4.1 輸入濾波器/升壓式轉換器/偏壓電源供應器

圖 3 中的電路圖顯示輸入 EMI 濾波器、PFC Stage，以及一次側偏壓電源供應器/啓動電路。功率因數修正器採用 PFS7326H。一次側與二次側偏壓供電來自於 PFC 電感器 (L2) 上的繞組。

4.2 EMI 濾波/浪湧限制

電容器 C1 和 C2 用於控制差模雜訊。電阻器 R1 用於阻尼，可提高功率因數並降低 EMI。電阻器 R2-4 會在移除 AC 電源後將 C1 和 C2 放電。電感器 L1 控制共模 EMI。U1、U3 和 BR1 的散熱片連接到一次側迴線，以消除散熱片成爲輻射/電容耦合雜訊的來源。熱敏電阻器 RT1 可限制浪湧。電容器 C33 (圖 4) 會濾波共模 EMI。電感器 L4 會濾波差模 EMI。

4.3 主電源 PFC Stage

R17-19 和 R23 等元件提供輸出電壓回授。電容器 C15 提供回授至 U1 FB 接腳的快速電壓微分值，用於 PFC 電路的快速下衝和過衝回應。C19、C20 和 R21、R22 及 R24 提供頻率補償。電阻器 R10-12 (由 C10 濾波) 提供輸入電壓資訊給 U1。電阻器 R13 (由 C11 濾波) 可將 U1 設定爲「效率」模式。如需有關 HiperPFS-2 效率模式的詳細資訊，請參閱 HiperPFS-2 產品規格型錄。電阻器 R14 可爲 U1 設定「電源備妥」臨界值。

電容器 C12 爲 U1 提供本機旁路。二極體 D2 會在初次施加 AC 時爲 PFC 輸出電容器 (C14) 充電，以將浪湧電流引離 PFC 電感器 L2 及 U1 的內部輸出二極體。電容器 C13 和 R15-16 用於縮短圍繞著元件 U1 和 C14 之高頻迴路的長度，以降低 EMI。與 C13 串聯的電阻器可抑制中頻 EMI 峰值。輸入 AC 會由 BR1 進行整流，並由 C9 進行濾波。選用電容器 C9 做爲低損失聚丙烯類型，以在 U1 開啓期間提供流經 L2 的高瞬間電流。熱敏電阻器 RT1 會限制啓動時的浪湧電流。

4.4 一次側偏壓電源供應器/啓動

R5-7、R8-R9、Q1 和 VR3 等元件爲 U1 提供啓動偏壓。一旦 U1 啓動，元件 D1、D3 和 C3-5 會透過 PFC 電感器 L2 上的繞組產生一次側偏壓供電。這可用於同時爲電源供應器的 PFC 和 LLC Stage 供電。建立一次側偏壓供電電壓後，它會用於透過二極體 D6 關閉 MOSFET Q1，以降低功耗。當電源供應器無法啓動時，電阻器 R8 和 R9 會阻止 Q1 過度功率消耗。

D7、Q2、C16-17 和 VR2 等元件會調節 U1 和 U3 的側偏壓供電電壓。D4、D5 和 C6-8 等元件會透過 L2 上的三層絕緣繞組爲二次側控制電路產生偏壓供電。

4.5 LLC 轉換器

圖 4 中的電路圖說明採用 LCS702HG 實作，具有定電流輸出的 ~43 V、150 W LLC DC-DC 轉換器。



4.6 一次側

積體電路 U3 納入 LLC 諧振半橋 (HB) 轉換器所需的控制電路、驅動器和輸出 MOSFET。U3 的 HB 輸出會經由阻隔/諧振電容器 (C30) 驅動輸出變壓器 T1。此電容器的額定值是依照操作漣波電流所訂，能耐受故障狀況下存在的高電壓。

變壓器 T1 具有 49 μ H 漏電感的設計，配合諧振電容器 C30 可如以下公式所示，將一次側串聯諧振頻率設為 ~259 kHz：

$$f_R = \frac{1}{6.28\sqrt{L_L \times C_R}}$$

其中 f_R 是以赫茲為單位的串聯諧振頻率， L_L 是以亨利為單位的變壓器漏電感， C_R 是以法拉為單位的諧振電容器 (C30) 值。

變壓器圈數比的設定方式是調整一次側圈數，使得標準輸入電壓並且滿載下的操作頻率接近、但略低於先前描述的諧振頻率。

從變壓器尺寸、輸出濾波器電容 (採用陶瓷/薄膜電容器) 與效率之間看來，250 kHz 操作頻率是良好的折衷值。

選定的二次側繞組圈數能在鐵芯與銅損失之間具有良好的折衷。AWG #44 Litz 線徑用於一次與 AWG #42 Litz 線徑，而針對二次，此組合可提供操作頻率 (~250 kHz) 的高能效。各 Litz 線徑規格內的股數，是為了在繞組適度與銅損失之間求取平衡而選定。

所選的鐵芯材料為 PW4 (Itacoil 出品)。此材料能提供良好的 (低損失) 效能。

元件 D9、R35 及 C28 組成自舉電路，供電給 U3 內部的高壓側驅動器。

元件 R34 及 C25 可為 U1 提供 +12 V 輸入的濾波及旁路功能，以及 V_{CC} 供電。注意： V_{CC} 電壓高於 15 V 可能會損傷 U3。

分壓電阻器 R26-29 可設定 U3 的高電壓開啓、關閉與過壓的臨界值。選定的分壓器值可設定 360 VDC 下的 LLC 開啓點，以及 285 VDC 下的關閉點，其中輸入過壓關閉點為 473 VDC。內建磁滯將輸入欠壓關閉點設為 280 VDC。

電容器 C29 是 +380 V 輸入的高頻率旁路電容器，連接 U3 的 D 及 S1/S2 接腳之間的短 Trace。串聯電阻器 R41-42 提供 EMI 阻尼。

電容器 C31 與 C30 組成分流器，用於對一次側電流的一部分取樣。以電阻器 R40 感測此電流，產生的訊號由 R39 及 C27 濾波。電容器 C31 應依照故障狀況下的峰值電壓訂定額



定值，並應使用穩定的低損失電介質，例如金屬化薄膜、SL 陶瓷或 NPO/COG 陶瓷。RD-382 中使用的電容器為一種具有 SL 溫度特性的盤式陶瓷電容器，常用於 CCFL 管的驅動器。選定的值可如以下公式所示設定 4.25 A 的 1 圈 (快速) 限電流，與 2.35 A 的 7 圈 (慢速) 限電流。

$$I_{CL} = \frac{0.5}{\left(\frac{C31}{C30 + C31}\right) \times R40}$$

I_{CL} 是以安培為單位的 7 圈限電流，R40 是以歐姆 (Ohms) 為單位的限電流電阻器，C30 及 C31 分別是以毫微法拉為單位的諧振和電流取樣電容器值。至於單圈限電流，請在上述公式中以 0.9 V 取代 0.5 V。

電阻器 R39 和電容器 C27 將一次側電流訊號濾波至 IS 接腳。電阻器 R39 設為 220 Ω ，即建議的最小值。C27 的值設為 1 nF 以免因雜訊而產生錯誤動作，但不致於高到大幅影響依以上方式計算的限電流設定值。這些元件應置於 IS 接腳附近，以得到最高效用。IS 接腳能承受負電流，因此電流感測不需要複雜的整流設計。

R33 和 R38 的 Thevenin 等效組合可設定停滯時間為 330 ns，U3 最大操作頻率成為 847 kHz。U3 的 DT/BF 輸入是由 C23 進行濾波。R33 與 R38 的組合也為 U3 選擇突波模式“1”。如此可將突波臨界值頻率的上下限分別設定為 382 kHz 和 437 kHz。

FEEDBACK 接腳具有入至 FEEDBACK 接腳每 μA 2.6 kHz 的近似特性。隨著流入 FEEDBACK 接腳的電流提高，U3 的操作頻率也會提高，因而降低輸出電壓。R30 與 R31 的串聯組合可設定 U3 的最低操作頻率 (~160 kHz)。此值設為比以滿載且大電容器最低電壓進行調節所需頻率略低的值。電阻器 R30 以 C21 旁通，藉由當回授迴路開啓時，起初允許較高的電流流入 FEEDBACK 接腳，達成啓動過程的輸出軟啓動。這會造成切換頻率開始時高之後降低，至輸出電壓達到調節穩定為止。電阻器 R31 一般設為與 R33 和 R38 的並聯組合等值，以便軟啓動時的初始頻率等於以 R33 和 R38 所設的最高切換頻率。如果 R31 的值低於此，會導致在施加輸入電壓時，於開始切換之前有所延遲。

光耦合器 U4 驅動 U3 FEEDBACK 接腳直到 R32，可限制進入 FEEDBACK 接腳的最大光耦合器電流。電容器 C26 能為 FEEDBACK 接腳濾波。電阻器 R36 能負載光耦合器的輸出，迫使其在相當高的靜態電流之下運作，因而提高增益。電阻器 R32 和 R36 也能增進大訊號步階回應與突波模式的輸出漣波。二極體 D10 能將 R36 與 F_{MAX} 軟啓動網路隔離。

4.7 輸出整流

變壓器 T1 的輸出由 D11 及 C34-35 進行整流和濾波。這些電容器具有聚酯纖維介質，是依照輸出漣波電流額定值所精心選擇。輸出整流器 D11 是針對高效率所選擇的 150 V 蕭特基整流器。變壓器半二次側的相互纏繞 (參閱第 8 節的變壓器構造詳細資料) 能減少兩個半



二次側之間的漏電感，以降低最壞狀況反向峰值電壓，並允許使用 150V 蕭特基二極體，因而提高效率。其他輸出濾波是由 L3 和 C36 所完成。電容器 C36 也能在 ~30 kHz 降低 LLC 「虛擬」輸出串聯 R-L 與輸出電容器 C34-35 造成的 LLC 輸出阻抗峰值。

4.8 輸出電流與電壓控制

輸出電流是透過電阻器 R52 和 R52 進行感測。這些電阻器是由二極體 D13 箝制，可避免電流控制電路在發生輸出短路時損壞。元件 R45 和 U2 可為電流感測放大器 U5 提供電壓參考。參考電壓是由 R46-47 和 R50 分降，並由 C39 濾波。電流感測電阻器的電壓是由 R51 和 C41 濾波，然後施加於 U5 的非轉化輸入。運算放大器 U5 會透過 D12 和 R25 來驅動光耦合器 U4。R25、R44、R51、C38 和 C41 等元件用於電流迴路的頻率補償。元件 VR1 和 R43 提供輸出電壓感測，以在移除輸出負載時保護電源供應器。這些元件是根據相對大的 R43 值及相對低的 VR1 電壓來加以選擇，以提供軟電壓限制特性。這有助於防止 V-I 曲線的膝點出現振盪，並改善向指定之 LED 負載供電的啟動特性。

J3、Q3-4、R48-49、R54-55、R46 和 C40 等元件用於提供遙控調光功能。J3 的調光電壓會由 R54 和 R55 轉換成電流，並透過電流鏡 Q3-Q4 施加於 R46。這會將參考電壓上的電流下拉至電流感測放大器 U5，進而降低設定的輸出電流。0-10 VDC 的調光電壓提供的輸出電流範圍為：0 V 時 100% 至 10 VDC 輸出時 ~20%。



5 PCB 佈局

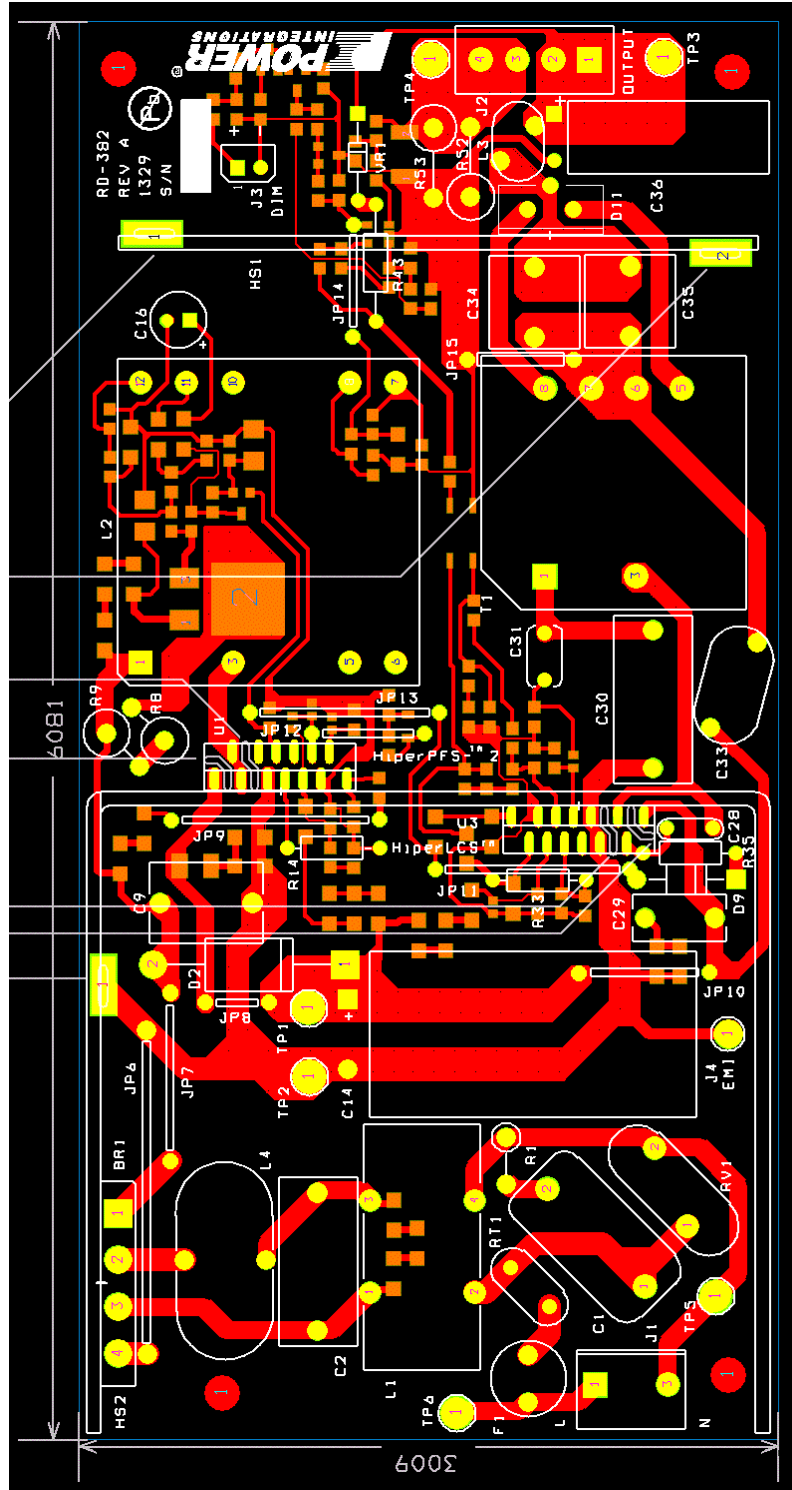


Figure 5 – Printed Circuit Layout, Top Side.



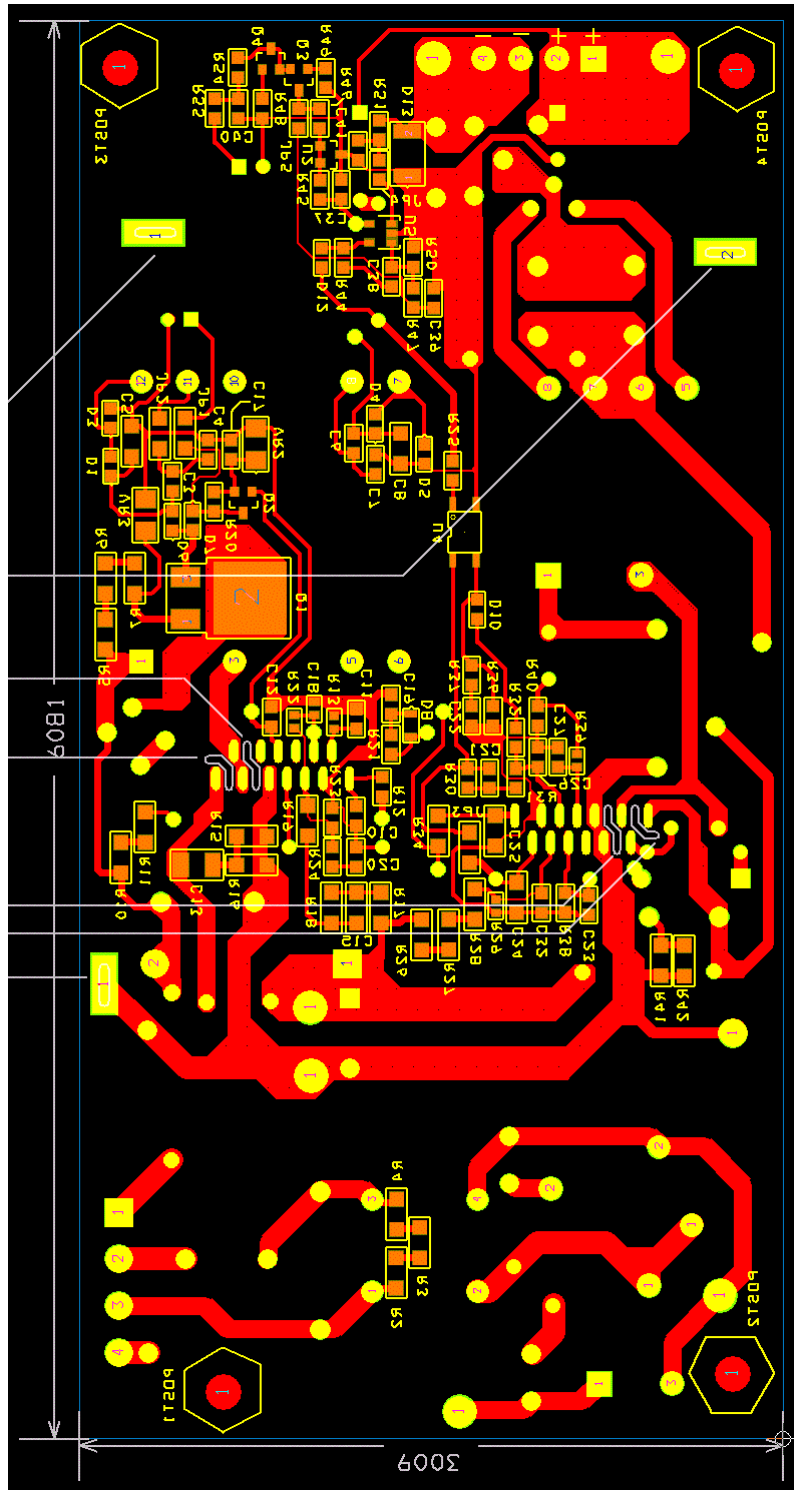


Figure 6 – Printed Circuit Layout, Bottom Side.



6 物料清單

Item	Qty	Ref Des	Description	Mfg Part Number	Mfg
1	1	BR1	600 V, 8 A, Bridge Rectifier, GBU Case	GBU8J-BP	Micro Commercial
2	1	C1	470 nF, 275 VAC, Film, X2	PX474K31D5	Carli
3	1	C2	220 nF, 275 VAC, Film, X2	ECQ-U2A224ML	Panasonic
4	7	C3 C4 C6 C7 C37 C39 C40	100 nF, 50 V, Ceramic, X7R, 0805	CC0805KRX7R9BB104	Yageo
5	2	C5 C8	1 μ F, 100 V, Ceramic, X7R, 1206	HMK316B7105KL-T	Taiyo Yuden
6	1	C9	470 nF, 450 V, METALPOLYPRO	ECW-F2W474JAQ	Panasonic
7	1	C10	22 nF, 50 V, Ceramic, X7R, 0805	ECJ-2VB1H223K	Panasonic
8	1	C11	1 nF, 200 V, Ceramic, X7R, 0805	08052C102KAT2A	AVX
9	1	C12	3.3 μ F, 25 V, Ceramic, X7R, 0805	C2012X7R1E335K	TDK
10	1	C13	22 nF, 630 V, Ceramic, X7R, 1210	GRM32QR72J223KW01L	Murata
11	1	C14	120 μ F, 450 V, Electrolytic, 20 %, (18 x 37mm)	450BXW120MEFC18X35	Rubycon
12	1	C15	47 nF, 200 V, Ceramic, X7R, 1206	12062C473KAT2A	AVX
13	1	C16	47 μ F, 50 V, Electrolytic, 20 %, (6.3 x 12.5 mm)	50YXM47MEFC6.3X11	Rubycon
14	2	C17 C19	2.2 μ F, 25 V, Ceramic, X7R, 0805	C2012X7R1E225M	TDK
15	1	C18	22 nF 50 V, Ceramic, X7R, 0603	C1608X7R1H223K	TDK
16	1	C20	47 nF, 50 V, Ceramic, X7R, 0805	GRM21BR71H473KA01L	Murata
17	1	C21	330 nF, 50 V, Ceramic, X7R, 0805	GRM219R71H334KA88D	Murata
18	1	C22	33 nF, 50 V, Ceramic, X7R, 0805	CC0805KRX7R9BB333	Yageo
19	3	C23 C26 C41	4.7 nF, 200 V, Ceramic, X7R, 0805	08052C472KAT2A	AVX
20	2	C24 C25	1 μ F, 25 V, Ceramic, X7R, 1206	C3216X7R1E105K	TDK
21	1	C27	1 nF, 200 V, Ceramic, X7R, 0805	08052C102KAT2A	AVX
22	1	C28	330 nF, 50 V, Ceramic, X7R	FK24X7R1H334K	TDK
23	1	C29	47 nF, 630 V, Film	MEXPD24704JJ	Duratech
24	1	C30	8.2 nF, 1000V VDC, Film	B32671L0822J000	Epcos
25	1	C31	47 pF, 1 kV, Disc Ceramic	DEA1X3A470JC1B	Murata
26	1	C32	22 nF, 200 V, Ceramic, X7R, 0805	08052C223KAT2A	AVX
27	1	C33	2.2 nF, Ceramic, Y1	440LD22-R	Vishay
28	2	C34 C35	4.7 μ F, 63 V, Polyester Film	B32560J475K	Epcos
29	1	C36	120 μ F, 63 V, Electrolytic, Gen. Purpose, (8 x 22)	EEU-FR1J121LB	Panasonic
30	1	C38	10 nF, 200 V, Ceramic, X7R, 0805	08052C103KAT2A	AVX
31	2	CLIP_LCS_PFS1 CLIP_LCS_PFS2	Heat sink Hardware, Clip LCS_II/PFS	EM-285V0	Kang Yang Hardware Enterprise
32	8	D1 D3 D4 D5 D6 D7 D10 D12	100 V, 0.2 A, Fast Switching, 50 ns, SOD-323	BAV19WS-7-F	Diodes, Inc.
33	1	D2	1000 V, 3 A, Rectifier, DO-201AD	1N5408-T	Diodes, Inc.
34	1	D8	75 V, 200 mA, Rectifier, SOD323	BAS16HT1G	ON Semi
35	1	D9	600 V, 1 A, Ultrafast Recovery, 75 ns, DO-41	UF4005-E3	Vishay
36	1	D11	150 V, 20 A, Schottky, TO-220AB	DSSK 20-015A	IXYS
37	1	D13	100 V, 1 A, Rectifier, Glass Passivated, DO-213AA (MELF)	DL4002-13-F	Diodes, Inc.
38	1	F1	5 A, 250V, Slow, TR5	37215000411	Wickman
39	1	HS1	HEAT SINK, Custom, Al, 3003, 0.062" Thk		Custom
40	1	HS2	HEAT SINK, Custom, Al, 3003, 0.062" Thk		Custom
41	1	J1	3 Position (1 x 3) header, 0.156 pitch, Vertical	B3P-VH	JST
42	1	J2	4 Position (1 x 4) header, 0.156 pitch, Vertical	26-48-1045	Molex
43	1	J3	2 Position (1 x 2) header, 0.1 pitch, Vertical	22-23-2021	Molex
44	3	JP1 JP2 JP3	0 Ω , 5%, 1/4 W, Thick Film, 1206	ERJ-8GEY0R00V	Panasonic



45	2	JP4 JP5	0 Ω , 5%, 1/8 W, Thick Film, 0805	ERJ-6GEY0R00V	Panasonic
46	1	JP6	Wire Jumper, Insulated, TFE, #18 AWG, 1.4 in	C2052A-12-02	Alpha
47	1	JP7	Wire Jumper, Non insulated, #22 AWG, 0.7 in	298	Alpha
48	1	JP8	Wire Jumper, Non insulated, #22 AWG, 0.3 in	298	Alpha
49	1	JP9	Wire Jumper, Insulated, #24 AWG, 0.9 in	C2003A-12-02	Gen Cable
50	1	JP10	Wire Jumper, Non insulated, #22 AWG, 0.6 in	298	Alpha
51	1	JP11	Wire Jumper, Non insulated, #22 AWG, 0.8 in	298	Alpha
52	2	JP12 JP15	Wire Jumper, Non insulated, #22 AWG, 0.5 in	298	Alpha
53	1	JP13	Wire Jumper, Insulated, #24 AWG, 0.8 in	C2003A-12-02	Gen Cable
54	1	JP14	Wire Jumper, Insulated, #24 AWG, 0.5 in	C2003A-12-02	Gen Cable
55	1	L1	9 mH, 5 A, Common Mode Choke	T22148-902S P.I. Custom	Fontaine
56	1	L2	Custom, RD-382 PFC Choke, 437 μ H, PQ32/30, Vertical, 9 pins		Power Integrations
57	1	L3	Output Inductor, Custom, 300 nH, \pm 15%, constructed on Micrometals T30-26 toroidal core		Power Integrations
58	1	L4	150 μ H, 3.4 A, Vertical Toroidal	2114-V-RC	Bourns
59	4	POST1 POST2 POST3 POST4	Post, Circuit Board, Female, Hex, 6-32, snap, 0.375L, Nylon	561-0375A	Eagle Hardware
60	1	Q1	400 V, 2 A, 4.4 Ohm, 600 V, N-Channel, DPAK	IRFRC20TRPBF	Vishay
61	3	Q2 Q3 Q4	NPN, Small Signal BJT, GP SS, 40 V, 0.6 A, SOT-23	MMBT4401LT1G	Diodes, Inc.
62	1	R1	4.7 Ω , 2 W, Flame Proof, Pulse Withstanding, Wire Wound	WHS2-4R7JA25	IT Elect_Welwyn
63	3	R2 R3 R4	680 k Ω , 5%, 1/4 W, Thick Film, 1206	ERJ-8GEYJ684V	Panasonic
64	3	R5 R6 R7	1.3 M Ω , 5%, 1/4 W, Thick Film, 1206	ERJ-8GEYJ135V	Panasonic
65	2	R8 R9	7.5 k Ω , 5%, 1 W, Metal Oxide	RSF100JB-7K5	Yageo
66	3	R10 R11 R17	1.50 M Ω , 1%, 1/4 W, Thick Film, 1206	ERJ-8ENF1504V	Panasonic
67	1	R12	1 M Ω , 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF1004V	Panasonic
68	1	R13	49.9 k Ω , 1%, 1/16 W, Thick Film, 0603	ERJ-3EKF4992V	Panasonic
69	1	R14	100 k Ω , 1%, 1/4 W, Metal Film	MFR-25FBF-100K	Yageo
70	3	R15 R16 R34	4.7 Ω , 5%, 1/4 W, Thick Film, 1206	ERJ-8GEYJ4R7V	Panasonic
71	1	R18	787 k Ω , 1%, 1/4 W, Thick Film, 1206	ERJ-8ENF7873V	Panasonic
72	1	R19	1.60 M Ω , 1%, 1/4 W, Thick Film, 1206	ERJ-8ENF1604V	Panasonic
73	1	R20	39 k Ω , 5%, 1/8 W, Thick Film, 0805	ERJ-6GEYJ393V	Panasonic
74	1	R21	6.2 k Ω , 5%, 1/8 W, Thick Film, 0805	ERJ-6GEYJ622V	Panasonic
75	1	R22	487 k Ω , 1%, 1/16 W, Thick Film, 0603	ERJ-3EKF4873V	Panasonic
76	1	R23	60.4 k Ω , 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF6042V	Panasonic
77	1	R24	3 k Ω , 5%, 1/8 W, Thick Film, 0805	ERJ-6GEYJ302V	Panasonic
78	3	R25 R32 R37	1 k Ω , 5%, 1/8 W, Thick Film, 0805	ERJ-6GEYJ102V	Panasonic
79	3	R26 R27 R28	976 k Ω , 1%, 1/4 W, Thick Film, 1206	ERJ-8ENF9763V	Panasonic
80	1	R29	19.6 k Ω , 1%, 1/16 W, Thick Film, 0603	ERJ-3EKF1962V	Panasonic
81	1	R30	46.4 k Ω , 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF4642V	Panasonic
82	1	R31	5.76 k Ω , 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF5761V	Panasonic
83	1	R33	6.81 k Ω , 1%, 1/4 W, Metal Film	MFR-25FBF-6K81	Yageo
84	1	R35	2.2 Ω , 5%, 1/4 W, Carbon Film	CFR-25JB-2R2	Yageo
85	3	R36 R44 R45	4.7 k Ω , 5%, 1/8 W, Thick Film, 0805	ERJ-6GEYJ472V	Panasonic
86	1	R38	127 k Ω , 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF1273V	Panasonic
87	1	R39	220 Ω , 5%, 1/10 W, Thick Film, 0603	ERJ-3GEYJ221V	Panasonic
88	1	R40	36 Ω , 5%, 1/8 W, Thick Film, 0805	ERJ-6GEYJ360V	Panasonic
89	2	R41 R42	1 Ω , 5%, 1/4 W, Thick Film, 1206	ERJ-8GEYJ1R0V	Panasonic
90	1	R43	10 k Ω , 5%, 1/4 W, Carbon Film	CFR-25JB-10K	Yageo



91	2	R46 R50	10 k Ω , 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF1002V	Panasonic
92	1	R47	121 k Ω , 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF1213V	Panasonic
93	2	R48 R49	100 Ω , 5%, 1/8 W, Thick Film, 0805	ERJ-6GEYJ101V	Panasonic
94	1	R51	20 k Ω , 5%, 1/8 W, Thick Film, 0805	ERJ-6GEYJ203V	Panasonic
95	2	R52 R53	0.1 Ω , 5%, 2 W, Thick Oxide	MO200J0R1B	Synton-Tech
96	2	R54 R55	24.9 k Ω , 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF2492V	Panasonic
97	1	RT1	NTC Thermistor, 2.5 Ω , 5 A	SL10 2R505	Ametherm
98	4	RTV1 RTV2 RTV3 RTV4	Thermally conductive Silicone Grease	120-SA	Wakefield
99	1	RV1	320 V, 80 J, 14 mm, RADIAL	V320LA20AP	Littlefuse
100	4	SCREW1 SCREW2 SCREW3 SCREW4	SCREW MACHINE PHIL 6-32 X 5/16 SS	PMSSS 632 0031 PH	Building Fasteners
101	2	SPACER_CER1 SPACER_CER2	SPACER RND, Steatite C220 Ceramic	CER-2	Richco
102	1	T1	Integrated Resonant Transformer, Horizontal, 8 pins	TRLEV25043A	Itacoil
103	2	TP1 TP3	Test Point, RED, THRU-HOLE MOUNT	5010	Keystone
104	4	TP2 TP4 TP5 TP6	Test Point, BLK, THRU-HOLE MOUNT	5011	Keystone
105	1	U1	HiperPFS-2, ESIP16/13	PFS7326H	Power Integrations
106	1	U2	IC, REG ZENER SHUNT ADJ SOT-23	LM431AIM3/NOPB	National Semi
107	1	U3	HiperLCS, ESIP16/13	LCS702HG	Power Integrations
108	1	U4	Optocoupler, 80 V, CTR 80-160%, 4-Mini Flat	PC357N1TJ00F	Sharp
109	1	U5	OP AMP SINGLE LOW PWR SOT23-5	LM321MF	National Semi
110	1	VR1	39 V, 5%, 500 mW, DO-35	1N5259B-T	Diodes, Inc.
111	1	VR2	12 V, 5%, 500 mW, DO-213AA (MELF)	ZMM5242B-7	Diodes, Inc.
112	1	VR3	18 V, 5%, 500 mW, DO-213AA (MELF)	ZMM5248B-7	Diodes, Inc.
114	4	WASHER1 WASHER2 WASHER3 WASHER4	Washer Flat #6, SS, Zinc Plate, 0.267 OD x 0.143 ID x 0.032 Thk	620-6Z	Olander



7 LED 面板特性

A commercial 150 W LED streetlight was used to test the RD-382 power supply. The LED array consisted of (6) 7 X 4 panels, as 4 wide, 7 deep. For the purposes of testing, the six panels were connected in series-parallel, resulting in an LED array 12 wide, 14 deep (see Figures 8 and 9). The V-I characteristic of the LED panels connected in this manner is shown below in Figure 7.

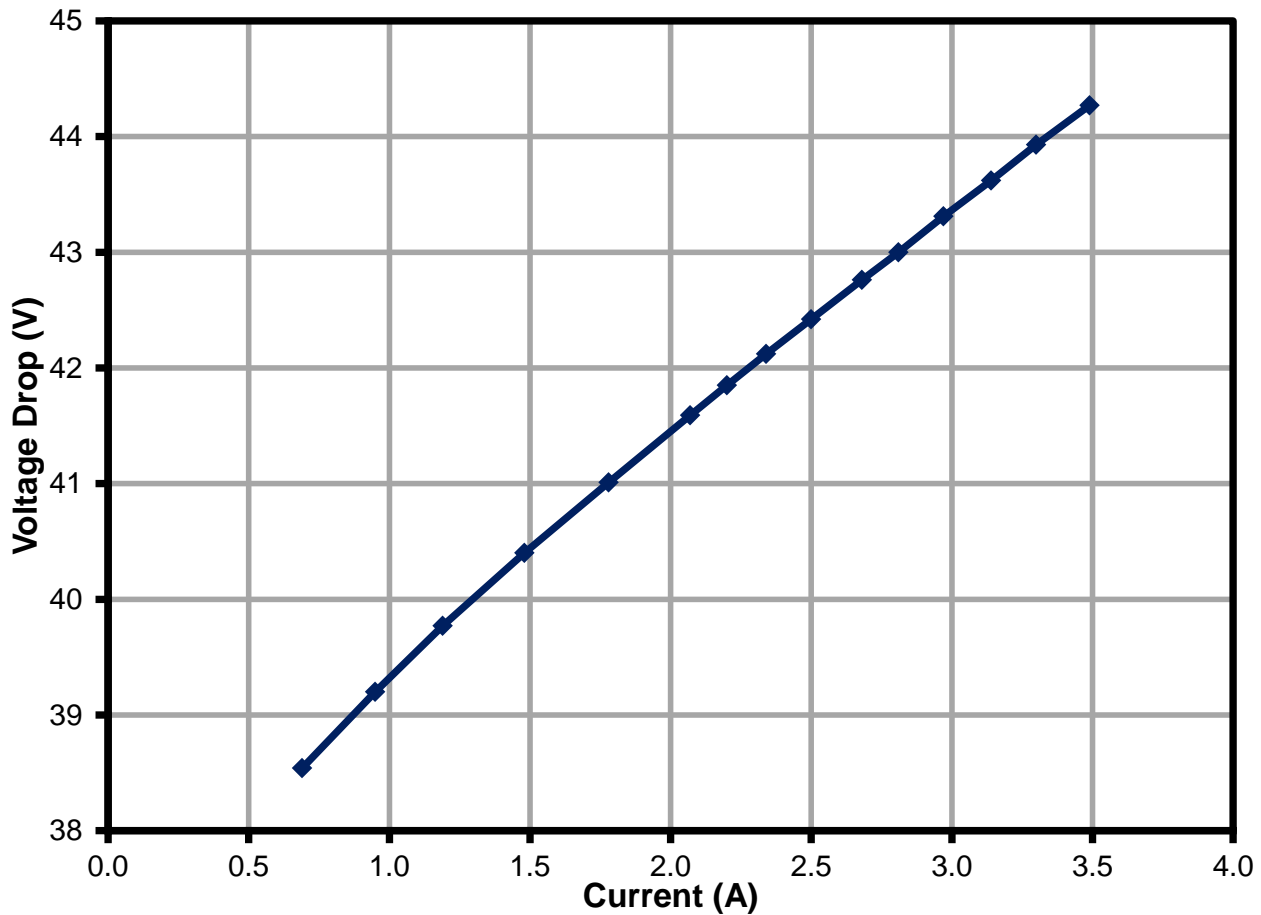


Figure 7 – Streetlight LED Array V-I Characteristic.



7.1 LED 面板電流共用

For the purpose of this report, the six LED panels in the street light were partitioned into 3 sections, each section consisting of two LED panels in series. Each panel was internally connected as an array of LEDs 4 wide and 7 deep so that two panels connected in series consisted of an array of LEDs 4 wide by 14 deep. The three sections were connected in parallel, forming a total LED load 12 wide and 14 deep. Using a DC current probe, the current in each 4 wide by 14 deep section was measured to determine the current distribution between sections, with results shown below.

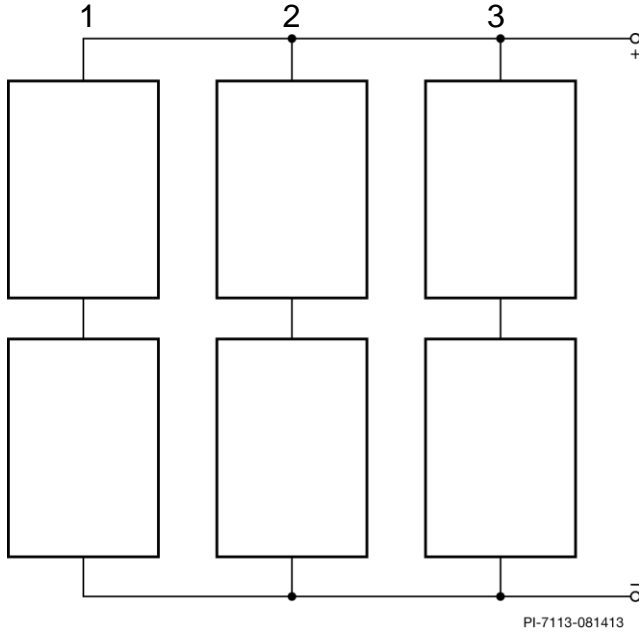


Figure 8 – LED Test Panel Layout.

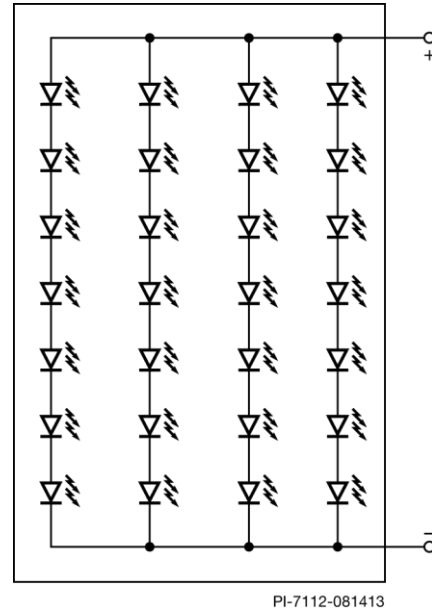


Figure 9 – Array of LEDs in Each Test Panel.

Section #	1	2	3
Current (A)	1.113 A	1.159 A	1.126 A

Maximum difference between sections was <5%.

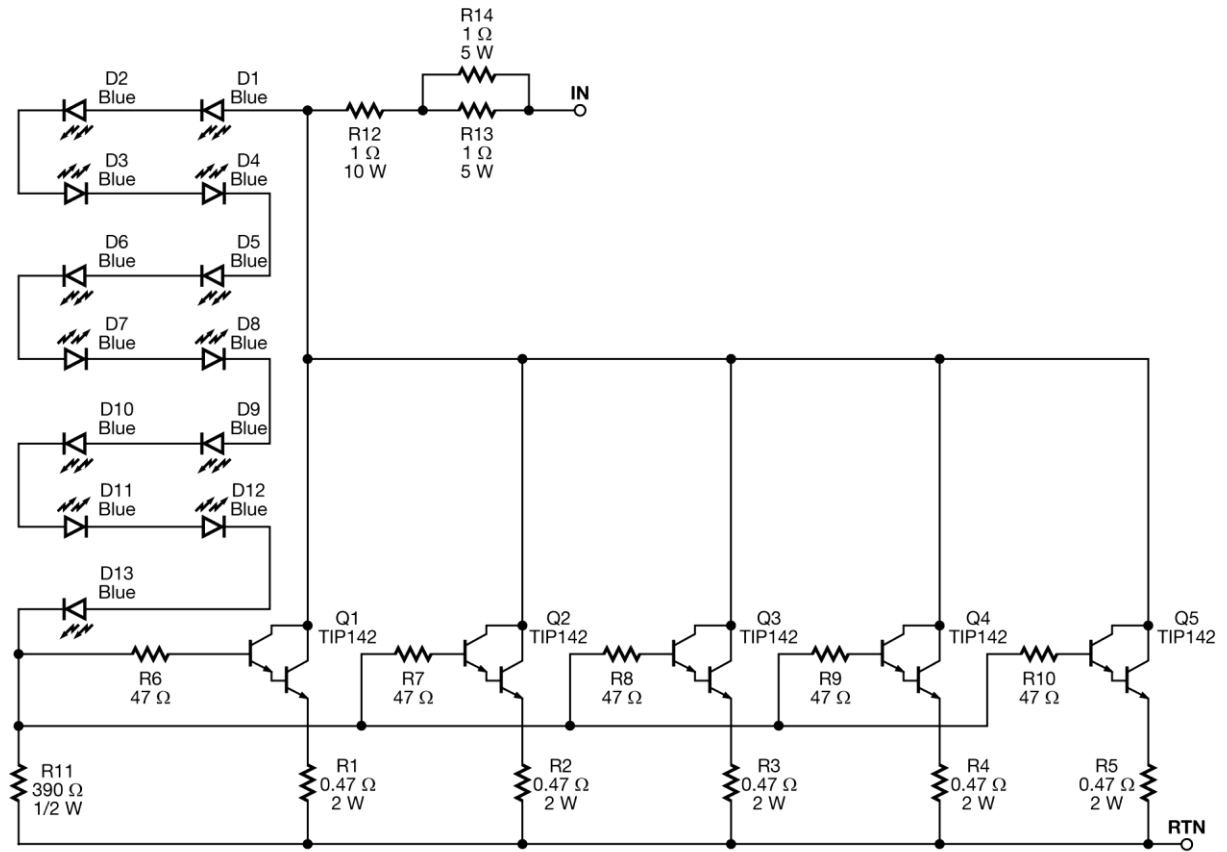


7.2 定電壓負載

Since this power supply has a constant current output tailored for a relatively fixed constant voltage load, the usual constant current electronic load cannot be used for testing. For bench testing at maximum power, a constant resistance load can be used, set such that the supply output is at maximum current and an output voltage of 43-44 V, as indicated by the V-I curve shown in Figure 7. Other testing, including dimming and gain-phase, will require the actual LED load or a constant voltage load that closely mimics its characteristics.

The streetlight LED as a load was both large and heavy. In order to facilitate EMI and surge testing, a constant voltage load was constructed to emulate the behavior of the LED array in a much smaller package. The circuit is shown in Figure 8. The load consists of paralleled power Darlington transistors Q1-5, each with an emitter resistor (R1-5) to facilitate current sharing. Base resistors R6-10 help prevent oscillation. A string of thirteen 3 mm blue LEDs (D1-13) are used as a voltage reference to mimic the characteristics of the LED panel. Resistor R11 is adjusted to vary the voltage at which the load turns on to match the characteristics of the LED panel. Resistors R12-14 add extra impedance in series with the load to approximate the characteristics of the LED panel. The completed array with heat sink is shown in Figure 9. A small fan was used to cool the heat sink when the load was operated for extended periods at full power. The V-I characteristics of the CV load are shown superimposed on those of the LED array in Figure 10. An electronic load with appropriate rating and a constant voltage option (with some series resistance) could also be used for testing, but this load has the advantage that no external AC power is needed.





PI-7134-092513

Figure 10 – Constant Voltage Load Schematic.



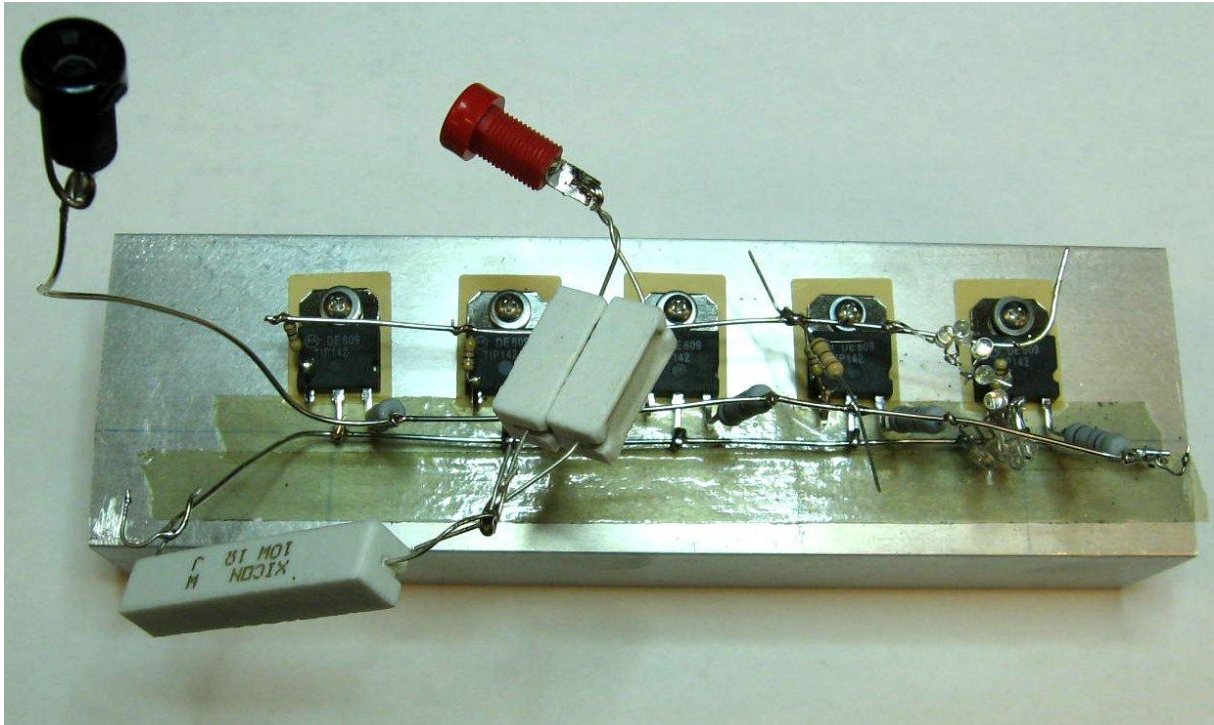


Figure 11 – Constant Voltage Load with Heat Sink.



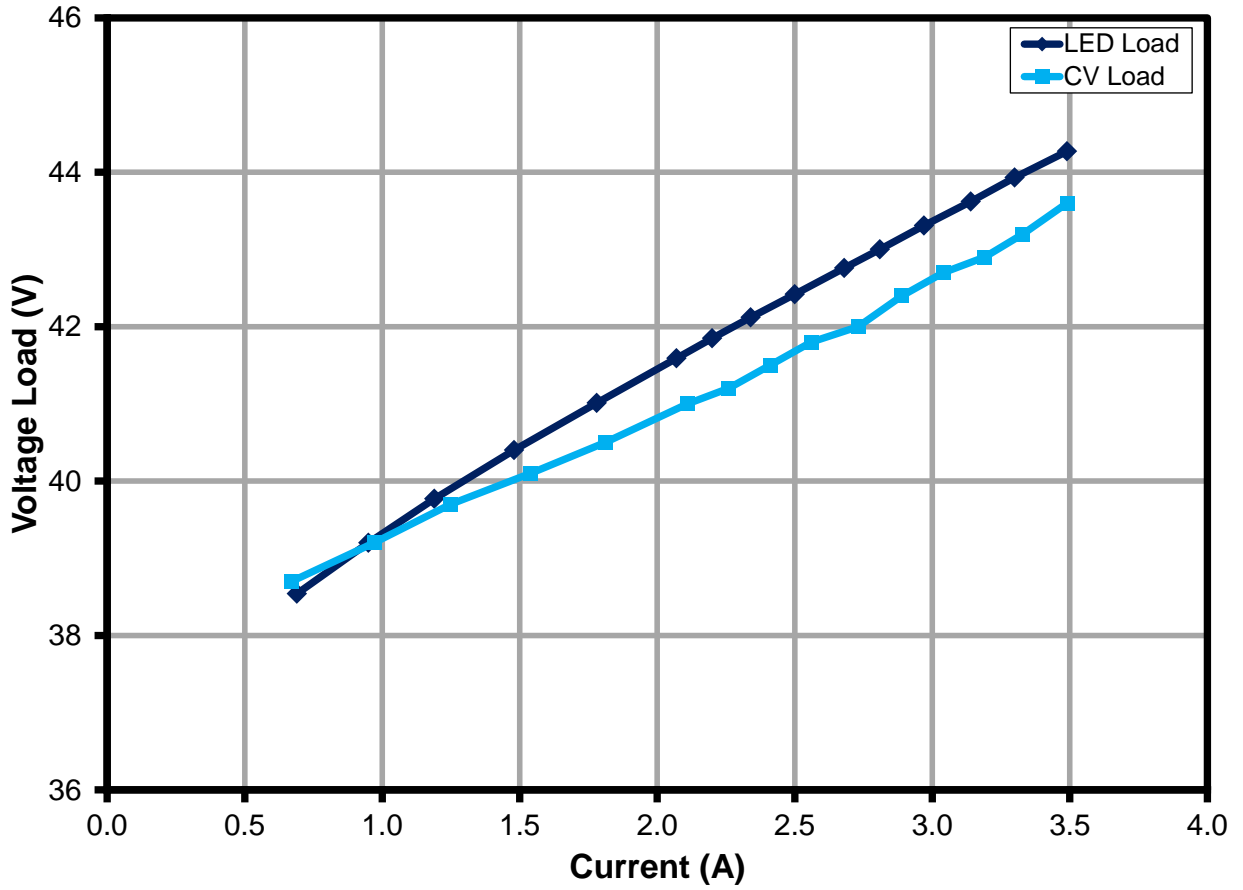


Figure 12 – Comparison of Streetlight LED Array V-I Characteristic with CV Load.



8 磁性元件

8.1 PFC 電感器 (L2) 規格

8.1.1 電氣圖

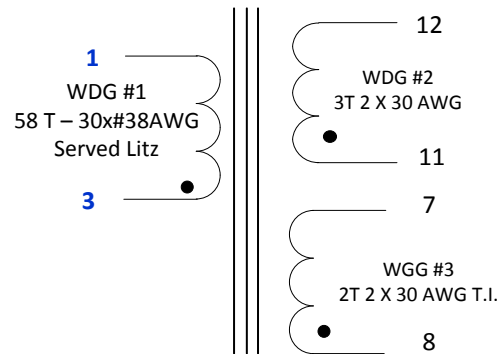


Figure 13 – PFC Choke Electrical Diagram.

8.1.2 電氣規格

Inductance	Pins 1-3 measured at 100 kHz, 0.4 V _{RMS} .	437 μ H +5%
Resonant Frequency	Pins 1-3. N/A	kHz (Min.)

8.1.3 材料

Item	Description
[1]	Core: TDK Core: PC44PQ32/20Z, gap for A _{LG} of 130 nH/T ² .
[2]	Bobbin: BPQ32/20-112CPFR – TDK.
[3]	Litz Wire: 30 x #38 AWG Single Coated Solderable, Served.
[4]	Tape, Polyester Film: 3M 1350-F1 or equivalent, 9.0 mm wide.
[5]	Magnet Wire, 30 AWG, Solderable Double Coated.
[6]	Triple Insulated Wire, 30 AWG, Furukawa TEX-E or equivalent.
[7]	Varnish: Dolph BC-359, or equivalent.



8.1.4 建構圖

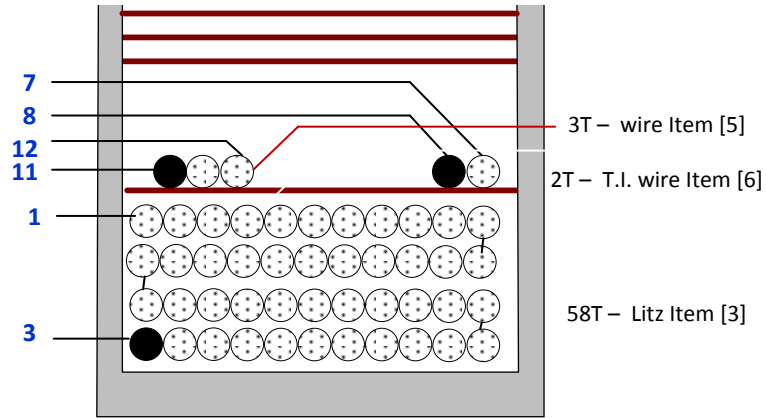


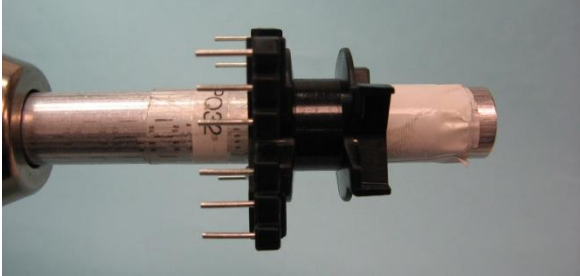
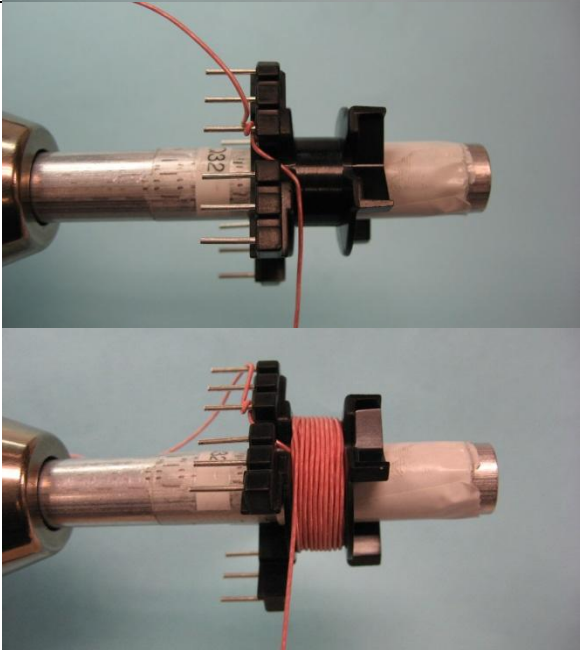
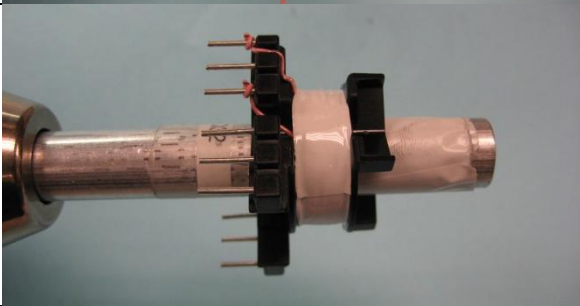
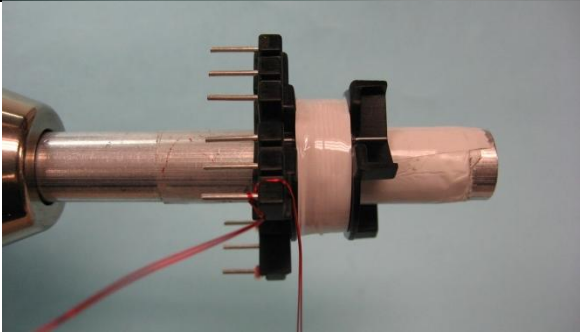
Figure 14 – PFC Inductor Build Diagram.

8.1.5 繞組指示

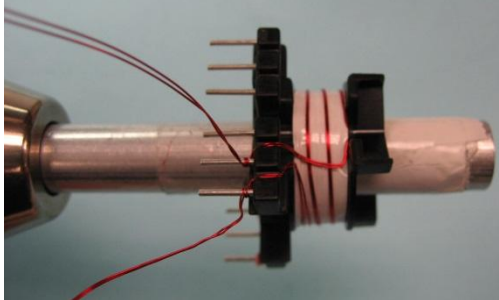
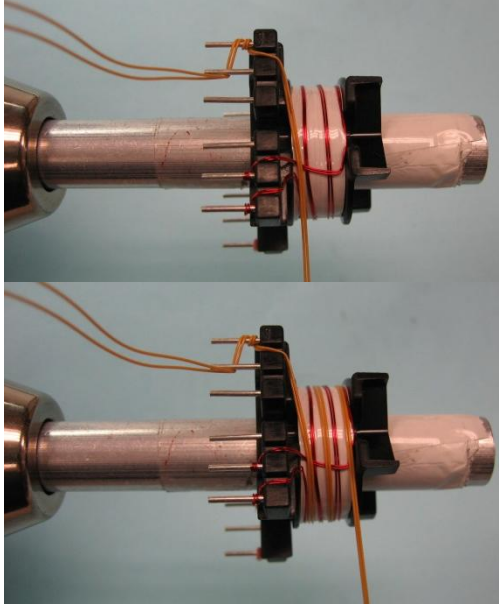
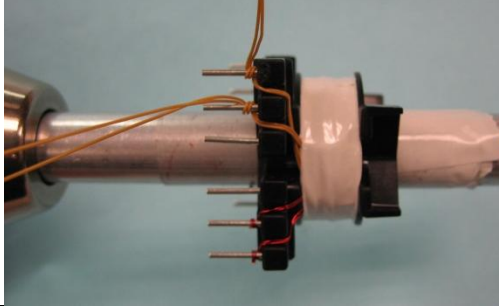

Winding Preparation	Place the bobbin on the mandrel with the pin side is on the left side. Winding direction is clockwise direction.
Winding #1	Starting at pin 3, wind 58 turns of Litz wire item [3], finish at pin 1.
Insulation	Apply one layer of tape item [4]
Winding #2	Starting at pin 11, wind 3 bifilar turns of wire, item [5]. Spread turns evenly across bobbin window. Finish at Pin 12.
Winding #3	Starting at pin 8, wind 2 bifilar turns of wire, item [6], directly on top of previous winding. Spread turns evenly across bobbin window. Finish at pin 7.
Insulation	Apply 3 layers of tape item [4].
Final Assembly	Grind core to specified inductance. Secure core halves with tape. Remove pins 2, 4, and 9. Dip varnish with item [7].



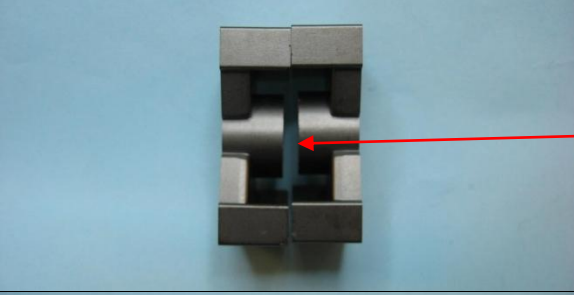
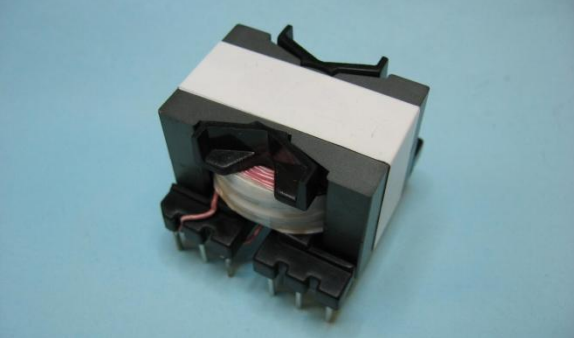
8.1.6 繞線示意圖

<p>Winding Preparation</p>		<p>Place the bobbin on the mandrel with the pin side is on the left side. Winding direction is clockwise direction</p>
<p>Winding #1</p>		<p>Starting at pin 3, wind 58 turns with 30x #38 served Litz wire, item [3].</p>
<p>Insulation</p>		<p>Apply 1 layer of insulating tape, item [4]. Terminate wire at pin 1</p>
<p>Winding #2</p>		<p>Starting at pin 11, wind 3 bifilar turns with #30 AWG double coated wire, item [5].</p>



		<p>Terminate wire at pin 12.</p> <p>Do not apply insulating tape to this winding.</p>
<p>Winding #3</p>		<p>Starting at pin 8, wind 2 bifilar turns with #30 AWG triple insulated wire, item [6].</p>
<p>Insulation</p>		<p>Apply 3 layers of insulating tape, item [4].</p> <p>Terminate wire at pin 7</p>
<p>Solder Terminations</p>		<p>Solder all wire terminations at pins 1, 3, 7, 8, 11, and 12</p>



Core Grinding		Grind core for specified inductance.
Final Assembly		Secure core halves with tape. Remove pins 2, 4, and 9.



8.2 LLC 變壓器 (T1) 規格

8.2.1 電氣圖

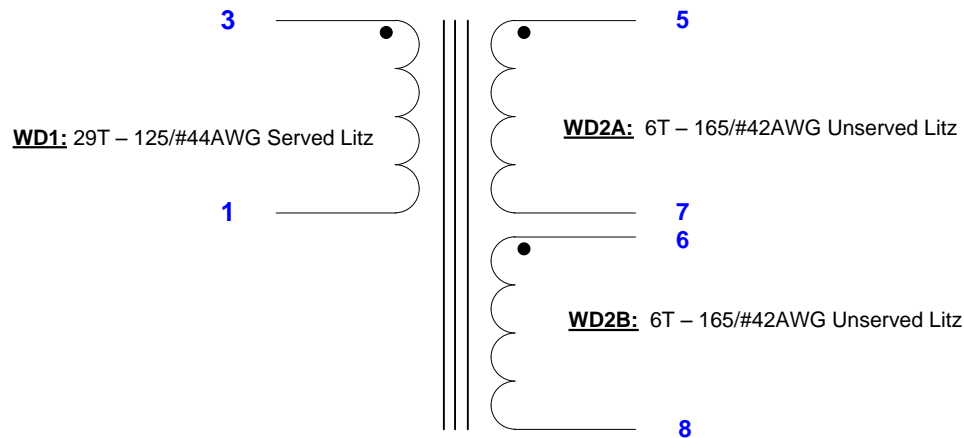


Figure 15 – LLC Transformer Schematic.

8.2.2 電氣規格

Electrical Strength	1 second, 60 Hz, from pins 1-3 to pins 5-8.	3000 VAC
Primary Inductance	Pins 1-3, all other windings open, measured at 100 kHz, 0.4 V _{RMS} .	340 μH ±10%
Resonant Frequency	Pins 2-5, all other windings open.	1800 kHz (Min)
Primary Leakage Inductance	Pins 1-5, with pins 5-8 shorted, measured at 100 kHz, 0.4 V _{RMS} .	49 μH ±5%

8.2.3 材料

Item	Description
[1]	Core Pair: Itacoil NFEV25A, PW4 material, gap for A _{LG} of 404 nH/T ² .
[2]	Bobbin: Itacoil RCEV25A.
[3]	Bobbin Cover, Itacoil GSEV25A.
[4]	Tape: Polyester Film, 3M 1350F-1 or equivalent, 12 mm wide.
[5]	Litz wire: 165/#42 Single Coated, Unserved.
[6]	Litz wire: 125/#44 Single Coated, Served.
[7]	Copper Tape, 3M-1181; or equivalent, 10 mm wide.
[8]	Wire, 20 AWG, Black, Stranded, UL 1015 Alpha 3073 BK or equivalent.



8.2.4 建構圖

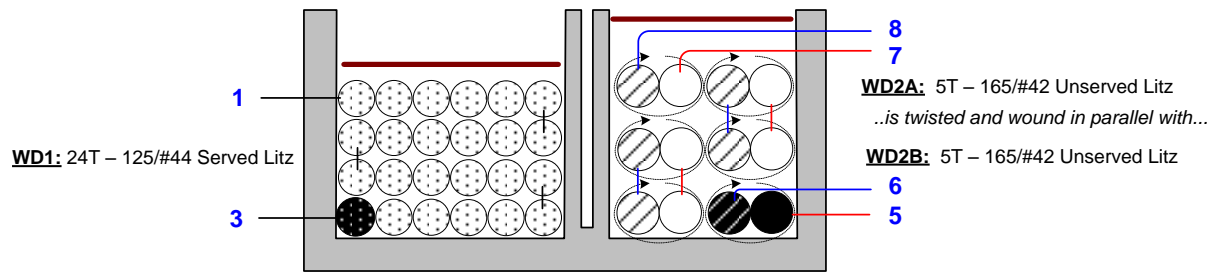


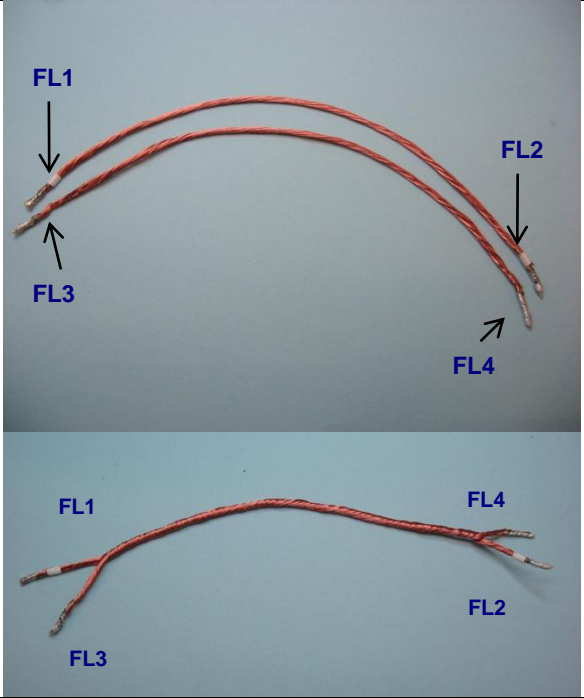
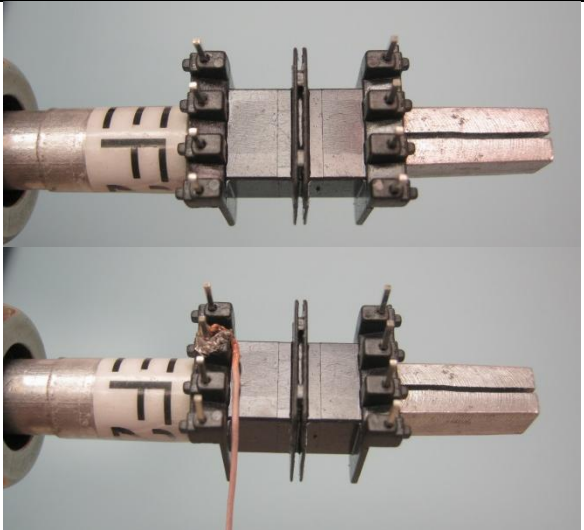
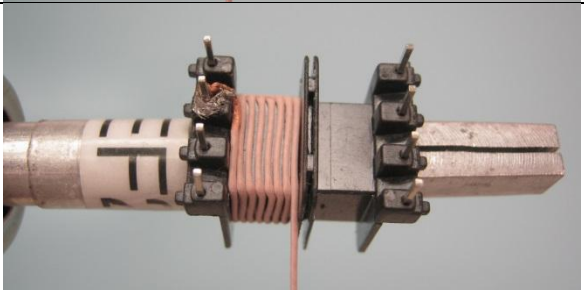
Figure 16 – LLC Transformer Build Diagram.

8.2.5 繞組指示

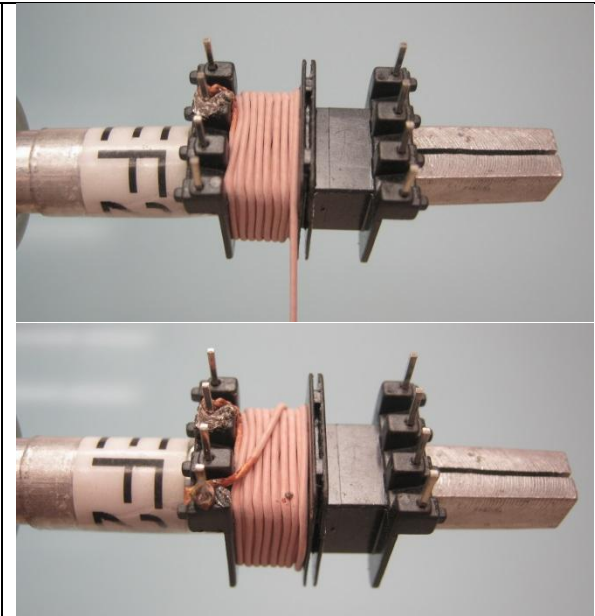
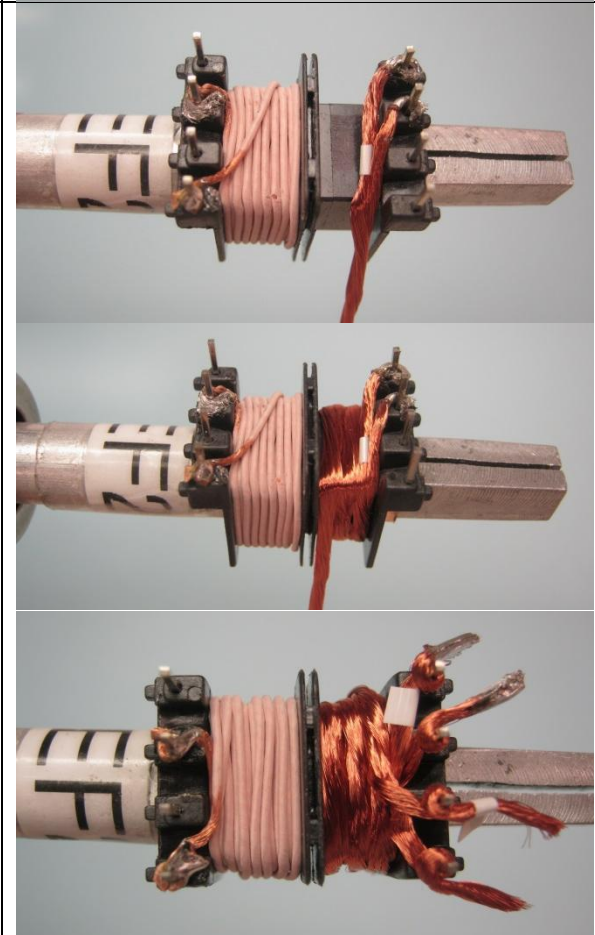
Secondary Wire Preparation	Prepare 2 strands of wire item [5] 12" length, tin ends. Label one strand to distinguish from other and designate it as FL1, FL2. Other strand will be designated as FL3 and FL4. Twist these 2 strands together ~20 twists evenly along length leaving 1" free at each end. See pictures below.
WD1 (Primary)	Place the bobbin item [2] on the mandrel with primary chamber on the left side. Note: primary chamber is wider than secondary chamber. Starting on pin 3, wind 29 turns of served Litz wire item [6] in 5 layers, and finish on Pin 1.
WD2A & WD2B (Secondary)	Using unserved Litz assembly prepared in step 1, start with FL1 on pins 5 and FL3 on pin 6, tightly wind 6 turns in secondary chamber. Finish with FL2 on pin 6 and FL4 on pin 8.
Bobbin Cover	Slide bobbin cover [3] into grooves in bobbin flanges as shown. Make sure cover is securely seated.
Finish	Remove pins 2, 4 of bobbin. Grind core halves [1] for specified inductance. Assemble and secure core halves using circumferential turn of copper tape [7] as shown, overlap ends, and solder. Solder 3" termination lead of stranded wire item [8] to core band close to pin 4 as shown, secure with two turns of tape item [4].



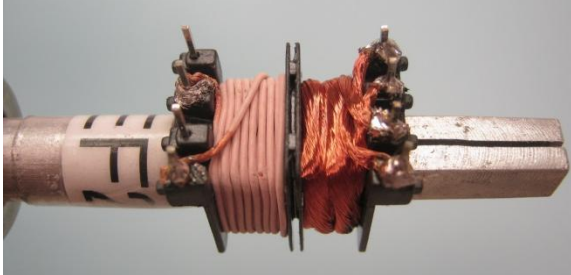
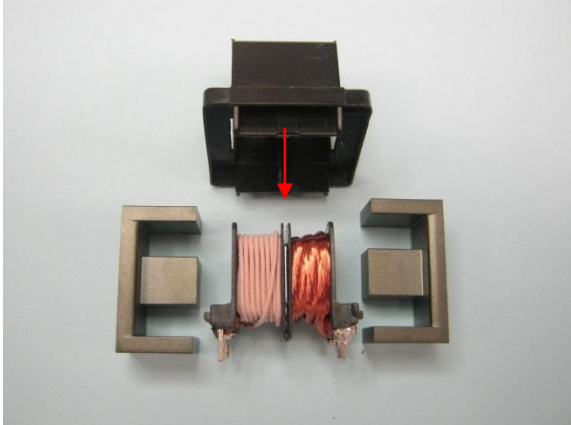
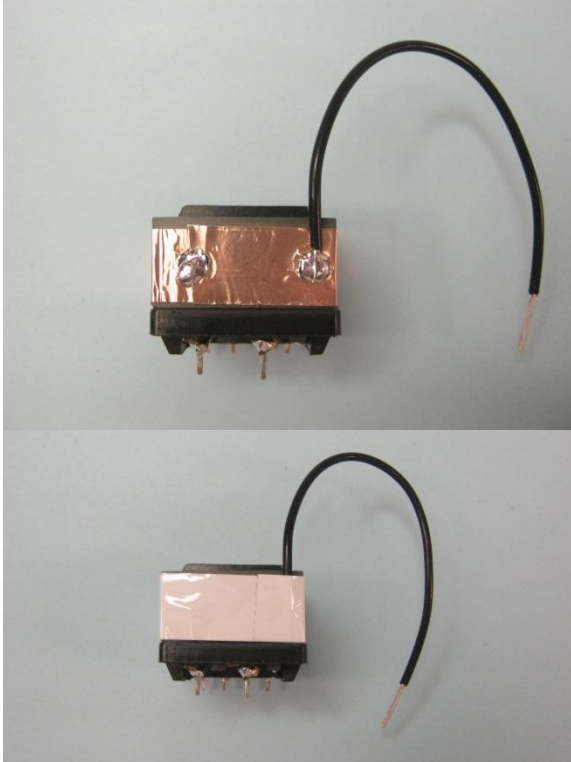
8.2.6 繞線示意圖

<p>Secondary Wire Preparation</p>		<p>Prepare 2 strands of wire item [7] 12" length, tin ends. Label one strand to distinguish from other and designate it as FL1, FL2. Other strand will be designated as FL3 and FL4. Twist these 2 strands together ~20 twists evenly along length leaving 1" free at each end.</p>
<p>WD1 (Primary)</p>		<p>Place the bobbin item [2] on the mandrel with primary chamber on the left side. Note: primary chamber is wider than secondary chamber. Starting on pin 3,</p>
<p>WD1 (Primary) (Cont'd)</p>		<p>Wind 29 turns of served Litz wire item [6] in 5 layers, and finish on pin 1.</p>



		
<p>WD2A & WD2B (Secondary)</p>		<p>Using unserved Litz assembly prepared in step 1, start with FL1 on pins 5 and FL3 on pin 6, tightly wind 6 turns in secondary chamber. Finish with FL2 on pin 6 and FL4 on pin 8.</p>



		
<p>Bobbin Cover</p>		<p>Slide bobbin cover [3] into grooves in bobbin flanges as shown. Make sure cover is securely seated.</p>
<p>Finish</p>		<p>Remove pins 2, 4 of bobbin. Grind core halves [1] for specified inductance. Assemble and secure core halves using circumferential turn of copper tape [7] as shown, overlap ends, and solder. Solder 3" termination lead of stranded wire item [8] to core band close to pin 4 as shown, secure with two turns of tape item [4].</p>



8.3 輸出電感器 (L3) 規格

8.3.1 電氣圖

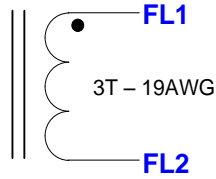


Figure 17 – Inductor Electrical Diagram.

8.3.2 電氣規格

Inductance	Pins FL1-FL2, all other windings open, measured at 100 kHz, 0.4 V _{RMS} .	300 nH, ±15%
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8.3.3 材料清單

Item	Description
[1]	Powdered Iron Toroidal Core: Micrometals T30-26.
[2]	Magnet wire: #19 AWG Solderable Double Coated.

8.3.4 構造細節



Figure 16 – Finished Part, Front View. Tin Leads to within ~ 1/8" of Toroid Body.



9 PFC 設計試算表

In this design, the spreadsheet generated warnings concerning the high value of KP selected, and for the operating current density of the Litz wire size selected for this design.

A high KP value can impact power factor and distortion, so a design generating this warning should be checked for any adverse impact. **This design met the requirements for power factor and harmonic distortion, and the high KP value allowed selection of a ferrite core for the PFC inductor, with consequent efficiency improvement.**

A warning for current density indicates that the design should be checked in its initial stages for excessive temperature rise in the PFC inductor. The guidelines incorporated the spreadsheet are conservative, so that a warning does not necessarily mean that a given design will fail thermally. **The measured temperature rise for this design was satisfactory.**

Hiper_PFS-II_Boost_062013; Rev.1.1; Copyright Power Integrations 2013	INPUT	INFO	OUTPUT	UNITS	Hiper_PFS-II_Boost_062013_Rev1-1.xls; Continuous Mode Boost Converter Design Spreadsheet
Enter Applications Variables					
Input Voltage Range			Universal		Input voltage range
VACMIN			90	V	Minimum AC input voltage
VACMAX			265	V	Maximum AC input voltage
VBROWNIN			76.69		Expected Minimum Brown-in Voltage
VBROWNOUT			68.33	V	Specify brownout voltage.
VO			385.00	V	Nominal Output voltage
PO	160.00		160.00	W	Nominal Output power
fL			50	Hz	Line frequency
TA Max			40	deg C	Maximum ambient temperature
n			0.93		Enter the efficiency estimate for the boost converter at VACMIN
KP	0.750	Warning	0.75		!!!Warning. KP is too high. Reduce KP to below 0.675 for Ferrite cores and to below 0.8 for other core types
VO_MIN			365.75	V	Minimum Output voltage
VO_RIPPLE_MAX			20	V	Maximum Output voltage ripple
tHOLDUP	18.00		18	ms	Holdup time
VHOLDUP_MIN			310	V	Minimum Voltage Output can drop to during holdup
I_INRUSH			40	A	Maximum allowable inrush current
Forced Air Cooling	no		no		Enter "Yes" for Forced air cooling. Otherwise enter "No"
PFS Parameters					
PFS Part Number	PFS7326H		PFS7326H		Selected PFS device
MODE	EFFICIENCY		EFFICIENCY		Mode of operation of PFS. For full mode enter "FULL" otherwise enter "EFFICIENCY" to indicate efficiency mode
R_RPIN			49.9	k-ohms	R pin resistor value
C_RPIN			1.00	nF	R pin capacitor value
IOCP min			6.80	A	Minimum Current limit



IOCP typ			7.20	A	Typical current limit
IOCP max			7.50	A	Maximum current limit
RDSON			0.62	ohms	Typical RDson at 100 °C
RV1			1.50	Mohms	Line sense resistor 1
RV2			1.50	Mohms	Line sense resistor 2
RV3			1.00	Mohms	Line sense resistor 3
C_VCC			3.30	uF	Supply decoupling capacitor
R_VCC			15.00	ohms	VCC resistor
C_V			22.00	nF	V pin decoupling capacitor
C_C			22.00	nF	Feedback C pin decoupling capacitor
Power good Vo lower threshold VPG(L)			333.00	V	Power good Vo lower threshold voltage
PGT set resistor			103.79	kohm	Power good threshold setting resistor
FS_PK			60.2	kHz	Estimated frequency of operation at crest of input voltage (at VACMIN)
FS_AVG			50.2	kHz	Estimated average frequency of operation over line cycle (at VACMIN)
IP			3.97	A	MOSFET peak current
PFS_IRMS			1.67	A	PFS MOSFET RMS current
PCOND_LOSS_PFS			1.73	W	Estimated PFS conduction losses
PSW_LOSS_PFS			0.78	W	Estimated PFS switching losses
PFS_TOTAL			2.51	W	Total Estimated PFS losses
TJ Max			100	deg C	Maximum steady-state junction temperature
Rth-JS			3.00	degC/W	Maximum thermal resistance (Junction to heatsink)
HEATSINK Theta-CA			15.30	degC/W	Maximum thermal resistance of heatsink
Basic Inductor Calculation					
LPFC			437	uH	Value of PFC inductor at peak of VACMIN and Full Load
LPFC (0 Bias)			437	uH	Value of PFC inductor at No load. This is the value measured with LCR meter
LP_TOL	5.00		5	%	Tolerance of PFC Inductor Value
LPFC_RMS			1.97	A	Inductor RMS current (calculated at VACMIN and Full Load)
Inductor Construction Parameters					
Core Type	Ferrite		Ferrite		Enter "Sendust", "Pow Iron" or "Ferrite"
Core Material	Auto		PC44		Select from 60u, 75u, 90u or 125 u for Sendust cores. Fixed at PC44 or equivalent for Ferrite cores. Fixed at 52 material for Pow Iron cores.
Core Geometry	Auto		PQ		Select from Toroid or EE for Sendust cores and from EE, or PQ for Ferrite cores
Core	PQ32/20		PQ32/20		Core part number
AE			170	mm^2	Core cross sectional area
LE			55.5	mm	Core mean path length
AL			6530	nH/t^2	Core AL value
VE			9.44	cm^3	Core volume
HT			5.12	mm	Core height/Height of window
MLT			67.1	cm	Mean length per turn
BW			8.98	mm	Bobbin width
NL			58		Inductor turns
LG			2.06	mm	Gap length (Ferrite cores only)
ILRMS			1.97	A	Inductor RMS current
Wire type	LITZ		LITZ		Select between "Litz" or "Regular" for double coated magnet wire
AWG	38		38	AWG	Inductor wire gauge
Filar	30		30		Inductor wire number of parallel strands



OD			0.102	mm	Outer diameter of single strand of wire
AC Resistance Ratio			1.01		Ratio of AC resistance to the DC resistance (using Dowell curves)
J		Warning	8.11	A/mm ²	!!! Warning Current density is too high and may cause heating in the inductor wire. Reduce J
BP_TARGET			3500	Gauss	Target flux density at VACMIN (Ferrite cores only)
BM			1757	Gauss	Maximum operating flux density
BP			3487	Gauss	Peak Flux density (Estimated at VBROWNOUT)
LPFC_CORE_LOSS			0.09	W	Estimated Inductor core Loss
LPFC_COPPER_LOSS			1.80	W	Estimated Inductor copper losses
LPFC_TOTAL LOSS			1.89	W	Total estimated Inductor Losses
FIT			79.72%	%	Estimated FIT factor for inductor
Layers			5.1		Estimated layers in winding
Critical Parameters					
IRMS			1.91	A	AC input RMS current
IO_AVG			0.42	A	Output average current
Output Diode (DO)					
Part Number	Auto		INTERNAL		PFC Diode Part Number
Type			SPECIAL		Diode Type - Special - Diodes specially catered for PFC applications, SiC - Silicon Carbide type, UF - Ultrafast recovery type
Manufacturer			PI		Diode Manufacturer
VRRM			600	V	Diode rated reverse voltage
IF			3	A	Diode rated forward current
TRR			31	ns	Diode Reverse recovery time
VF			1.47	V	Diode rated forward voltage drop
PCOND_DIODE			0.61	W	Estimated Diode conduction losses
PSW_DIODE			0.16	W	Estimated Diode switching losses
P_DIODE			0.77	W	Total estimated Diode losses
TJ Max			100	deg C	Maximum steady-state operating temperature
Rth-JS			3.85	degC/W	Maximum thermal resistance (Junction to heatsink)
HEATSINK Theta-CA			15.30	degC/W	Maximum thermal resistance of heatsink
Output Capacitor					
CO	Auto		120.00	uF	Minimum value of Output capacitance
VO_RIPPLE_EXPECTED			11.9	V	Expected ripple voltage on Output with selected Output capacitor
T_HOLDUP_EXPECTED			19.5	ms	Expected holdup time with selected Output capacitor
ESR_LF			1.38	ohms	Low Frequency Capacitor ESR
ESR_HF			0.55	ohms	High Frequency Capacitor ESR
IC_RMS_LF			0.29	A	Low Frequency Capacitor RMS current
IC_RMS_HF			0.85	A	High Frequency Capacitor RMS current
CO_LF_LOSS			0.12	W	Estimated Low Frequency ESR loss in Output capacitor
CO_HF_LOSS			0.39	W	Estimated High frequency ESR loss in Output capacitor
Total CO LOSS			0.51	W	Total estimated losses in Output Capacitor
Input Bridge (BR1) and Fuse (F1)					
I ² t Rating			8.43	A ² s	Minimum I ² t rating for fuse
Fuse Current rating			3.00	A	Minimum Current rating of fuse
VF			0.90	V	Input bridge Diode forward Diode drop
IAVG			1.86	A	Input average current at 70 VAC.



PIV_INPUT BRIDGE			375	V	Peak inverse voltage of input bridge
PCOND_LOSS_BRIDGE			3.10	W	Estimated Bridge Diode conduction loss
CIN			0.47	uF	Input capacitor. Use metallized polypropylene or film foil type with high ripple current rating
RT			9.37	ohms	Input Thermistor value
D_Precharge			1N5407		Recommended precharge Diode
Feedback Components					
R1			1.50	Mohms	Feedback network, first high voltage divider resistor
R3			1.60	Mohms	Feedback network, third high voltage divider resistor
R2			787.00	kohms	Feedback network, second high voltage divider resistor
C1			47.00	nF	Feedback network, loop speedup capacitor
R4			60.40	kohms	Feedback network, lower divider resistor
R6			487.00	kohms	Feedback network - pole setting resistor
R7			6.98	kohms	Feedback network - zero setting resistor
C2			47.00	nF	Feedback component- noise suppression capacitor
R5			3.00	kohms	Damping resistor in serie with C3
C3			2.20	uF	Feedback network - compensation capacitor
D1			BAV116		Feedback network - capacitor failure detection Diode
Loss Budget (Estimated at VACMIN)					
PFS Losses			2.51	W	Total estimated losses in PFS
Boost diode Losses			0.77	W	Total estimated losses in Output Diode
Input Bridge losses			3.10	W	Total estimated losses in input bridge module
Inductor losses			1.89	W	Total estimated losses in PFC choke
Output Capacitor Loss			0.51	W	Total estimated losses in Output capacitor
Total losses			8.78	W	Overall loss estimate
Efficiency			0.95		Estimated efficiency at VACMIN. Verify efficiency at other line voltages



10 LLC 變壓器設計試算表

HiperLCS_040312; Rev.1.3; Copyright Power Integrations 2012	INPUTS	INFO	OUTPUTS	UNITS	HiperLCS_040312_Rev1-3.xls; HiperLCS Half-Bridge, Continuous mode LLC Resonant Converter Design Spreadsheet
Enter Input Parameters					
Vbulk_nom			380	V	Nominal LLC input voltage
Vbrownout	287		287	V	Brownout threshold voltage. HiperLCS will shut down if voltage drops below this value. Allowable value is between 65% and 76% of Vbulk_nom. Set to 65% for max holdup time
Vbrownin			362	V	Startup threshold on bulk capacitor
VOV_shut			476	V	OV protection on bulk voltage
VOV_restart			459	V	Restart voltage after OV protection.
CBULK	120.00		120	uF	Minimum value of bulk cap to meet holdup time requirement; Adjust holdup time and Vbrownout to change bulk cap value
tHOLDUP			23.8	ms	Bulk capacitor hold up time
Enter LLC (secondary) outputs			The spreadsheet assumes AC stacking of the secondaries		
VO1	43.00		43.0	V	Main Output Voltage. Spreadsheet assumes that this is the regulated output
IO1	3.50		3.5	A	Main output maximum current
VD1	0.70		0.70	V	Forward voltage of diode in Main output
PO1			151	W	Output Power from first LLC output
VO2			0.0	V	Second Output Voltage
IO2			0.0	A	Second output current
VD2			0.70	V	Forward voltage of diode used in second output
PO2			0.00	W	Output Power from second LLC output
P_LL			151	W	Specified LLC output power
LCS Device Selection					
Device	LCS702		LCS702		LCS Device
RDS-ON (MAX)			1.39	ohms	RDS-ON (max) of selected device
Coss			250	pF	Equivalent Coss of selected device
Cpri			40	pF	Stray Capacitance at transformer primary
Pcond_loss			1.5	W	Conduction loss at nominal line and full load
Tmax-hs			90	deg C	Maximum heatsink temperature
Theta J-HS			9.1	deg C/W	Thermal resistance junction to heatsink (with grease and no insulator)
Expected Junction temperature			103	deg C	Expected Junction temperature
Ta max			50	deg C	Expected max ambient temperature
Theta HS-A			27	deg C/W	Required thermal resistance heatsink to ambient
LLC Resonant Parameter and Transformer Calculations (generates red curve)					
Vres_target	380		380	V	Desired Input voltage at which power train operates at resonance. If greater than Vbulk_nom, LLC operates below resonance at VBULK.
Po			153	W	LLC output power including diode loss
Vo			43.70	V	Main Output voltage (includes diode drop) for calculating Nsec and turns ratio
f_target			250	kHz	Desired switching frequency at Vbulk_nom. 66 kHz to 300 kHz, recommended 180-250 kHz
Lpar			291	uH	Parallel inductance. (Lpar = Lopen - Lres for integrated transformer; Lpar = Lmag for non-integrated low-leakage transformer)
Lpri			341	uH	Primary open circuit inductance for integrated transformer; for low-leakage transformer it is sum of primary inductance and series inductor. If left blank, auto-calculation shows value necessary for slight loss of ZVS at ~80% of Vnom
Lres	50.00		50.0	uH	Series inductance or primary leakage inductance of integrated transformer; if left blank auto-calculation is for K=4
Kratio			5.8		Ratio of Lpar to Lres. Maintain value of K such that 2.1 < K < 11. Preferred Lres is such that K<7.
Cres	8.20		8.2	nF	Series resonant capacitor. Red background cells produce red



				graph. If Lpar, Lres, Cres, and n_RATIO_red_graph are left blank, they will be auto-calculated
Lsec		14.618	uH	Secondary side inductance of one phase of main output; measure and enter value, or adjust value until f_predicted matches what is measured ;
m		50	%	Leakage distribution factor (primary to secondary). >50% signifies most of the leakage is in primary side. Gap physically under secondary yields >50%, requiring fewer primary turns.
n_eq		4.47		Turns ratio of LLC equivalent circuit ideal transformer
Npri	29.0	29.0		Primary number of turns; if input is blank, default value is auto-calculation so that f_predicted = f_target and m=50%
Nsec	6.0	6.0		Secondary number of turns (each phase of Main output). Default value is estimate to maintain BAC<=200 mT, using selected core (below)
f_predicted		227	kHz	Expected frequency at nominal input voltage and full load; Heavily influenced by n_eq and primary turns
f_res		249	kHz	Series resonant frequency (defined by series inductance Lres and C)
f_brownout		155	kHz	Expected switching frequency at Vbrownout, full load. Set HiperLCS minimum frequency to this value.
f_par		95	kHz	Parallel resonant frequency (defined by Lpar + Lres and C)
f_inversion		135	kHz	LLC full load gain inversion frequency. Operation below this frequency results in operation in gain inversion region.
Vinversion		247	V	LLC full load gain inversion point input voltage
Vres_expected		390	V	
RMS Currents and Voltages				
IRMS_LLC_Primary		1.03	A	Primary winding RMS current at full load, Vbulk_nom and f_predicted
Winding 1 (Lower secondary Voltage) RMS current		2.8	A	Winding 1 (Lower secondary Voltage) RMS current
Lower Secondary Voltage Capacitor RMS current		1.8	A	Lower Secondary Voltage Capacitor RMS current
Winding 2 (Higher secondary Voltage) RMS current		0.0	A	Winding 2 (Higher secondary Voltage) RMS current
Higher Secondary Voltage Capacitor RMS current		0.0	A	Higher Secondary Voltage Capacitor RMS current
Cres_Vrms		88	V	Resonant capacitor AC RMS Voltage at full load and nominal input voltage
Virtual Transformer Trial - (generates blue curve)				
New primary turns		29.0		Trial transformer primary turns; default value is from resonant section
New secondary turns		6.0		Trial transformer secondary turns; default value is from resonant section
New Lpri		341	uH	Trial transformer open circuit inductance; default value is from resonant section
New Cres		8.2	nF	Trial value of series capacitor (if left blank calculated value chosen so f_res same as in main resonant section above)
New estimated Lres		50.0	uH	Trial transformer estimated Lres
New estimated Lpar		291	uH	Estimated value of Lpar for trial transformer
New estimated Lsec		14.618	uH	Estimated value of secondary leakage inductance
New Kratio		5.8		Ratio of Lpar to Lres for trial transformer
New equivalent circuit transformer turns ratio		4.47		Estimated effective transformer turns ratio
V powertrain inversion new		247	V	Input voltage at LLC full load gain inversion point
f_res_trial		249	kHz	New Series resonant frequency
f_predicted_trial		227	kHz	New nominal operating frequency
IRMS_LLC_Primary		1.03	A	Primary winding RMS current at full load and nominal input voltage (Vbulk) and f_predicted_trial
Winding 1 (Lower secondary Voltage) RMS current		2.7	A	RMS current through Output 1 winding, assuming half sinusoidal waveshape



Lower Secondary Voltage Capacitor RMS current	1.6	A	Lower Secondary Voltage Capacitor RMS current
Winding 2 (Higher secondary Voltage) RMS current	2.7	A	RMS current through Output 2 winding; Output 1 winding is AC stacked on top of Output 2 winding
Higher Secondary Voltage Capacitor RMS current	0.0	A	Higher Secondary Voltage Capacitor RMS current
Vres_expected_trial	390	V	Expected value of input voltage at which LLC operates at resonance.
Transformer Core Calculations (Calculates From Resonant Parameter Section)			
Transformer Core	Auto	EEL25	Transformer Core
Ae	0.76	0.76	cm ² Enter transformer core cross-sectional area
Ve	5.35	5.35	cm ³ Enter the volume of core
Aw		107.9	mm ² Area of window
Bw	15.50	15.5	mm Total Width of Bobbin
Loss density		200.0	mW/cm ³ Enter the loss per unit volume at the switching frequency and BAC (Units same as kW/m ³)
MLT	5.20	5.2	cm Mean length per turn
Nchambers	2	2	Number of Bobbin chambers
Wsep	1.60	1.6	mm Winding separator distance (will result in loss of winding area)
Ploss		1.1	W Estimated core loss
Bpkfmin		155	mT First Quadrant peak flux density at minimum frequency.
BAC		211	mT AC peak to peak flux density (calculated at f_predicted, Vbulk at full load)
Primary Winding			
Npri		29.0	Number of primary turns; determined in LLC resonant section
Primary gauge	44	44	AWG Individual wire strand gauge used for primary winding
Equivalent Primary Metric Wire gauge		0.050	mm Equivalent diameter of wire in metric units
Primary litz strands	125	125	Number of strands in Litz wire; for non-litz primary winding, set to 1
Primary Winding Allocation Factor		50	% Primary window allocation factor - percentage of winding space allocated to primary
AW_P		48	mm ² Winding window area for primary
Fill Factor		25%	% Fill factor for primary winding (typical max fill is 60%)
Resistivity_25 C_Primary		75.42	m-ohm/m Resistivity in milli-ohms per meter
Primary DCR 25 C		113.73	m-ohm Estimated resistance at 25 C
Primary DCR 100 C		152.40	m-ohm Estimated resistance at 100 C (approximately 33% higher than at 25 C)
Primary RMS current		1.03	A Measured RMS current through the primary winding
ACR_Trif_Primary		259.81	m-ohm Measured AC resistance (at 100 kHz, room temperature), multiply by 1.33 to approximate 100 C winding temperature
Primary copper loss		0.27	W Total primary winding copper loss at 85 C
Primary Layers		3.02	Number of layers in primary Winding
Secondary Winding 1 (Lower secondary voltage OR Single output)			Note - Power loss calculations are for each winding half of secondary
Output Voltage		43.00	V Output Voltage (assumes AC stacked windings)
Sec 1 Turns		6.00	Secondary winding turns (each phase)
Sec 1 RMS current (total, AC+DC)		2.8	A RMS current through Output 1 winding, assuming half sinusoidal waveshape
Winding current (DC component)		1.75	A DC component of winding current
Winding current (AC RMS component)		2.17	A AC component of winding current
Sec 1 Wire gauge		42	AWG Individual wire strand gauge used for secondary winding
Equivalent secondary 1 Metric Wire gauge		0.060	mm Equivalent diameter of wire in metric units
Sec 1 litz strands	165	165	Number of strands used in Litz wire; for non-litz non-integrated transformer set to 1
Resistivity_25 C_sec1		35.93	m-ohm/m Resistivity in milli-ohms per meter
DCR_25C_Sec1		11.21	m-ohm Estimated resistance per phase at 25 C (for reference)
DCR_100C_Sec1		15.02	m-ohm Estimated resistance per phase at 100 C (approximately 33% higher than at 25 C)
DCR_Ploss_Sec1		0.37	W Estimated Power loss due to DC resistance (both secondary



			phases)
ACR_Sec1	15.25	m-ohm	Measured AC resistance per phase (at 100 kHz, room temperature), multiply by 1.33 to approximate 100 C winding temperature. Default value of ACR is twice the DCR value at 100 C
ACR_Ploss_Sec1	0.14	W	Estimated AC copper loss (both secondary phases)
Total winding 1 Copper Losses	0.51	W	Total (AC + DC) winding copper loss for both secondary phases
Capacitor RMS current	1.8	A	Output capacitor RMS current
Co1	1.8	uF	Secondary 1 output capacitor
Capacitor ripple voltage	3.0	%	Peak to Peak ripple voltage on secondary 1 output capacitor
Output rectifier RMS Current	2.8	A	Schottky losses are a stronger function of load DC current. Sync Rectifier losses are a function of RMS current
Secondary 1 Layers	1.00		Number of layers in secondary 1 Winding
Secondary Winding 2 (Higher secondary voltage)			Note - Power loss calculations are for each winding half of secondary
Output Voltage	0.00	V	Output Voltage (assumes AC stacked windings)
Sec 2 Turns	0.00		Secondary winding turns (each phase) AC stacked on top of secondary winding 1
Sec 2 RMS current (total, AC+DC)	2.8	A	RMS current through Output 2 winding; Output 1 winding is AC stacked on top of Output 2 winding
Winding current (DC component)	0.0	A	DC component of winding current
Winding current (AC RMS component)	0.0	A	AC component of winding current
Sec 2 Wire gauge	42	AWG	Individual wire strand gauge used for secondary winding
Equivalent secondary 2 Metric Wire gauge	0.060	mm	Equivalent diameter of wire in metric units
Sec 2 litz strands	0		Number of strands used in Litz wire; for non-litz non-integrated transformer set to 1
Resistivity_25 C_sec2	59292.53	m-ohm/m	Resistivity in milli-ohms per meter
Transformer Secondary MLT	5.20	cm	Mean length per turn
DCR_25C_Sec2	0.00	m-ohm	Estimated resistance per phase at 25 C (for reference)
DCR_100C_Sec2	0.00	m-ohm	Estimated resistance per phase at 100 C (approximately 33% higher than at 25 C)
DCR_Ploss_Sec1	0.00	W	Estimated Power loss due to DC resistance (both secondary halves)
ACR_Sec2	0.00	m-ohm	Measured AC resistance per phase (at 100 kHz, room temperature), multiply by 1.33 to approximate 100 C winding temperature. Default value of ACR is twice the DCR value at 100 C
ACR_Ploss_Sec2	0.00	W	Estimated AC copper loss (both secondary halves)
Total winding 2 Copper Losses	0.00	W	Total (AC + DC) winding copper loss for both secondary halves
Capacitor RMS current	0.0	A	Output capacitor RMS current
Co2	N/A	uF	Secondary 2 output capacitor
Capacitor ripple voltage	N/A	%	Peak to Peak ripple voltage on secondary 1 output capacitor
Output rectifier RMS Current	0.0	A	Schottky losses are a stronger function of load DC current. Sync Rectifier losses are a function of RMS current
Secondary 2 Layers	1.00		Number of layers in secondary 2 Winding
Transformer Loss Calculations			Does not include fringing flux loss from gap
Primary copper loss (from Primary section)	0.27	W	Total primary winding copper loss at 85 C
Secondary copper Loss	0.51	W	Total copper loss in secondary winding
Transformer total copper loss	0.78	W	Total copper loss in transformer (primary + secondary)
AW_S	48.38	mm^2	Area of window for secondary winding
Secondary Fill Factor	19%	%	% Fill factor for secondary windings; typical max fill is 60% for served and 75% for unserved Litz
Signal Pins Resistor Values			
f_min	155	kHz	Minimum frequency when optocoupler is cut-off. Only change this variable based on actual bench measurements
Dead Time	320	ns	Dead time
Burst Mode	1	1	Select Burst Mode: 1, 2, and 3 have hysteresis and have different frequency thresholds
f_max	847	kHz	Max internal clock frequency, dependent on dead-time setting. Is also start-up frequency
f_burst_start	382	kHz	Lower threshold frequency of burst mode, provides hysteresis. This is switching frequency at restart after a bursting off-period



f_burst_stop	437	kHz	Upper threshold frequency of burst mode; This is switching frequency at which a bursting off-period stops	
DT/BF pin upper divider resistor	6.79	k-ohms	Resistor from DT/BF pin to VREF pin	
DT/BF pin lower divider resistor	129	k-ohms	Resistor from DT/BF pin to G pin	
Rstart	5.79	k-ohms	Start-up resistor - resistor in series with soft-start capacitor; equivalent resistance from FB to VREF pins at startup. Use default value unless additional start-up delay is desired.	
Start up delay	0.0	ms	Start-up delay; delay before switching begins. Reduce R_START to increase delay	
Rfmin	46.2	k-ohms	Resistor from VREF pin to FB pin, to set min operating frequency; This resistor plus Rstart determine f_MIN. Includes 7% HiperLCS frequency tolerance to ensure f_min is below f_brownout	
C_softstart	0.33	uF	Softstart capacitor. Recommended values are between 0.1 uF and 0.47 uF	
Ropto	1.2	k-ohms	Resistor in series with opto emitter	
OV/UV pin lower resistor	19.60	19.6	k-ohm	Lower resistor in OV/UV pin divider
OV/UV pin upper resistor	2.93	M-ohm	Total upper resistance in OV/UV pin divider	
LLC Capacitive Divider Current Sense Circuit				
Slow current limit	2.35	A	8-cycle current limit - check positive half-cycles during brownout and startup	
Fast current limit	4.24	A	1-cycle current limit - check positive half-cycles during startup	
LLC sense capacitor	47	pF	HV sense capacitor, forms current divider with main resonant capacitor	
RLLC sense resistor	37.3	ohms	LLC current sense resistor, senses current in sense capacitor	
IS pin current limit resistor	220	ohms	Limits current from sense resistor into IS pin when voltage on sense R is < -0.5V	
IS pin noise filter capacitor	1.0	nF	IS pin bypass capacitor; forms a pole with IS pin current limit capacitor	
IS pin noise filter pole frequency	724	kHz	This pole attenuates IS pin signal	
Loss Budget				
LCS device Conduction loss	1.5	W	Conduction loss at nominal line and full load	
Output diode Loss	2.5	W	Estimated diode losses	
Transformer estimated total copper loss	0.78	W	Total copper loss in transformer (primary + secondary)	
Transformer estimated total core loss	1.1	W	Estimated core loss	
Total transformer losses	1.9	W	Total transformer losses	
Total estimated losses	5.8	W	Total losses in LLC stage	
Estimated Efficiency	96%	%	Estimated efficiency	
PIN	156	W	LLC input power	



11 散熱片

11.1 主要散熱片

11.1.1 主要散熱片鋼板

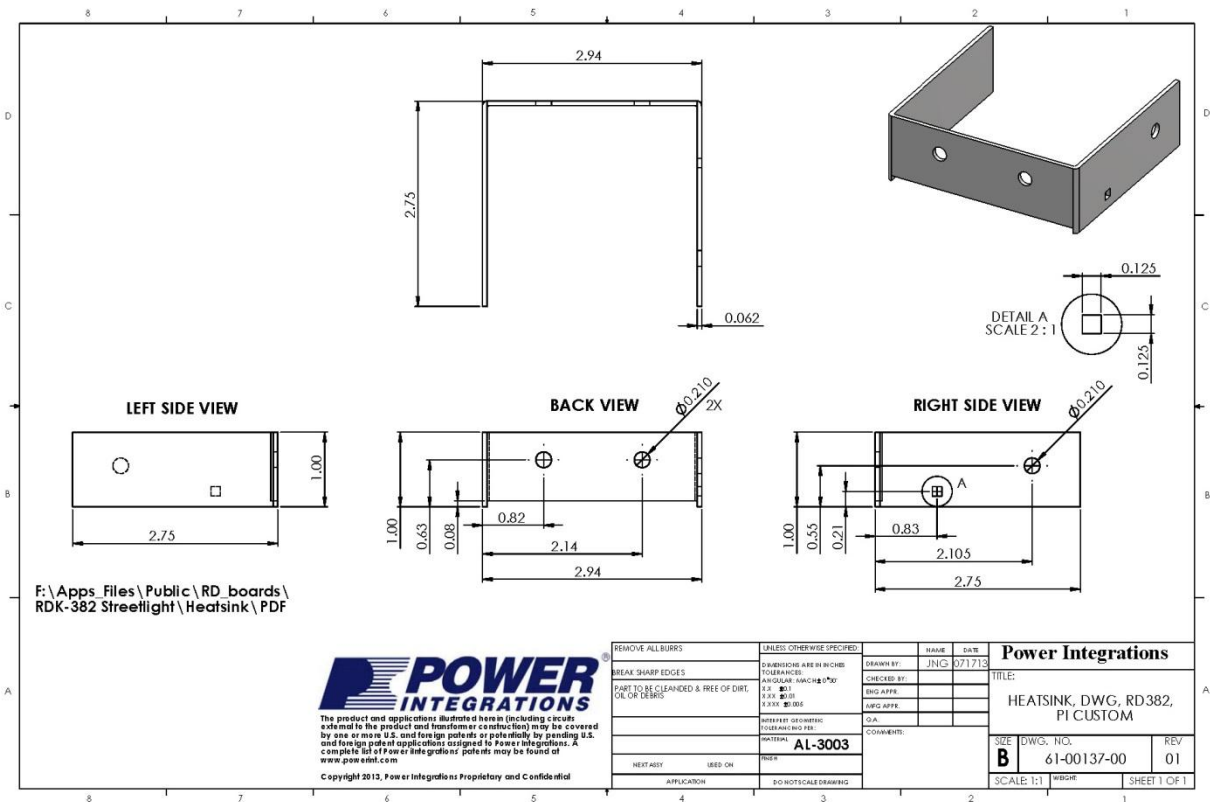


Figure 18 – RD-382 Primary Heat Sink Sheet Metal Drawing.



11.1.2 含扣件固定的主要散熱片

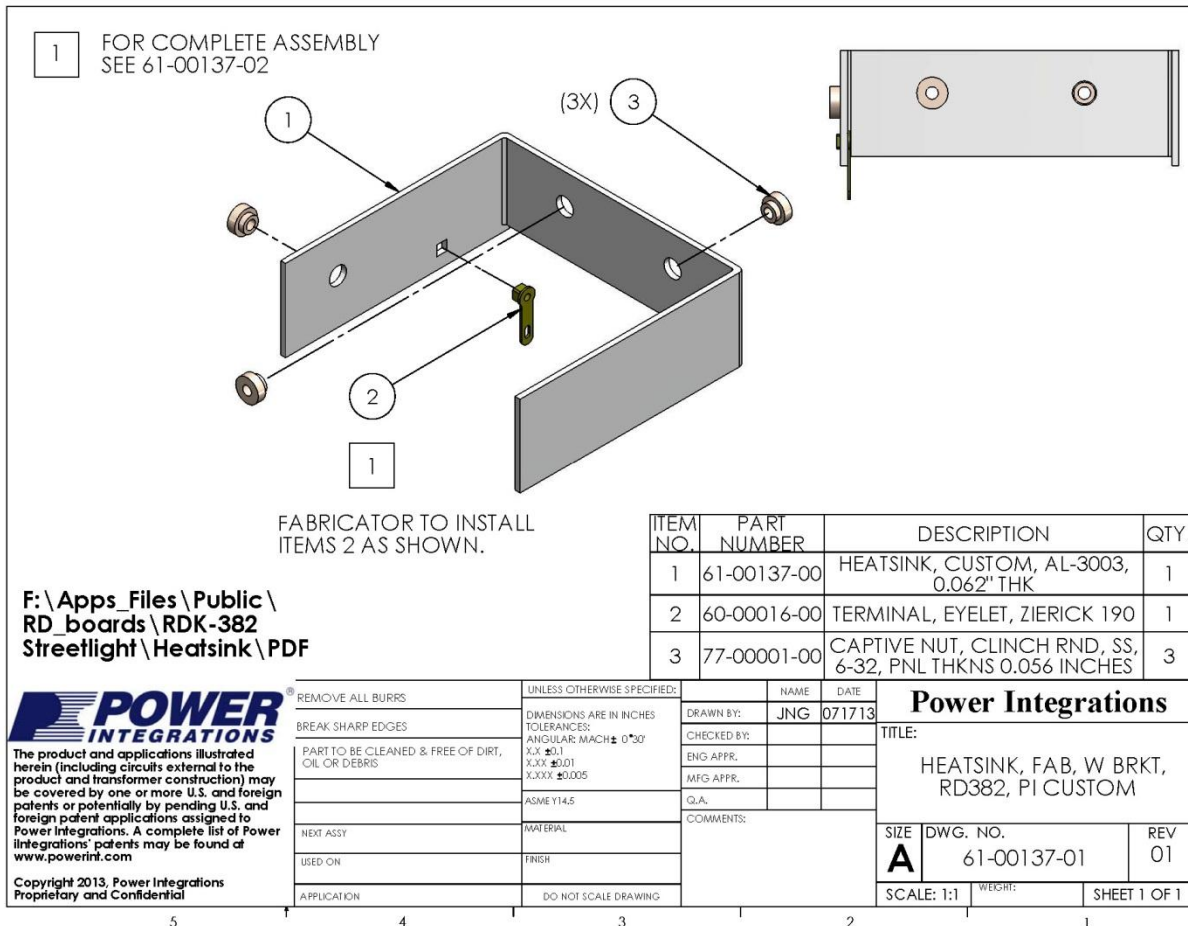


Figure 19 – Finished Primary Heat Sink Drawing with Installed Fasteners.



11.1.3 主要散熱片組裝

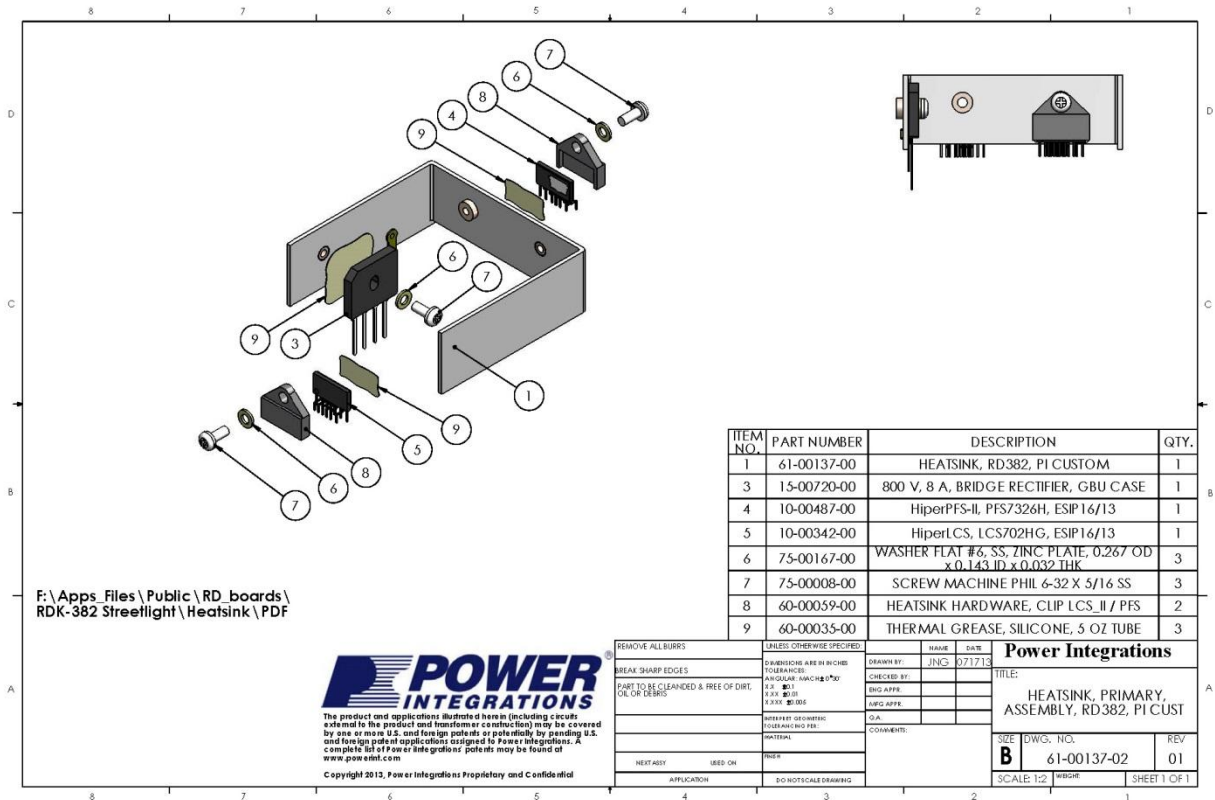


Figure 20 – RD-382 Primary Heat Sink Assembly.



11.2 次要散熱片

11.2.1 次要散熱片鋼板

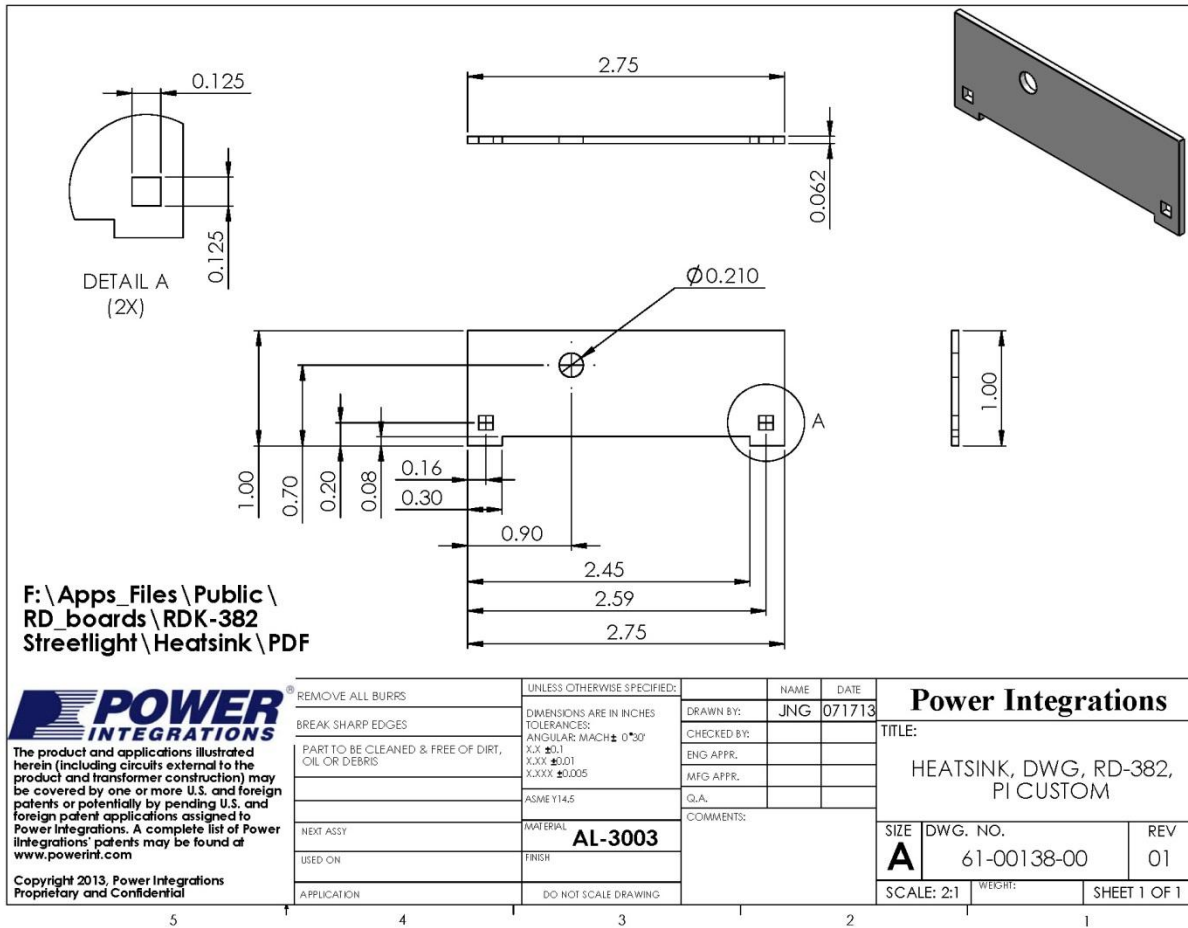


Figure 21 – Secondary Heat Sink Sheet Metal Drawing.



11.2.2 含扣件固定的次要散熱片

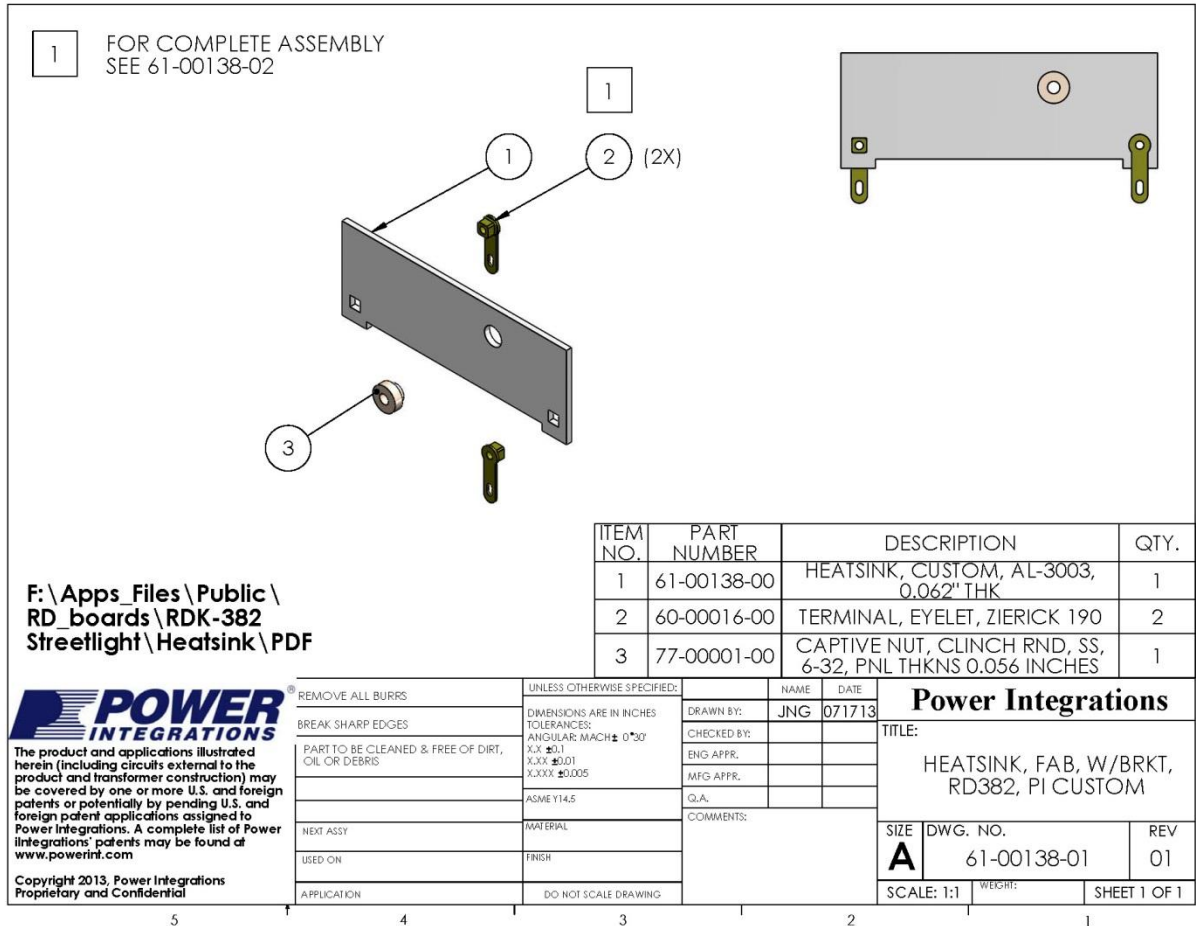


Figure 22 – Finished Secondary Heat Sink with Installed Fasteners.



11.2.3 次要散熱片組裝

ITEM NO.	PART NUMBER	DESCRIPTION	QTY.
1	61-00138-00	HEATSINK, RD382, PI CUTOM	1
3	15-00401-00	150 V, 20 A, SCHOTTKY, TO-220AB	1
4	60-00035-00	THERMAL GREASE-SILICONE, 5 OZ TUBE	1
5	75-00008-00	SCREW MACHINE PHIL 6-32 X 5/16 SS	1
6	75-00167-00	WASHER FLAT #6, SS, ZINC PLATE, 0.267 OD x 0.143 ID x 0.032 THK	1

F:\Apps_Files\Public\RD_boards\RDK-382\Streetlight\Heatsink\PDF

POWER INTEGRATIONS

REMOVE ALL BURRS
BREAK SHARP EDGES
PART TO BE CLEANED & FREE OF DIRT, OIL OR DEBRIS

UNLESS OTHERWISE SPECIFIED:
DIMENSIONS ARE IN INCHES
TOLERANCES:
ANGULAR: MACH ± 0°30'
X.X ±.01
X.XX ±.001
X.XXX ±0.005

ASME Y14.5MATERIAL
FINISH

DO NOT SCALE DRAWING

Power Integrations
TITLE:
HEATSINK, SECONDARY, ASSY,
RD382, PI CUSTOM

SIZE **A** DWG. NO. 61-00138-02 REV 01

SCALE: 1:2 SHEET 1 OF 1

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Proprietary and Confidential

Figure 23 – RD-382 Secondary Heat Sink Assembly.



12 RD-382 效能資料

All measurements were taken at room temperature and 60 Hz (input frequency) unless otherwise specified. Output voltage measurements were taken at the output connectors.

12.1 LLC Stage 效率

To make this measurement, the LLC stage was supplied by connecting an external 380 VDC source across bulk capacitor C14, with a 2-channel bench supply to source the primary and secondary bias voltages. The output of the supply was used to power the LED streetlight described in Section 7, and the dimming input of the supply was used to program the current delivered to this load in order to vary the output power.

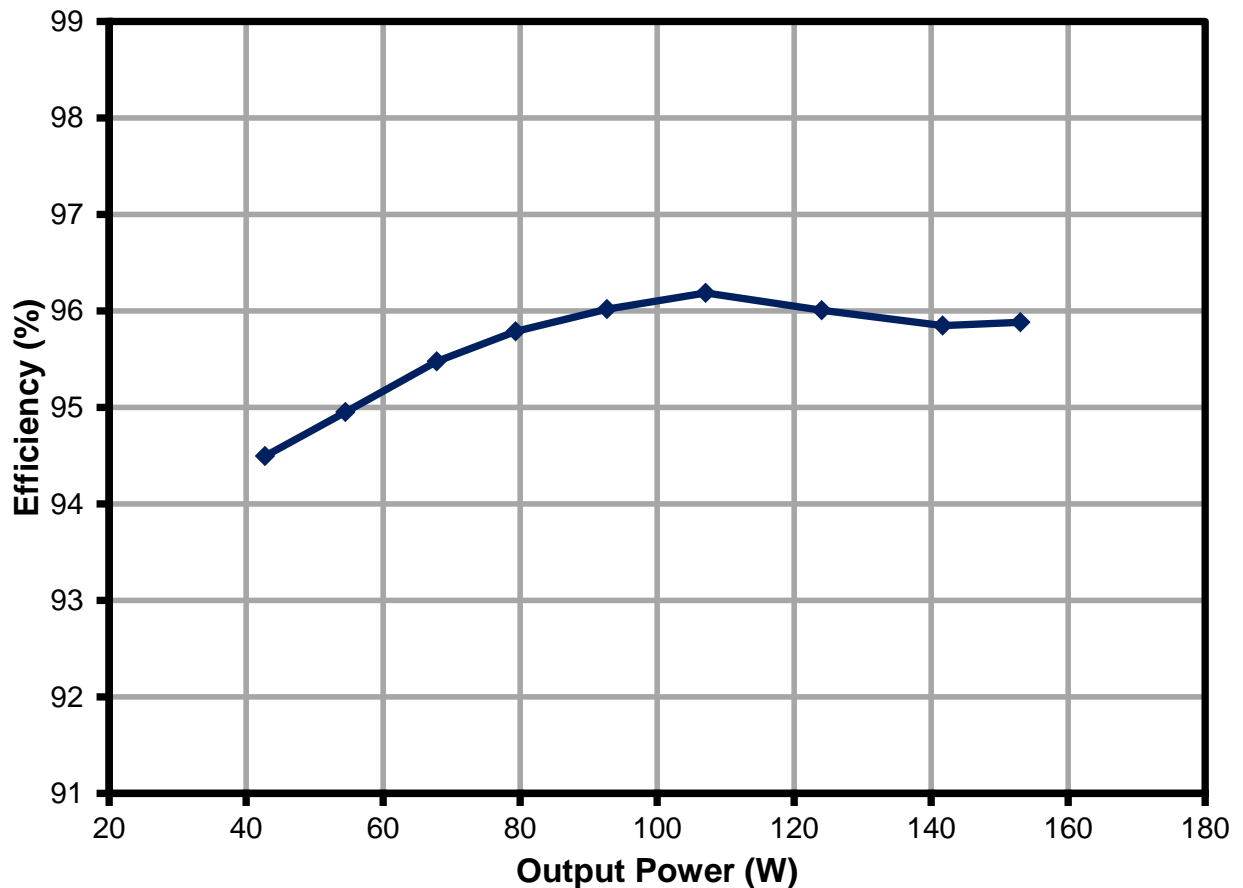


Figure 24 – LLC Stage Efficiency vs. Load, 380 VDC Input.



12.2 整體效率

Figures below show the total supply efficiency (PFC and LLC stages). AC input was supplied using a sine wave source. The output was loaded with an electronic load set for constant resistance, with the load adjusted for maximum output current (3.5 A) and 43 V output voltage.

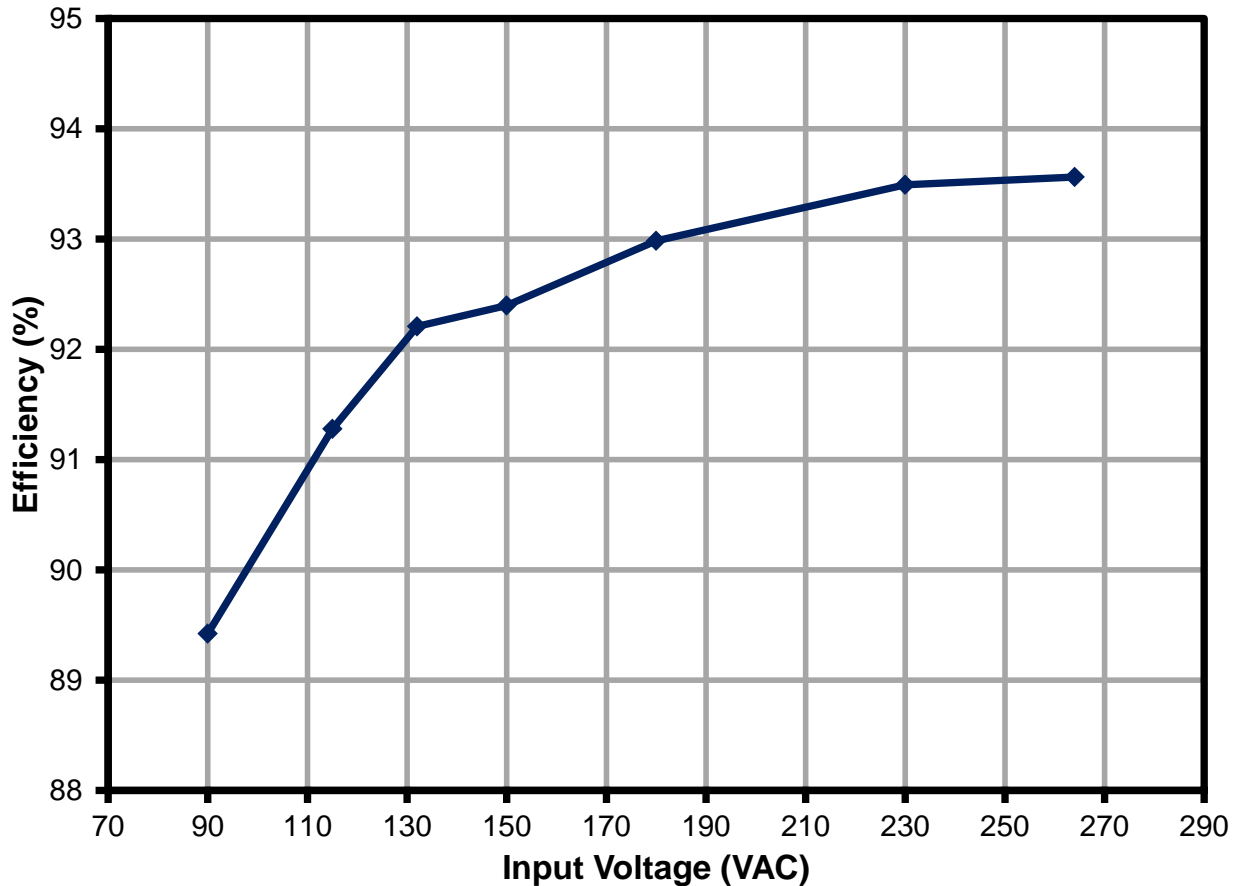


Figure 25 – Total Efficiency vs. Input Voltage, 100% Load.



12.3 功率因數 (PF)

Power factor measurements were made using a sine wave AC source and a constant resistance electronic load as described in section 12.2.

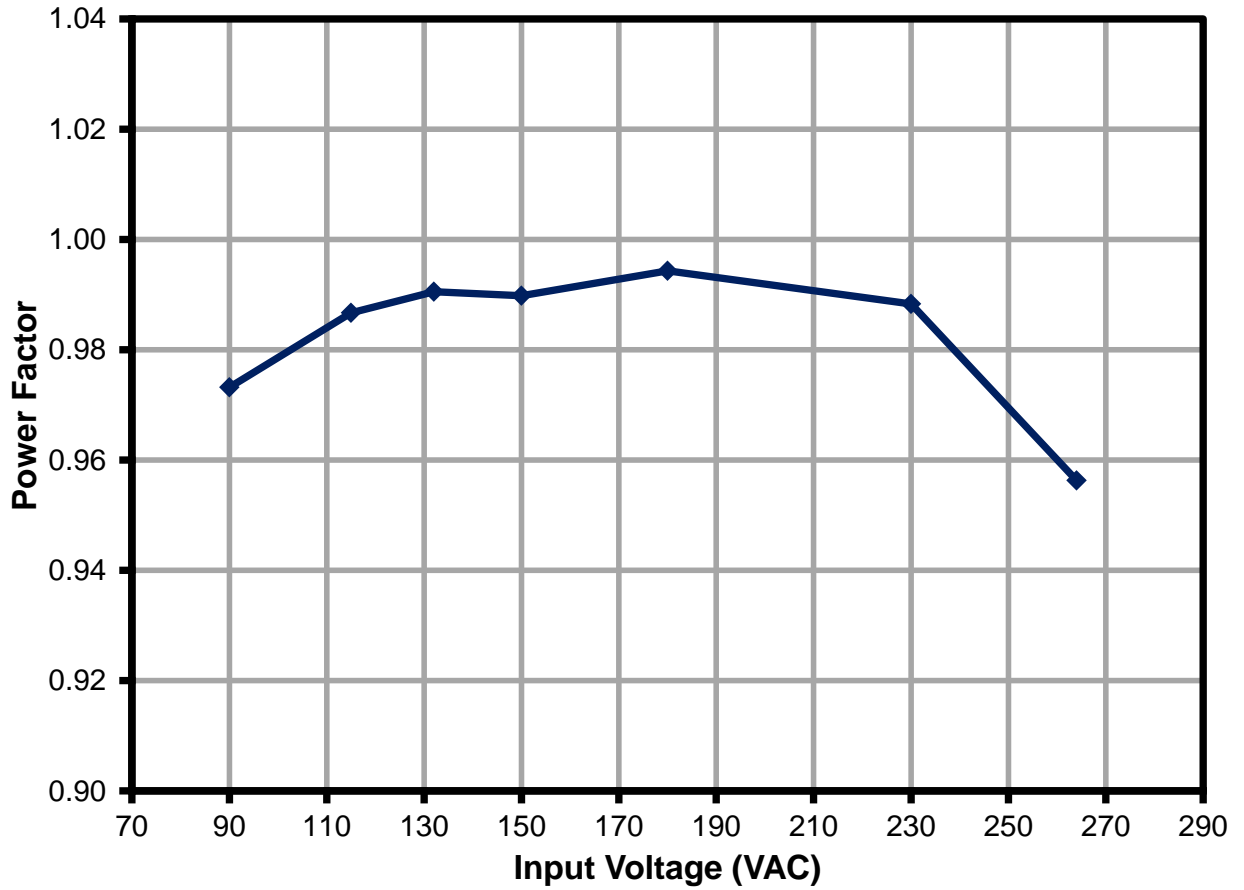


Figure 26 – Power Factor vs. Input Voltage, 100% Load.



12.4 諧波分佈

Input current harmonic distribution was measured using a sine wave source and an LED load (Section 7).

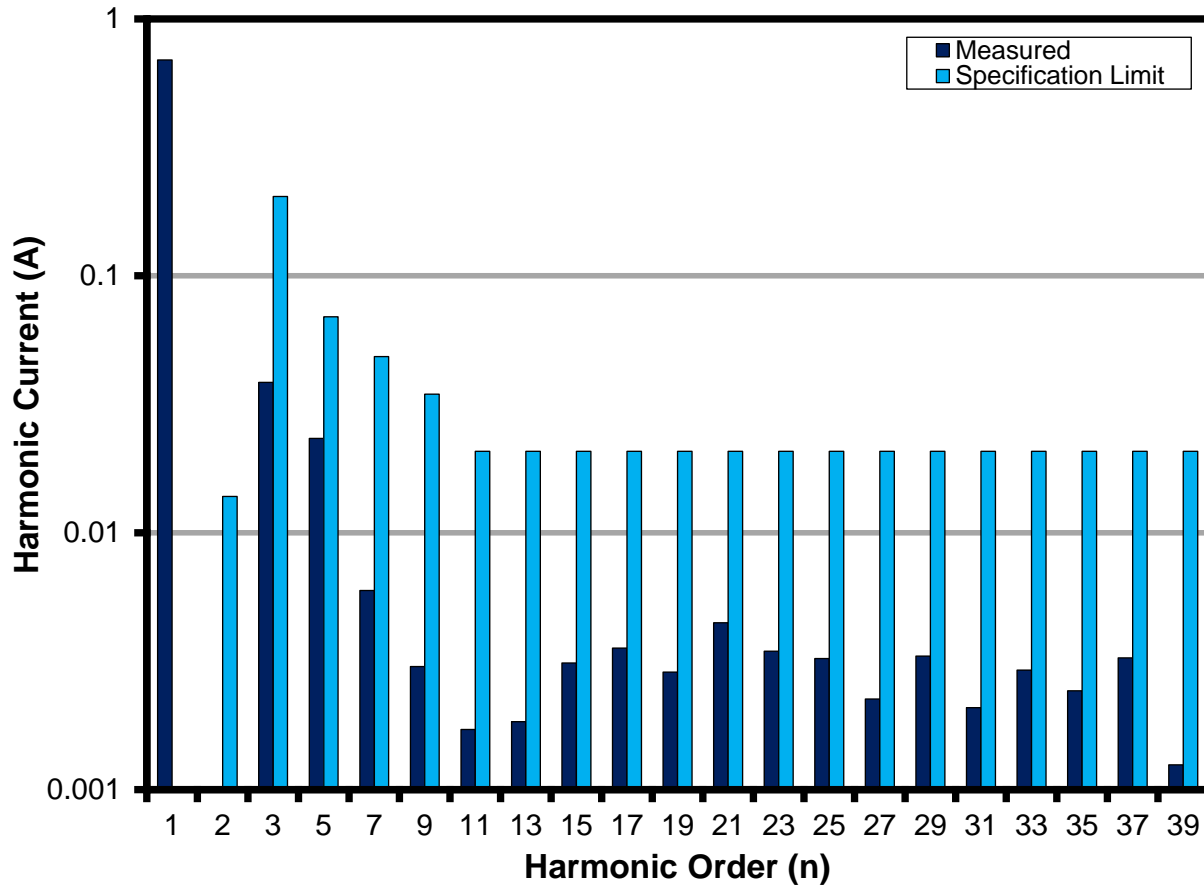


Figure 27 – Input Current Harmonic Distribution, 230 VAC / 50 Hz Input, 100% Load.

12.5 THD , 100% 負載

THD was measured using the LED streetlight load described in Section 7 of this report.

Input Voltage (VAC)	Frequency (Hz)	THD (%)
115	60	8.30
230	50	7.38

12.6 輸出電流與調光輸入電壓

Output dimming characteristics were measured using a sine wave AC source and the streetlight LED array described in Section 7. Dimming voltage was provided using a bench supply.

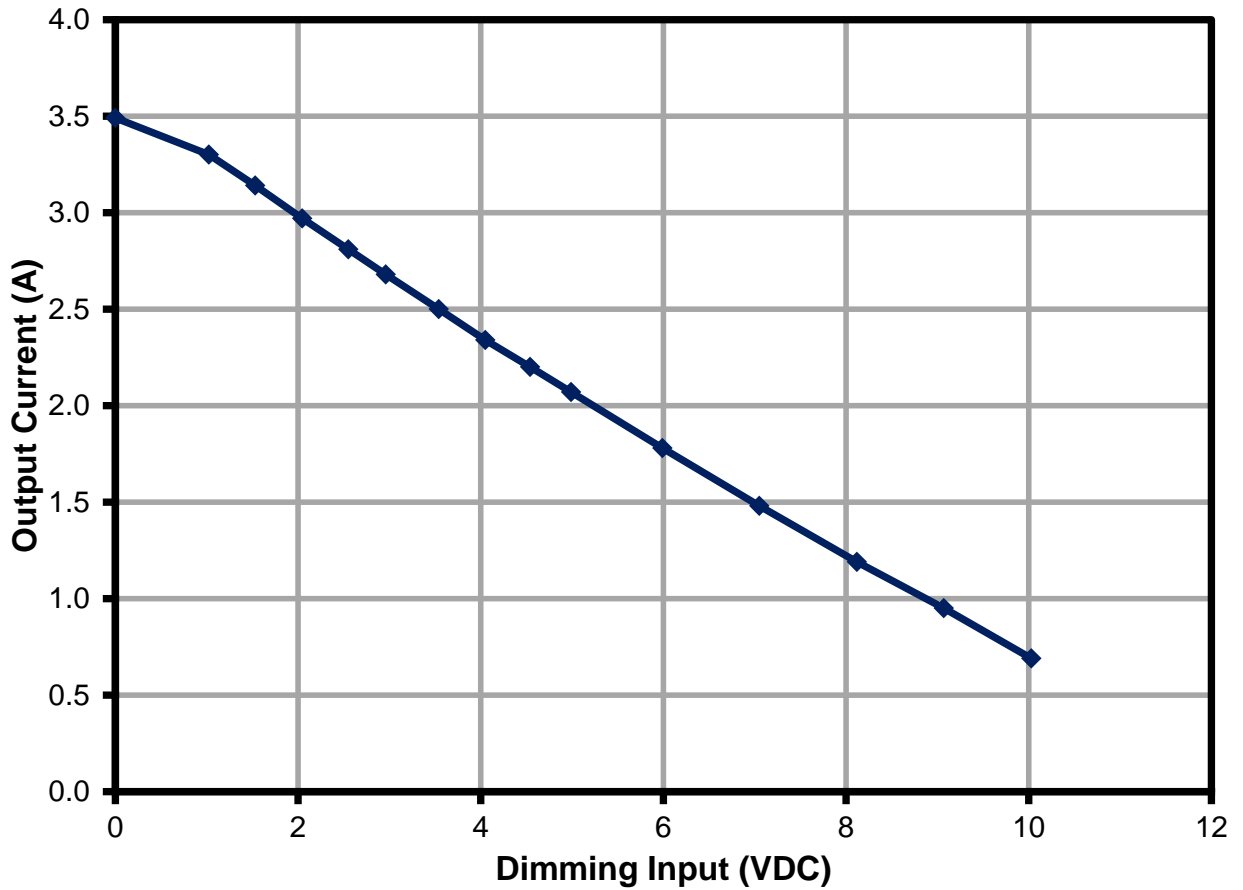


Figure 28 – RD-382 Output Current vs. Dimming Voltage.



13 波形

13.1 輸入電流，100% 負載

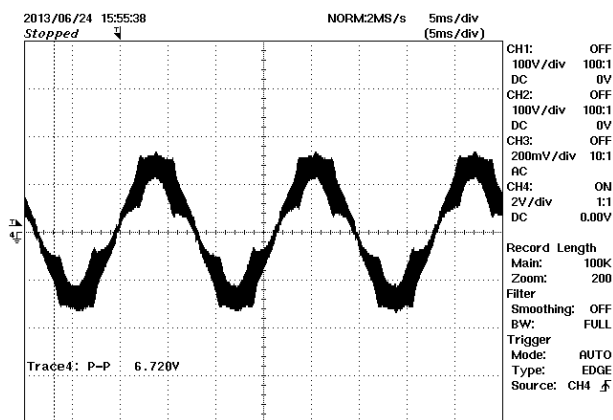


Figure 29 – Input Current, 90 VAC, 150 W Load, 2 A, 5 ms / div

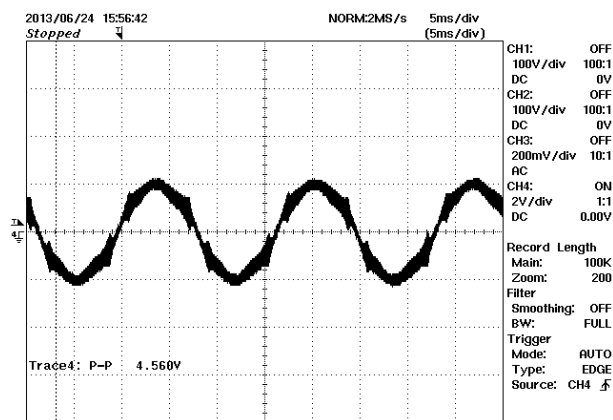


Figure 30 – Input Current, 115 VAC, 150 W Load, 2 A, 5 ms / div.

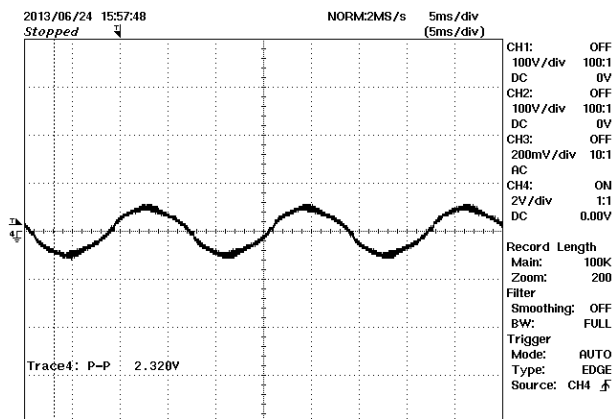


Figure 31 – Input Current, 230 VAC, 150 W Load, 2 A, 5 ms / div.

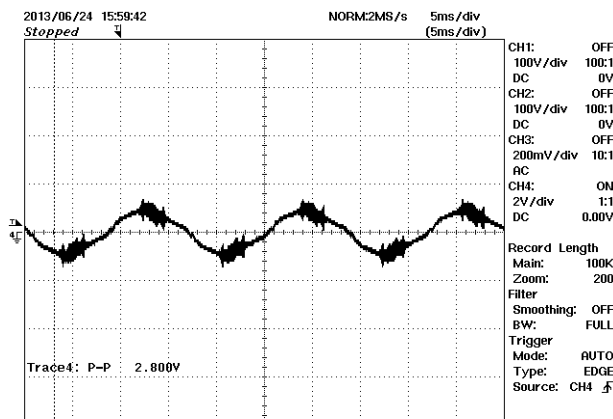


Figure 32 – Input Current, 265 VAC, 150 W Load, 2 A, 5 ms / div.

13.2 LLC 一次側電壓和電流

The LLC stage current was measured by inserting a current sensing loop in series with the ground side of resonating capacitor C30 that measures the LLC transformer (T2) primary current. The output was loaded with an electronic load set for constant resistance, with the load adjusted for maximum output current and 43 V output voltage.

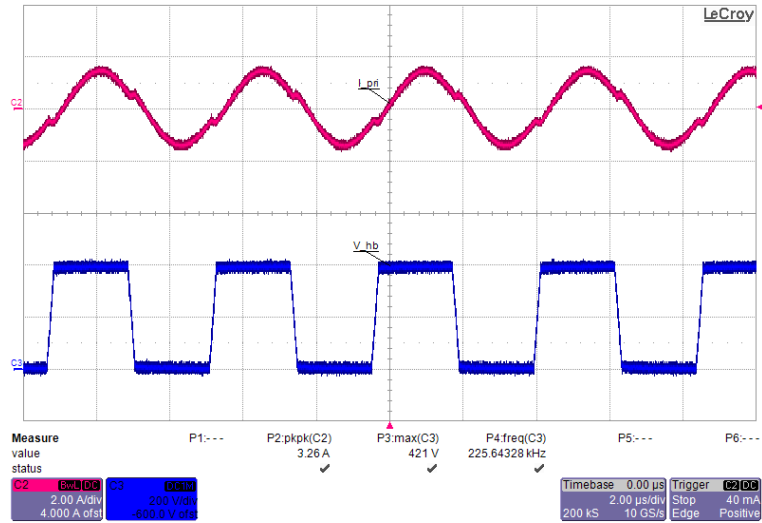


Figure 33 – LLC Stage Primary Voltage and Current, 100% Load.
 Upper: Current, 2 A / div.
 Lower: Voltage, 200 V, 2 μ s / div.



13.3 輸出整流器反向峰值電壓

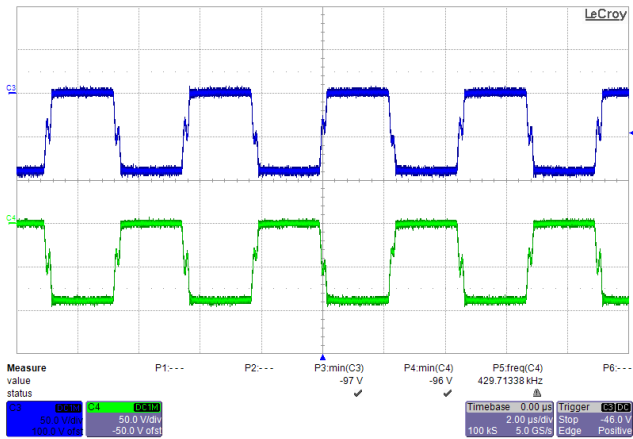


Figure 34 – Output Rectifier (D11) Reverse Voltage, 100% Load. Top and Bottom Traces Show Voltages on Each Half of D11, at 50 V, 2 μs / div.

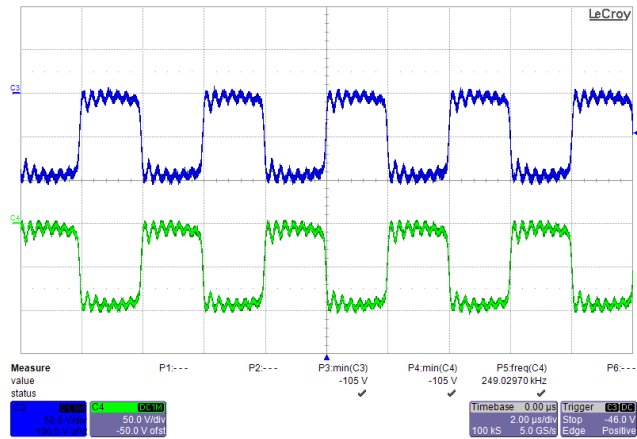


Figure 35 – Output Rectifier (D11) Reverse Voltage, No-Load. Top and Bottom Traces Show Voltages on Each Half of D11, at 50 V, 2 μs / div.



13.4 PFC 電感器+ 切换電壓和電流，100% 負載

Since the PFC in this power supply utilizes the internal output diode of the HiperPFS-2, the measured drain current cannot be separated from the PFC inductor current.

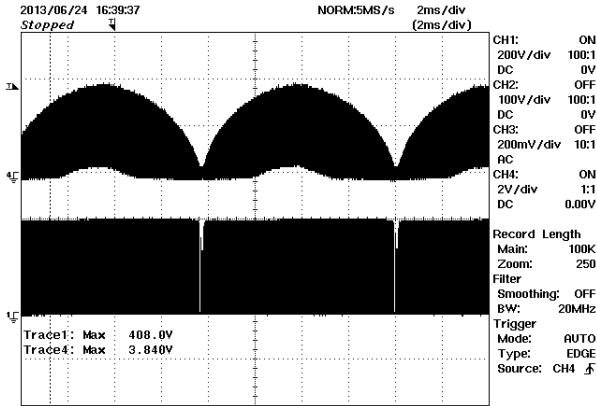


Figure 36 – PFC Stage Drain Voltage and Current, Full Load, 115 VAC.
Upper: Switch + Inductor Current, 2 A / div.
Lower: V_{DRAIN} , 200 V, 2 ms / div.

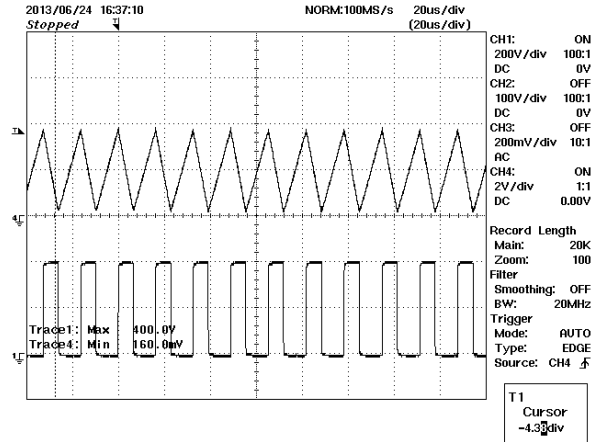


Figure 37 – PFC Stage Drain Voltage and Current, Full Load, 115 VAC.
Upper: Switch + Inductor Current, 2 A / div.
Lower: V_{DRAIN} , 200 V, 20 μ s / div.

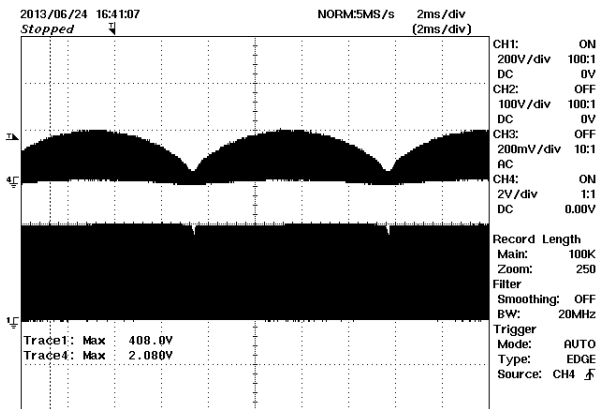


Figure 38 – PFC Stage Drain Voltage and Current, Full Load, 230 VAC.
Upper: Switch + Inductor Current, 2 A / div.
Lower: V_{DRAIN} , 200 V, 2 ms / div.

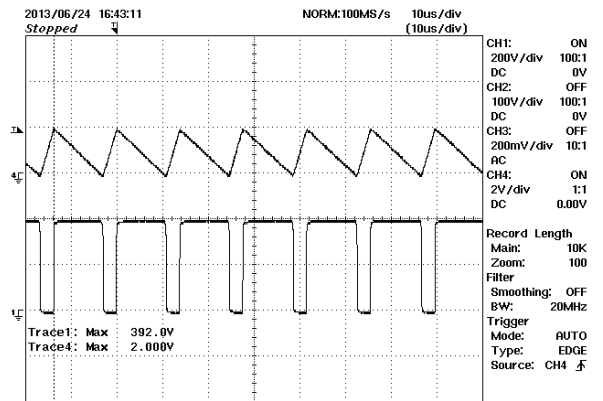


Figure 39 – PFC Stage Drain Voltage and Current, Full Load, 230 VAC.
Upper: Switch + Inductor Current, 2 A / div.
Lower: V_{DRAIN} , 200 V, 10 μ s / div.



13.5 啟動時的 AC 輸入電流和 PFC 輸出電壓

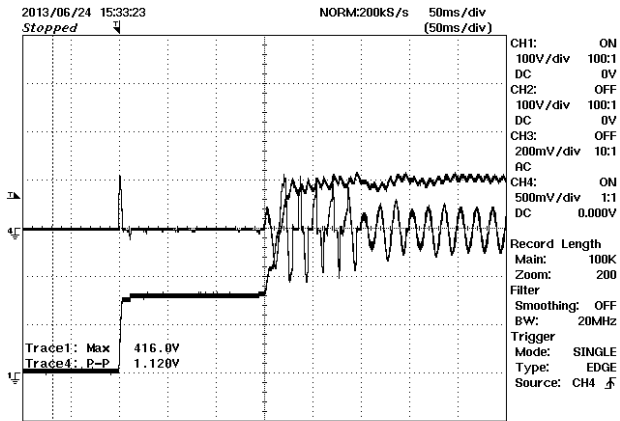


Figure 40 – AC Input Current vs. PFC Output Voltage at Start-up, Full Load, 115 VAC.
Upper: AC Input Current, 25 A / div.
Lower: PFC Voltage, 100 V, 50 ms / div.

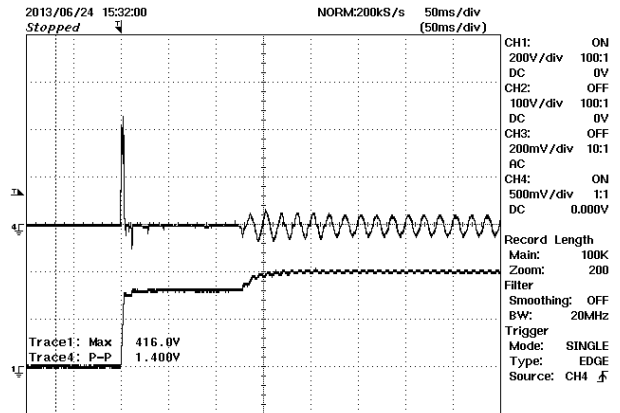


Figure 41 – AC Input Current vs. PFC Output Voltage at Start-up, Full Load, 230 VAC.
Upper: AC Input Current, 5 A / div.
Lower: PFC Voltage, 200 V, 50 ms / div.

13.6 使用 LED 輸出負載的 LLC 啟動輸出電壓和變壓器一次側電流

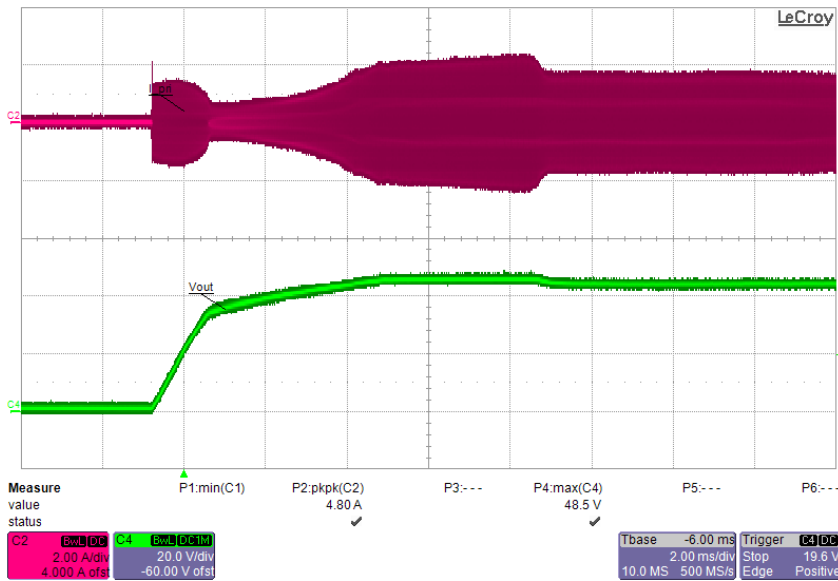


Figure 42 – LLC Start-up. 115 VAC, 100% Load.
Upper: LLC Primary Current, 2 A / div.
Lower: LLC V_{OUT} , 20 V, 2 ms / div.



13.7 使用 LED 負載的輸出電壓/電流啓動

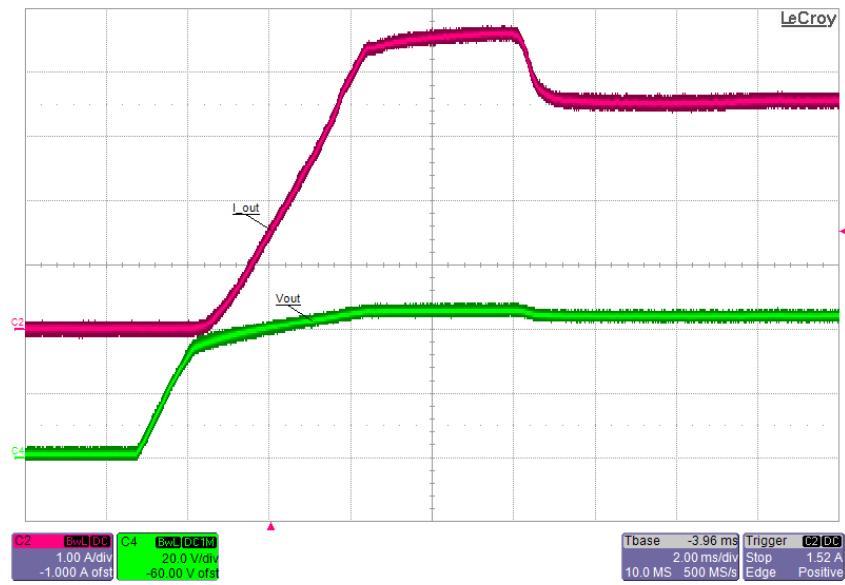


Figure 43 – LLC Start-up. 115 VAC, 100% Load, LED Load.
 Upper: LLC I_{OUT} , 1 A / div.
 Lower: LLC V_{OUT} , 20 V, 2 ms / div.



13.8 LLC 輸出短路

The figure below shows the effect of an output short circuit on the LLC primary current and on the output current. A mercury displacement relay was used to short the output to get a fast, bounce-free connection.

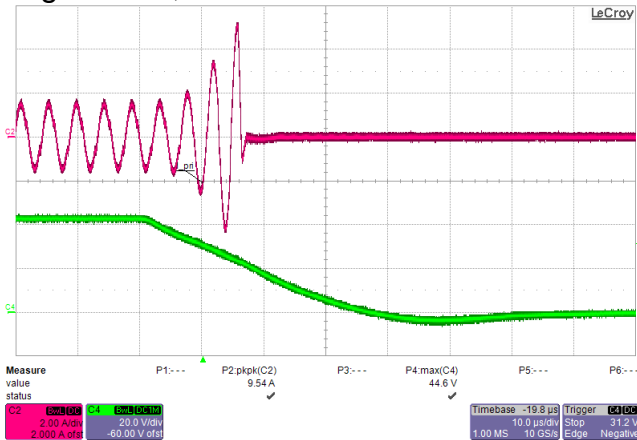


Figure 44 – Output Short-Circuit Test.
 Upper: LLC Primary Current, 2 A / div.
 Lower: LLC V_{OUT} , 20 V, 10 μ s / div.

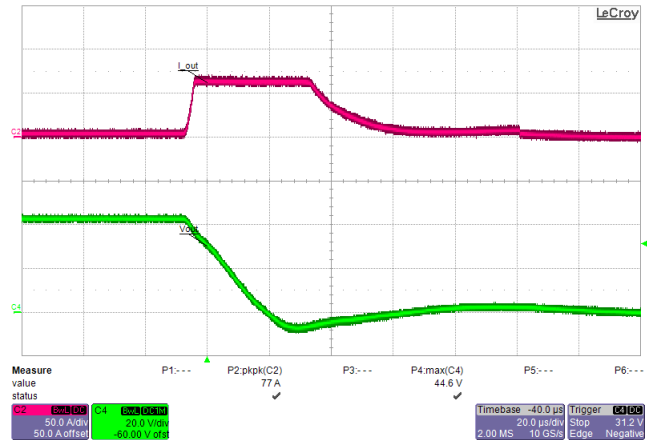


Figure 45 – Output Short-Circuit Test.
 Upper: LLC I_{OUT} , 50 A / div.
 Lower: LLC V_{OUT} , 20 V, 10 μ s / div.



13.9 輸出漣波的測量

13.9.1 漣波測量技術

For DC output ripple measurements a modified oscilloscope test probe is used to reduce spurious signals. Details of the probe modification are provided in the figures below.

Tie two capacitors in parallel across the probe tip of the 4987BA probe adapter. Use a $0.1 \mu\text{F} / 50 \text{ V}$ ceramic capacitor and $1.0 \mu\text{F} / 100 \text{ V}$ aluminum electrolytic capacitor. The aluminum-electrolytic capacitor is polarized, so always maintain proper polarity across DC outputs.

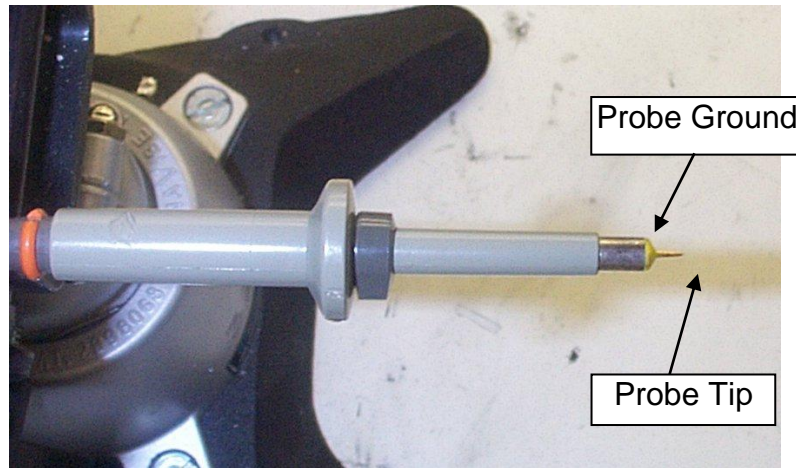


Figure 46 – Oscilloscope Probe Prepared for Ripple Measurement (End Cap and Ground Lead Removed).



Figure 47 – Oscilloscope Probe with Probe Master 4987BA BNC Adapter (Modified with Wires for Probe Ground for Ripple measurement and Two Parallel Decoupling Capacitors Added).

13.9.2 漣波的測量

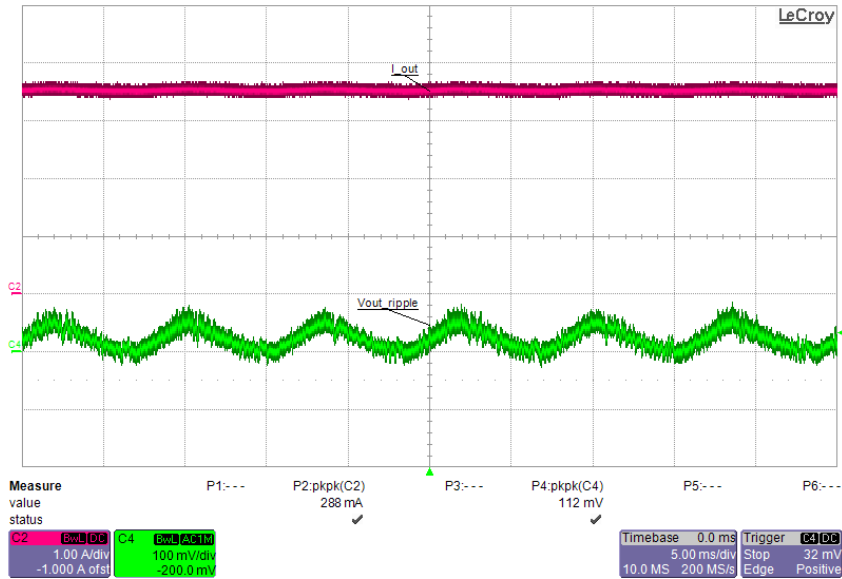


Figure 48 – Output Ripple, Full Load, 115 VAC.
Upper: I_{OUT} , 1 A / div.
Lower: Output Voltage Ripple, 100 mV, 5 ms / div.



14 温度配置

The board was operated at room temperature, with output set at maximum using a constant resistance load. For each test condition the unit was allowed to thermally stabilize (~1 hr) before measurements were made.

14.1 90 VAC、60 Hz、150 W 輸出、室温

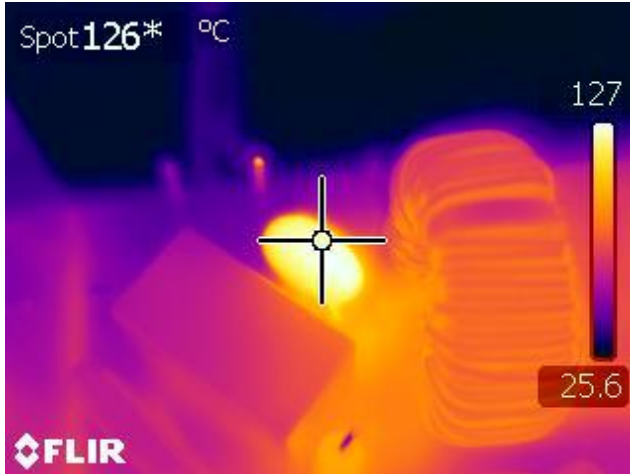


Figure 49 – Inrush Limiting Thermistor (RT1), 90 VAC Input, 100% Load, Room Temperature.

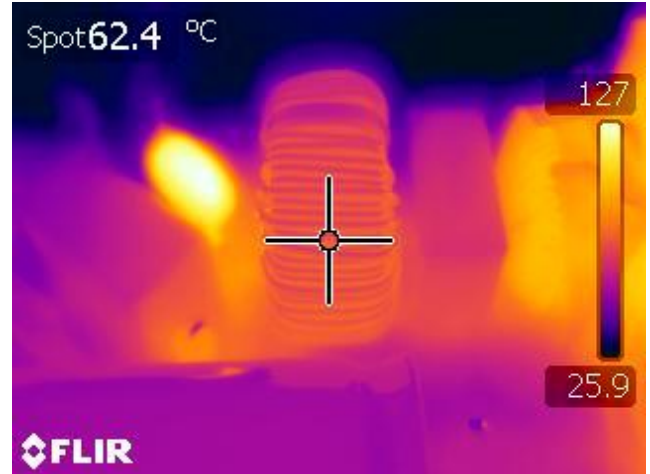


Figure 50 – Common Mode Choke (L1), 90 VAC Input, 100% Load, Room Temperature.

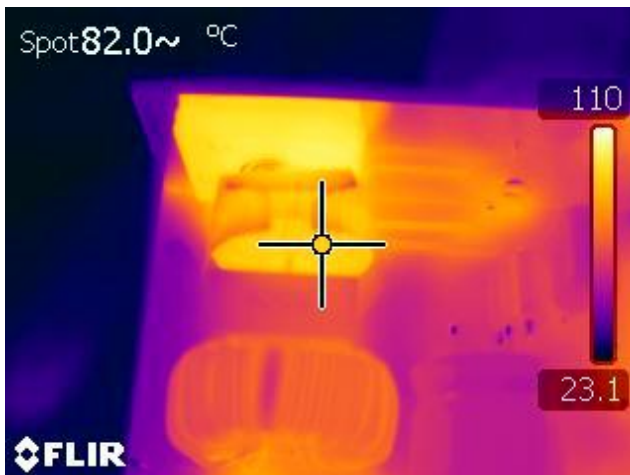


Figure 51 – Differential Mode Choke (L4), 90 VAC Input, 100% Load, Room Temperature.

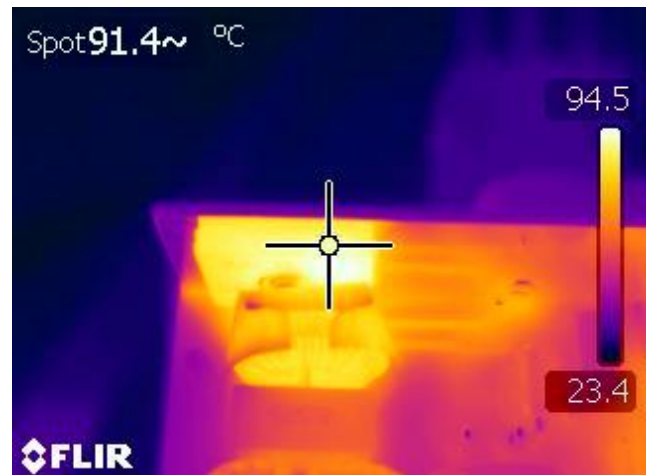


Figure 52 – Input Rectifier Bridge (BR1), 90 VAC Input, 100% Load, Room Temperature.



Figure 53 – PFC IC (U1), 90 VAC Input, 100% Load, Room Temperature.

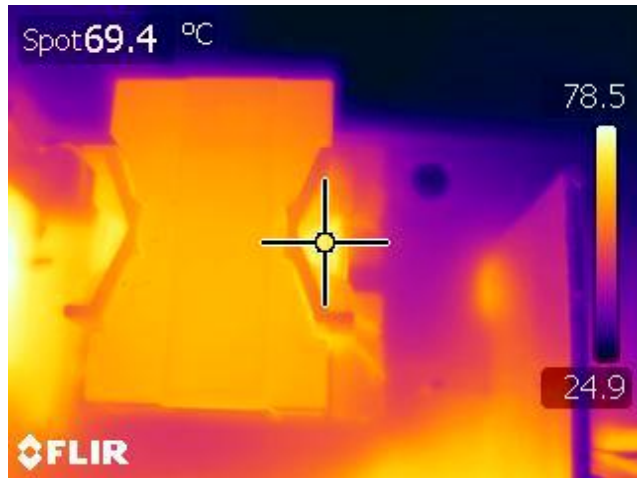


Figure 54 – PFC Inductor (L2), 90 VAC Input, 100% Load, Room Temperature.

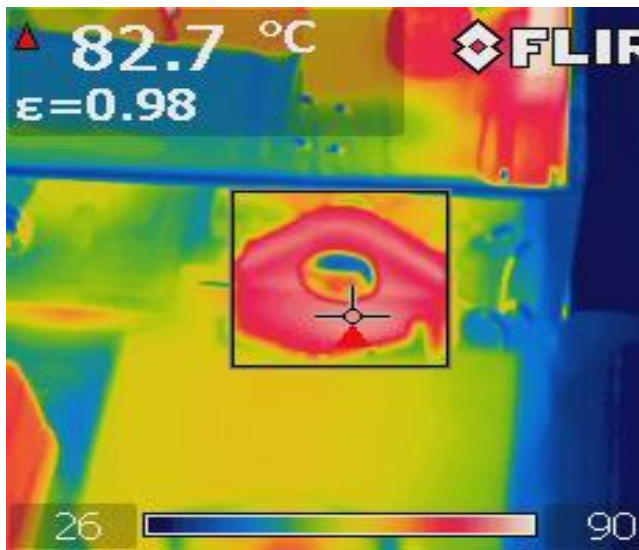


Figure 55 – LLC IC (U3), 90 VAC Input, 100% Load, Room Temperature.

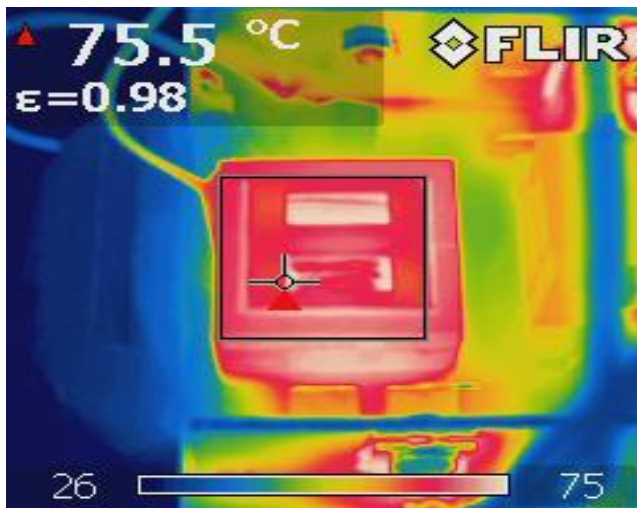


Figure 56 – LLC Transformer (T2), 90 VAC Input, 100% Load, Room Temperature.



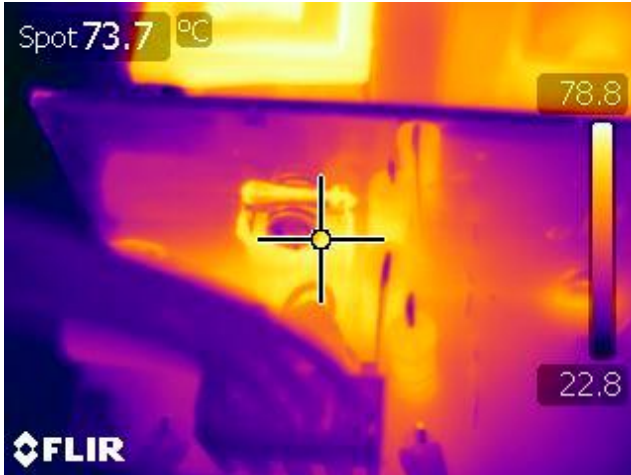


Figure 57 – Output Rectifier (D11), 90 VAC Input, 100% Load, Room Temperature.



Figure 58 – Current Sense Resistor (R53), 90 VAC Input, 100% Load, Room Temperature.



14.2 115 VAC、60 Hz、150 W 輸出、室温

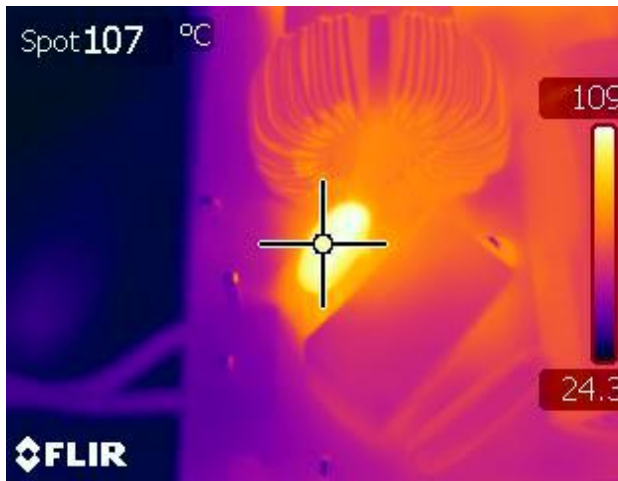


Figure 59 – Inrush Limiting Thermistor (RT1), 115 VAC Input, 100% Load, Room Temperature.



Figure 60 – Common Mode Choke (L1), 115 VAC Input, 100% Load, Room Temperature.

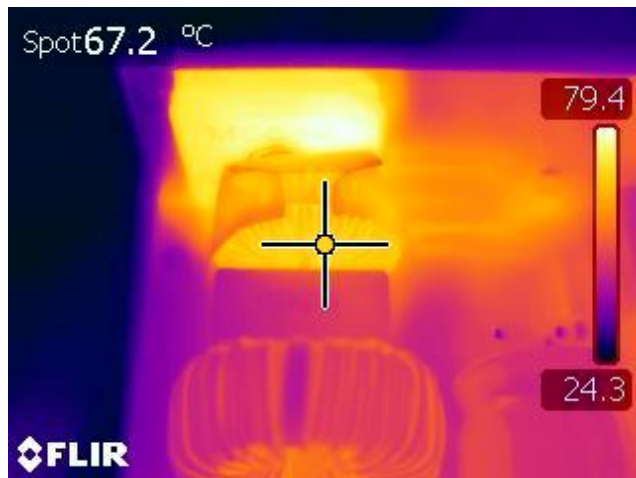


Figure 61 – Differential Mode Choke (L4), 115 VAC Input, 100% Load, Room Temperature.



Figure 62 – Input Rectifier Bridge (BR1), 115 VAC Input, 100% Load, Room Temperature.

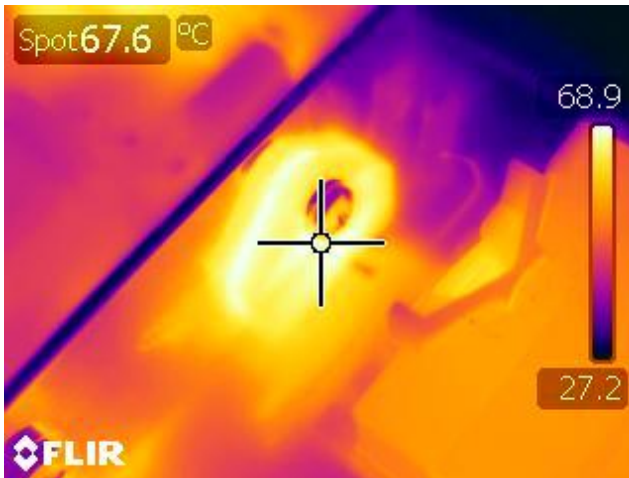


Figure 63 – PFC IC (U1), 115 VAC Input, 100% Load, Room Temperature.

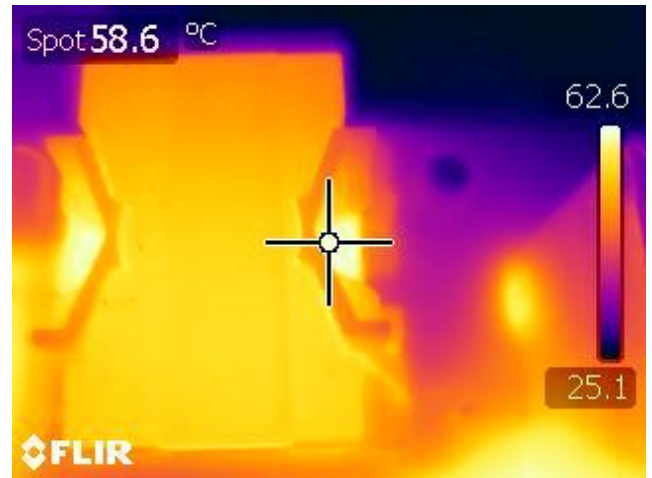


Figure 64 – PFC Inductor (L2), 115 VAC Input, 100% Load, Room Temperature

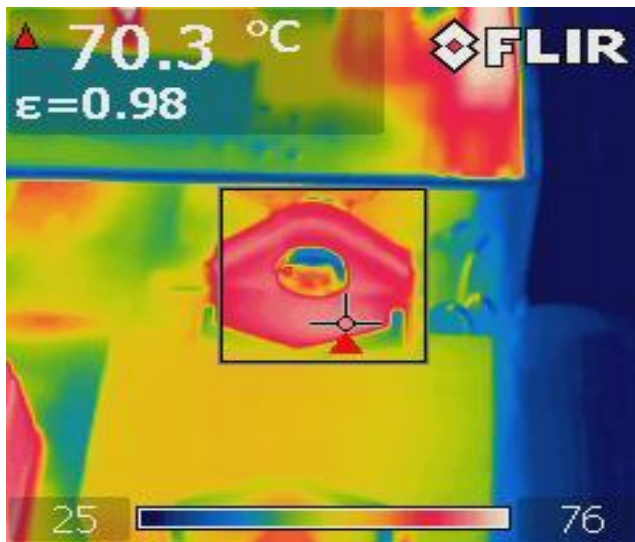


Figure 65 – LLC IC (U3), 115 VAC Input, 100% Load, Room Temperature.

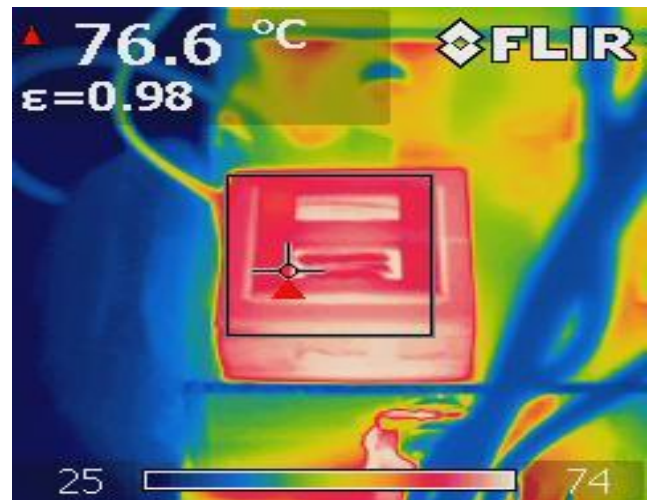


Figure 66 – LLC Transformer (T1), 115 VAC Input, 100% Load, Room Temperature.





Figure 67 – Output Rectifier (D11), 115 VAC Input, 100% Load, Room Temperature.



Figure 68 – Current Sense Resistor (R53), 115 VAC Input, 100% Load, Room Temperature.



14.3 230 VAC、50 Hz、150 W 輸出、室温

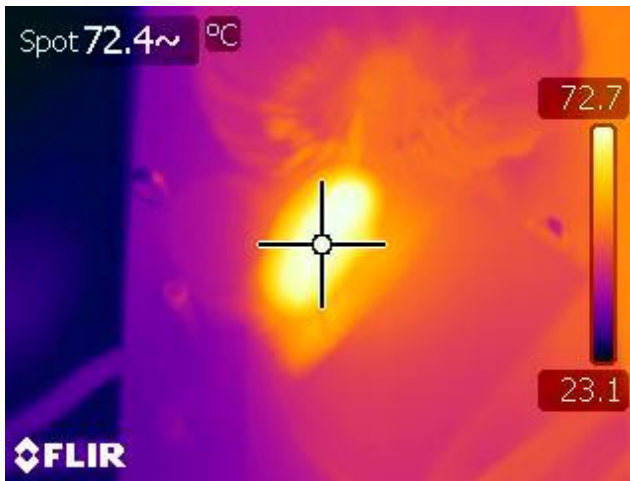


Figure 69 – Inrush Limiting Thermistor (RT1), 230 VAC Input, 100% Load, Room Temperature.



Figure 70 – Common Mode Choke (L1), 230 VAC Input, 100% Load, Room Temperature.



Figure 71 – Differential Mode Choke (L4), 230 VAC Input, 100% Load, Room Temperature.

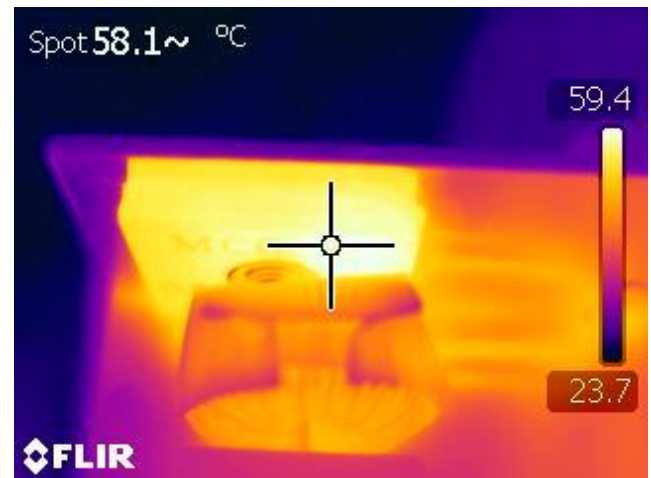


Figure 72 – Input Rectifier Bridge (BR1), 230 VAC Input, 100% Load, Room Temperature.



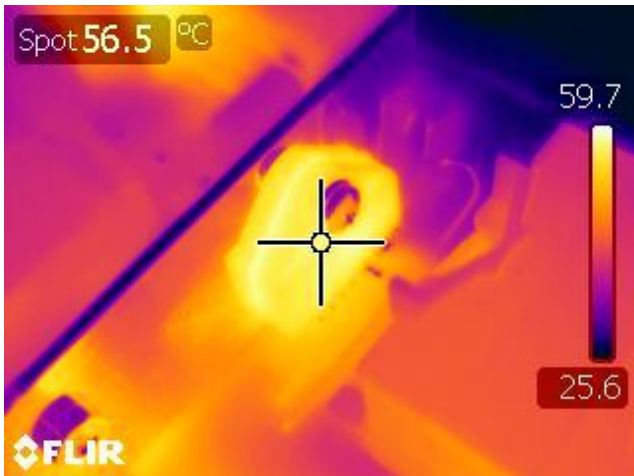


Figure 73 – PFC IC (U1), 230 VAC Input, 100% Load, Room Temperature.

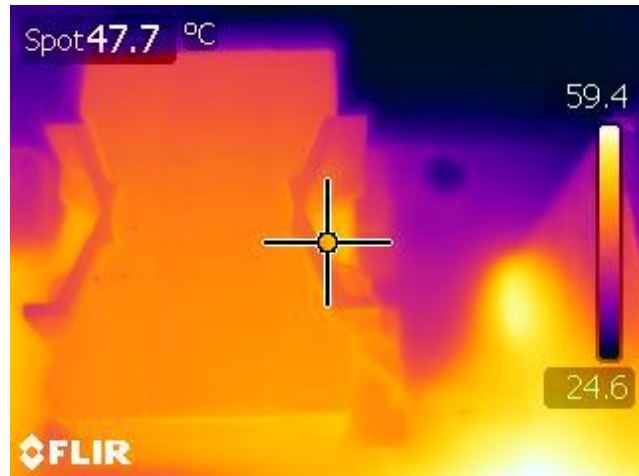


Figure 74 – PFC Inductor (L2), 230 VAC Input, 100% Load, Room Temperature

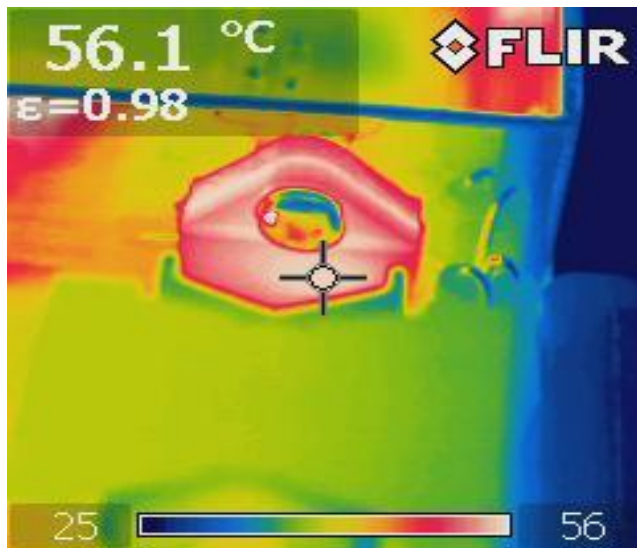


Figure 75 – LLC IC (U3), 230 VAC Input, 100% Load, Room Temperature.

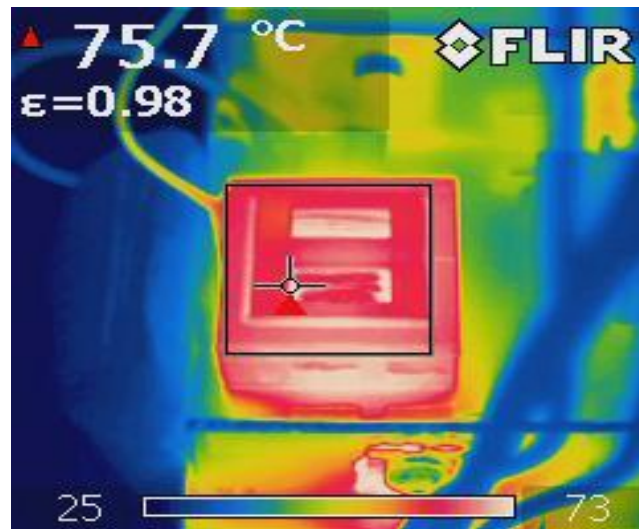


Figure 76 – LLC Transformer (T1), 230 VAC Input, 100% Load, Room Temperature.





Figure 77 – Output Rectifier (D11), 230 VAC Input, 100% Load, Room Temperature.



Figure 78 – Current Sense Resistor (R53), 230 VAC Input, 100% Load, Room Temperature.



15 輸出增益-相位

Gain-phase was tested a maximum load using the constant voltage load described in Section 7.1. It is important to use the actual LED load or a load with similar characteristics during gain-phase testing, as a load with different output characteristic will yield inaccurate results.

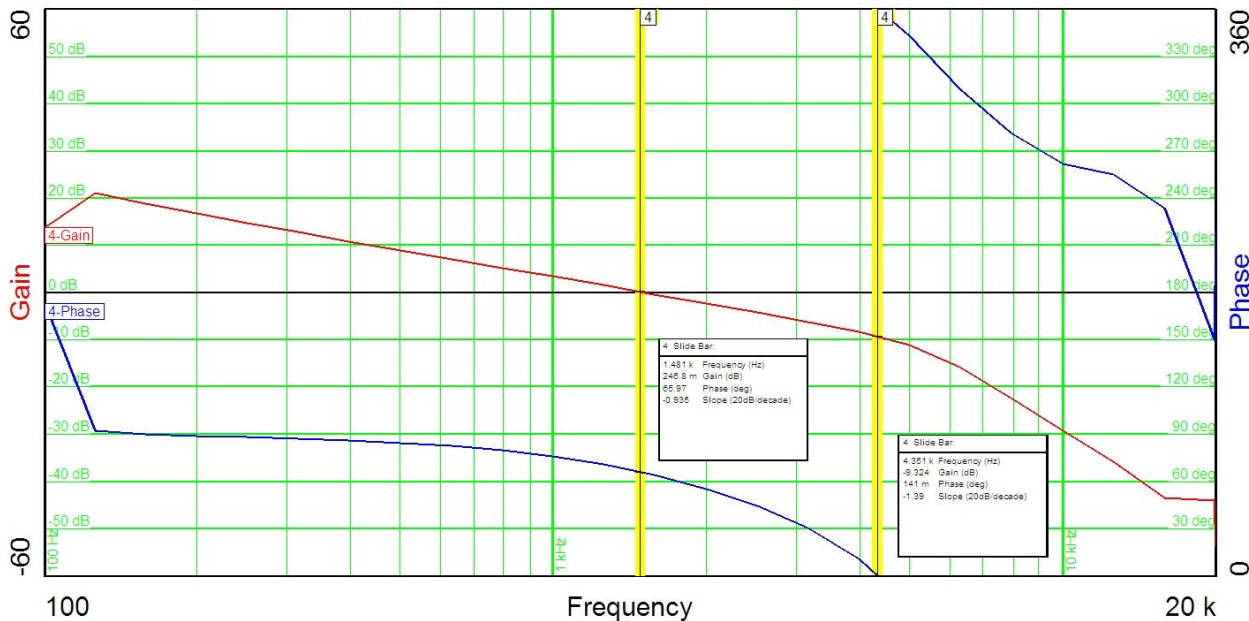


Figure 79 – LLC Converter Gain-Phase, 100% Load Crossover Frequency – 1.5 kHz, Phase Margin - 66°.



16 傳導性 EMI

Conducted EMI tests were performed using the constant voltage load described in Section 7.1. The output return was connected to the LISN artificial hand to simulate the capacitance of a typical set of LED panels to chassis ground. The step change in readings at 80 MHz is due to an automatic 10 dB scale change of the EMI receiver rather than an actual peak at 80 MHz.

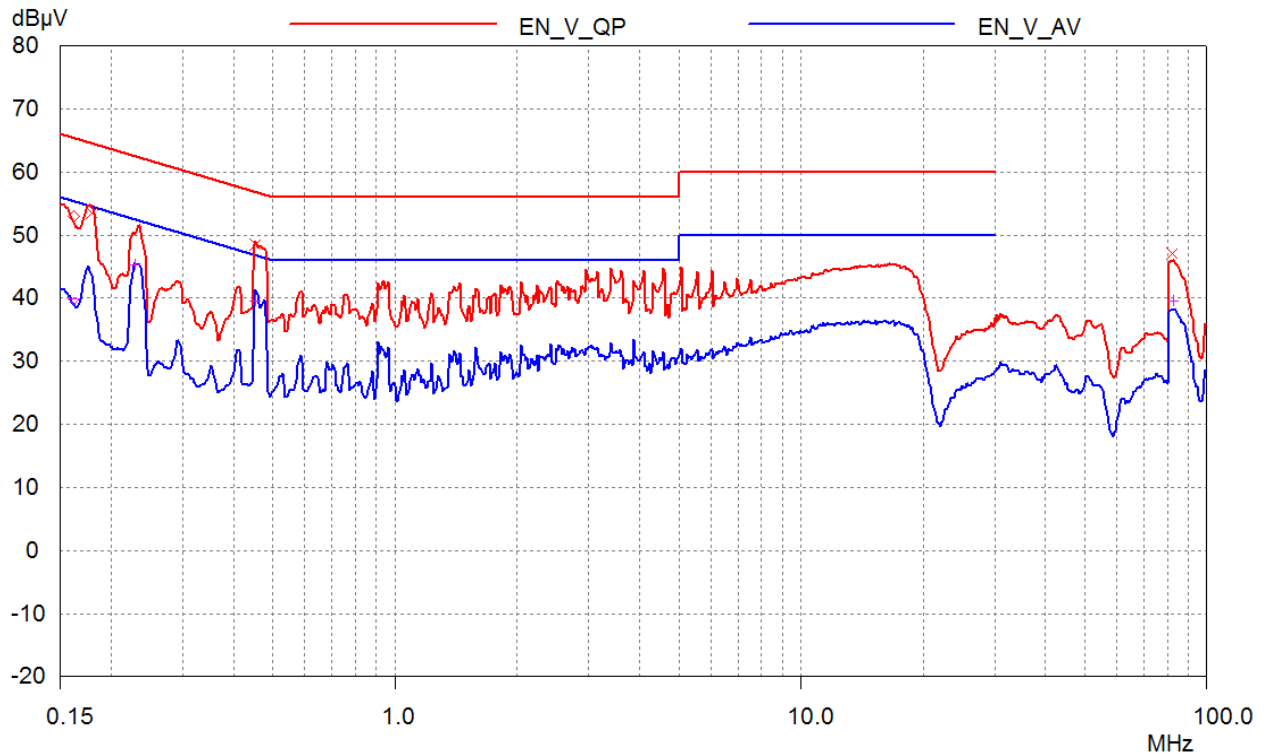


Figure 80 – Conducted EMI, 115 VAC, Full Load.



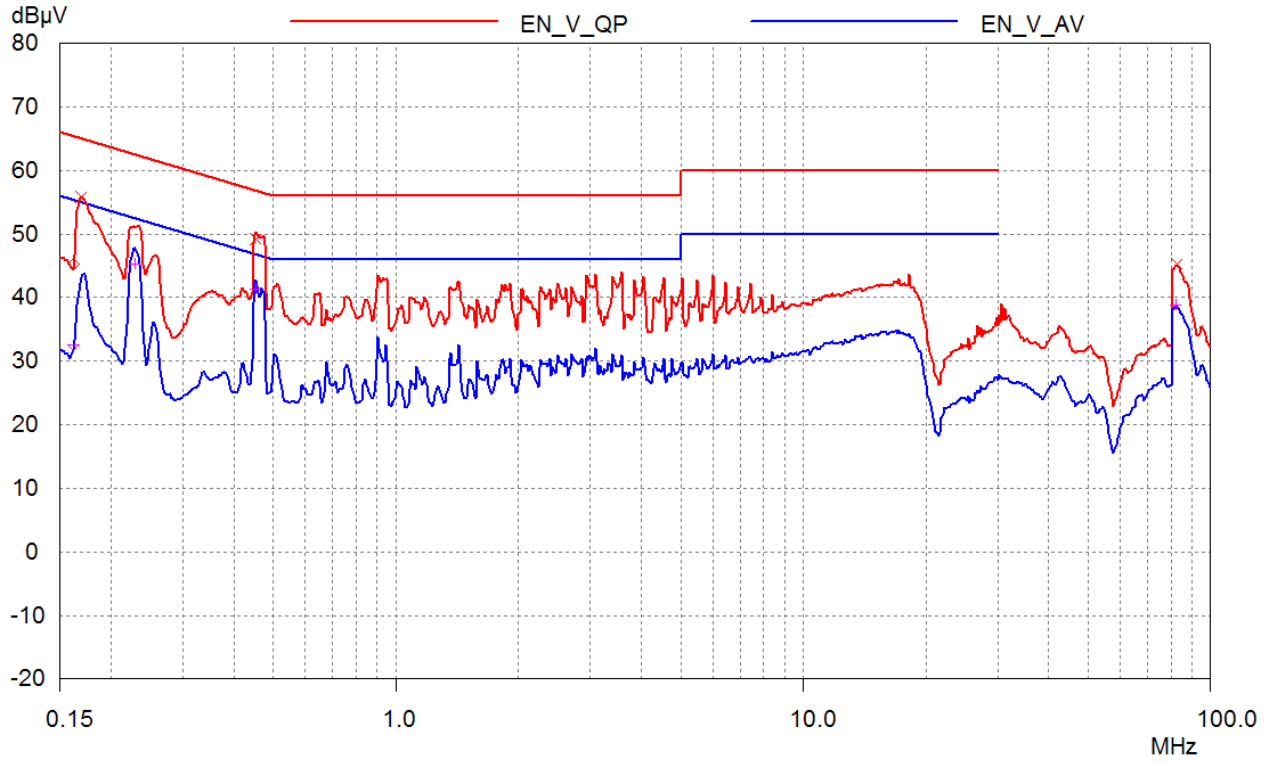


Figure 81 – Conducted EMI, 230 VAC, Full Load.



17 線電壓突波測試

17.1 線電壓突波測試裝置

The picture below shows the power supply set-up for surge testing. The supply is placed on a ground plane approximately the size of the power supply. A piece of single-sided copper clad printed circuit material was used in this case, but a piece of aluminum sheet with appropriate insulation would also work. An IEC AC connector was wired to the power supply AC input, with the safety ground connected to the ground plane. The CV output load (described in section 7) was placed on top of the ground plane so that it would capacitively couple to the safety ground. A 48 V fan was located inside the plastic shroud shown in the figure, and used to cool the CV load during testing. An indicator consisting of a GaP yellow-green led in series with a 39 V Zener diode and a 100 ohm resistor was placed across the output of the supply and used as a sensitive output dropout detector during line surge testing.

The UUT was tested using a Teseq NSG 3060 surge tester. Results of common mode and differential mode surge testing are shown below. A test failure was defined as a non-recoverable output interruption requiring supply repair or recycling AC input voltage.

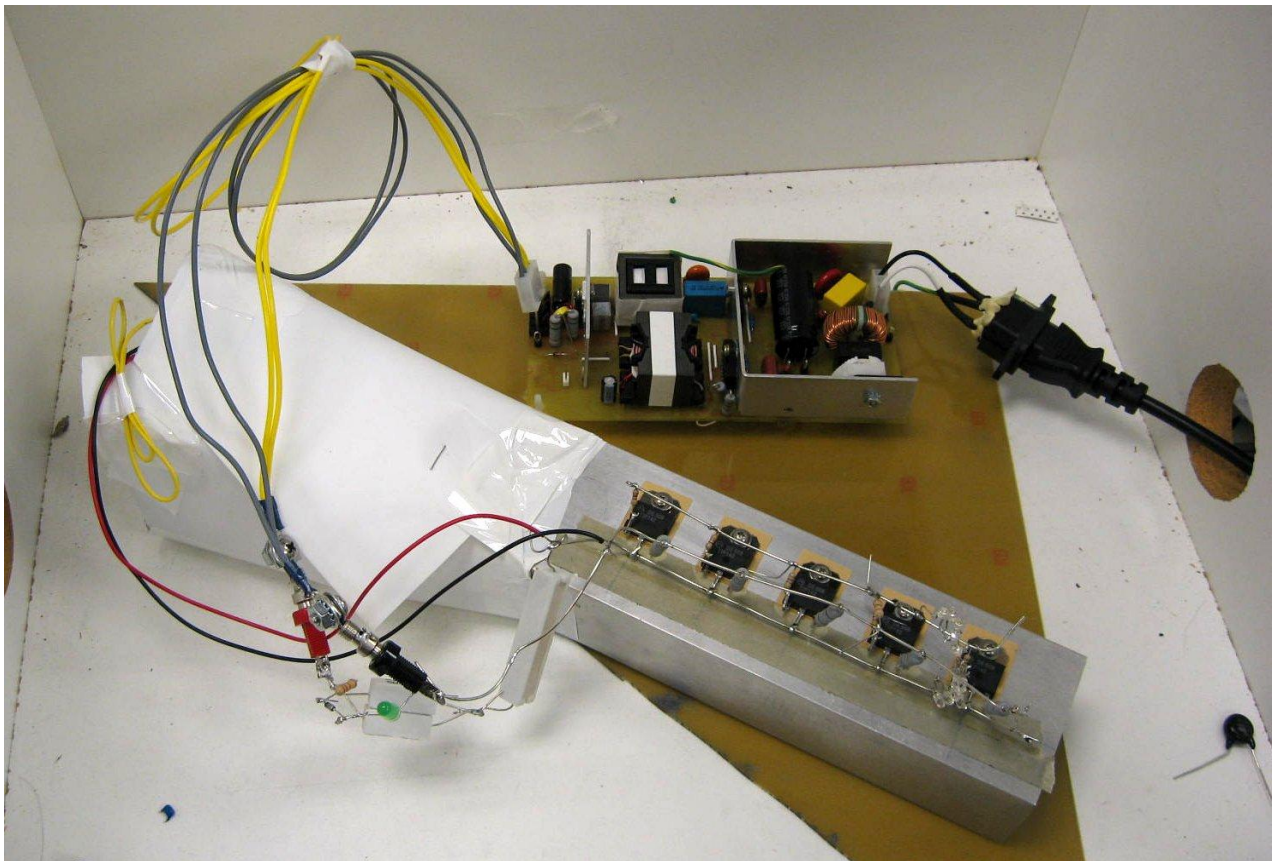


Figure 82 – Line Surge Physical Set-up.

17.2 差模突波，1.2/50 μ 秒

AC Input Voltage (VAC)	Surge Voltage (kV)	Phase Angle (°)	Generator Impedance (Ω)	Number of Strikes	Test Result
115	+2	90	2	10	PASS
115	-2	90	2	10	PASS
115	+2	270	2	10	PASS
115	-2	270	2	10	PASS
115	+2	0	2	10	PASS
115	-2	0	2	10	PASS

AC Input Voltage (VAC)	Surge Voltage (kV)	Phase Angle (°)	Generator Impedance (Ω)	Number of Strikes	Test Result
230	+2	90	2	10	PASS
230	-2	90	2	10	PASS
230	+2	270	2	10	PASS
230	-2	270	2	10	PASS
230	+2	0	2	10	PASS
230	-2	0	2	10	PASS

17.3 共模突波，1.2/50 μ 秒

AC Input Voltage (VAC)	Surge Voltage (kV)	Phase Angle (°)	Generator Impedance (Ω)	Number of Strikes	Test Result
115	+4	90	12	10	PASS
115	-4	90	12	10	PASS
115	+4	270	12	10	PASS
115	-4	270	12	10	PASS
115	+4	0	12	10	PASS
115	-4	0	12	10	PASS

AC Input Voltage (VAC)	Surge Voltage (kV)	Phase Angle (°)	Generator Impedance (Ω)	Number of Strikes	Test Result
230	+4	90	12	10	PASS
230	-4	90	12	10	PASS
230	+4	270	12	10	PASS
230	-4	270	12	10	PASS
230	+4	0	12	10	PASS
230	-4	0	12	10	PASS



18 修訂記錄

Date	Author	Revision	Description and Changes	Reviewed
04-Mar-14	RH	6.1	Initial Release	Apps & Mktg
28-May-14	RH	6.2	Schematic Updated	



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